40MX and 42MX FPGA Families

Features

High Capacity

- Single-Chip ASIC Alternative
- 3,000 to 54,000 System Gates
- Up to 2.5 kbits Configurable Dual-Port SRAM
- Fast Wide-Decode Circuitry
- Up to 202 User-Programmable I/O Pins

High Performance

- 5.6 ns Clock-to-Out
- 250 MHz Performance
- 5 ns Dual-Port SRAM Access
- 100 MHz FIFOs
- 7.5 ns 35-Bit Address Decode

HiRel Features

- Commercial, Industrial, and Military Temperature Plastic Packages
- Commercial, Military Temperature and MIL-STD-883 Ceramic Packages
- QML Certification
- Ceramic Devices Available to DSCC SMD

Ease of Integration

- Mixed Voltage Operation (5.0V or 3.3V I/O)
- Synthesis-Friendly Architecture to Support ASIC Design Methodologies
- Up to 100% Resource Utilization and 100% Pin Fixing
- Deterministic, User-Controllable Timing
- Unique In-System Diagnostic and Verification Capability with Silicon Explorer II
- Low Power Consumption
- IEEE Standard 1149.1 (JTAG) Boundary Scan Testing
- 5.0V and 3.3V Programmable PCI-Compliant I/O

Product Profile

Device	A40MX02	A40MX04	A42MX09	A42MX16	A42MX24	A42MX36
Capacity						
System Gates	3,000	6,000	14,000	24,000	36,000	54,000
SRAM Bits	N/A	N/A	N/A	N/A	N/A	2,560
Logic Modules						
Sequential	—	—	348	624	954	1,230
Combinatorial	295	547	336	608	912	1,184
Decode	—	—	N/A	N/A	24	24
Clock-to-Out	9.5 ns	9.5 ns	5.6 ns	6.1 ns	6.1 ns	6.3 ns
SRAM Modules (64x4 or 32x8)	N/A	N/A	N/A	N/A	N/A	10
Dedicated Flip-Flops	—	—	348	624	954	1,230
Maximum Flip-Flops	147	273	516	928	1,410	1,822
Clocks	1	1	2	2	2	6
User I/O (Maximum)	57	69	104	140	176	202
PCI	No	No	No	No	Yes	Yes
Boundary Scan Test (BST)	No	No	No	No	Yes	Yes
Packages (by pin count)						
PLCC	44, 68	44, 68, 84	84	84	84	—
PQFP	100	100	100, 160	100, 160, 208	160, 208	208, 240
VQFP	80	80	100	100	—	—
TQFP	—	—	176	176	176	—
CQFP	—	—	—	—	—	208, 256
PBGA	—	—	—	—	—	272

General Description

Actel's 40MX and 42MX families provide a high-performance, single-chip solution for shortening the system design and development cycle, offering a cost-effective alternative to ASICs. The 40MX and 42MX devices are excellent choices for integrating logic that is currently implemented in multiple PALs, CPLDs, and FPGAs. Example applications include high-speed controllers and address decoding, peripheral bus interfaces, DSP, and co-processor functions.

The MX device architecture is based on Actel's patented antifuse technology implemented in a 0.45μ triple-metal CMOS process. With capacities ranging from 3,000 to 54,000 system gates, the synthesis-friendly MX devices provide performance up to 250 MHz, are live on power-up, and require up to five times lower stand-by power consumption than any other FPGA device. Actel's MX FPGAs provide up to 202 user I/Os and are available in a wide variety of packages and speed grades.

Actel's 42MX devices also feature MultiPlex I/Os, which support mixed voltage systems, enable programmable PCI, deliver high-performance operation at both 5.0V and 3.3V, and provide a low-power mode.

The MX PCI-Compliant devices are fully compliant with the PCI Local Bus Specification (version 2.1). They deliver 200 MHz on-chip operation and 6.1 ns clock-to-output performance with capacities spanning from 36,000 to 54,000 system gates. MX devices comply 100 percent to the electrical and timing specifications detailed in the PCI specification. However, as with all programmable logic devices, the performance of the final product depends upon the user's design and optimization techniques.

The MX24 and MX36 devices also include system-level features such as IEEE Standard 1149.1 (JTAG) Boudary Scan Testing, dual-port SRAM, and fast wide-decode modules. The A42MX36 device offers dual-port SRAM for implementing fast FIFOs, LIFOs, and temporary data storage. The large number of storage elements can efficiently address applications requiring wide datapath manipulation and can perform transformation functions such as those required for telecommunications, networking, and DSP.

All products in the 40MX and 42MX families are available 100 percent tested over the military temperature range. In addition, the largest member of the family, the A42MX36, is available in both CQ208 and CQ256 ceramic packages screened to MIL-STD-883 levels. For easy prototyping and conversion from plastic to ceramic, the CQ208 and PQ208 devices are pin compatible.

Ordering Information

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A42MX16    –          PQ    100
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Application (Temperature Range)
Blank = Commercial (0 to +70°C)
    I = Industrial (–40 to +85°C)
    M = Military (–55 to +125°C)
    B = MIL-STD-883

Package Lead Count

Package Type
    PL = Plastic Leaded Chip Carrier
    PQ = Plastic Quad Flat Pack
    TQ = Thin (1.4 mm) Quad Flat Pack
    VQ = Very Thin (1.0 mm) Quad Flat Pack
    BG = Ball Grid Array
    CQ = Ceramic Quad Flat Pack

Speed Grade
    Blank = Standard Speed
       –1 = Approximately 15% Faster than Standard
       –2 = Approximately 25% Faster than Standard
       –3 = Approximately 35% Faster than Standard
       –F = Approximately 40% Slower than Standard

Part Number
    A40MX02= 3,000 System Gates
    A40MX04= 6,000 System Gates
    A42MX09= 14,000 System Gates
    A42MX16= 24,000 System Gates
    A42MX24= 36,000 System Gates
    A42MX36= 54,000 System Gates

Product Plan

	Speed Grade[1]					Application			
	Std	−1	−2	−3	−F[2]	C	I	M	B
A40MX02 Device									
44-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
68-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
80-Pin Very Thin Plastic Quad Flat Pack (VQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
A40MX04 Device									
44-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
68-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
84-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
80-Pin Very Thin Plastic Quad Flat Pack (VQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
A42MX09 Device									
84-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
160-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
176-Pin Thin Plastic Quad Flat Pack (TQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Very Thin Plastic Quad Flat Pack (VQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
A42MX16 Device									
84-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
160-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
208-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
176-Pin Thin Plastic Quad Flat Pack (TQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
100-Pin Very Thin Plastic Quad Flat Pack (VQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
A42MX24 Device									
84-Pin Plastic Leaded Chip Carrier (PLCC)	✔	✔	✔	✔	✔	✔	✔	✔	—
160-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
208-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
176-Pin Thin Plastic Quad Flat Pack (TQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
A42MX36 Device									
208-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
240-Pin Plastic Quad Flat Pack (PQFP)	✔	✔	✔	✔	✔	✔	✔	✔	—
272-Pin Plastic Ball Grid Array (PBGA)	✔	✔	✔	✔	✔	✔	✔	✔	—
208-Pin Ceramic Quad Flat Pack (CQFP)	✔	✔	✔	—	—	✔	—	✔[3]	✔[3]
256-Pin Ceramic Quad Flat Pack (CQFP)	✔	✔	✔	—	—	✔	—	✔[3]	✔[3]

Contact your Actel sales representative for product availability.

Applications: C = Commercial   *Availability:*   ✔ = Available   *Speed Grade:*   −1 = *Approx. 15% faster than Standard*
            I = Industrial   P = Planned   −2 = *Approx. 25% faster than Standard*
            M = Military   — = Not Planned   −3 = *Approx. 35% faster than Standard*
                                                            −F = *Approx. 40% slower than Standard*
† *Only Std, −1, −2 Speed Grade*
• *Only Std, −1 Speed Grade*

Development Tool Support

The MX devices are fully supported by Actel's line of FPGA development tools, including the Actel DeskTOP series and Designer Series tools. The Actel DeskTOP series is an integrated design environment for PCs that includes design entry, simulation, synthesis, and place-and-route tools. Designer Series, Actel's suite of FPGA development point tools for PCs and Workstations, includes the ACTgen Macro Builder, timing-driven place-and-route and analysis tools, and device programming software.

In addition, the MX devices contain ActionProbe circuitry that provides built-in access to every node in a design,

enabling 100 percent real-time observation and analysis of a device's internal logic nodes without design iteration. The probe circuitry is accessed by Silicon Explorer II, an easy-to-use integrated verification and logic analysis tool that can sample data at 100 MHz (asynchronous) or 66 MHz (synchronous). Silicon Explorer II attaches to a PC's standard COM port, turning the PC into a fully functional 18-channel logic analyzer. Silicon Explorer II allows designers to complete the design verification process at their desks and reduces verification time from several hours per cycle to only a few seconds.

Plastic Device Resources

Device	User I/Os										
	PLCC 44-Pin	PLCC 68-Pin	PLCC 84-Pin	PQFP 100-Pin	PQFP 160-Pin	PQFP 208-Pin	PQFP 240-Pin	VQFP 80-Pin	VQFP 100-Pin	TQFP 176-Pin	PBGA 272-Pin
A40MX02	34	57	—	57	—	—	—	57	—	—	—
A40MX04	34	57	69	69	—	—	—	69	—	—	—
A42MX09	—	—	72	83	101	—	—	—	83	104	—
A42MX16	—	—	72	83	125	140	—	—	83	140	—
A42MX24	—	—	72	—	125	176	—	—	—	150	—
A42MX36	—	—	—	—	—	176	202	—	—	—	202

Package Definitions *(Contact your Actel sales representative for product availability.)*

PLCC = Plastic Leaded Chip Carrier, PQFP = Plastic Quad Flat Pack, TQFP = Thin Quad Flat Pack, VQFP = Very Thin Quad Flat Pack, PBGA = Plastic Ball Grid Array

Ceramic Device Resources

Device	User I/Os	
	CQFP 208-Pin	CQFP 256-Pin
A42MX36	176	202

Package Definitions *(Contact your Actel sales representative for product availability.)*

CQFP = Ceramic Quad Flat Pack

Power Requirements

40MX

The 40MX FPGAs will operate in 5.0V-only systems or 3.3V-only systems.

V_{CC}	Input	Output
5.0V	5.0V	5.0V
3.3V	3.3V	3.3V

42MX

The 42MX FPGAs will operate in 5.0V-only systems, 3.3V-only systems, or mixed 5.0V/3.3V systems.

V_{CCA}	V_{CCI}	Input	Output
5.0V	5.0V	5.0V	5.0V
3.3V	3.3V	3.3V	3.3V
5.0V	3.3V	3.3V, 5.0V	3.3V

Mixed Voltage Power Up and Power Down

When powering up the device in the mixed voltage mode (V_{CCA} = 5.0V and V_{CCI} = 3.3V), V_{CCA} must be greater than or equal to V_{CCI} throughout the power-up sequence. If V_{CCI} is 0.5V greater than V_{CCA} when both are above 1.5V, then the I/Os' input protection junction on the I/Os will be forward biased, causing them to draw large amounts of current. When V_{CCA} and V_{CCI} are in the 1.5V to 2.0V region and V_{CCI} is greater than V_{CCA}, all I/Os would momentarily behave as outputs that are in a logical high state, and I_{CC} rises to high levels. For power down, any sequence with V_{CCA} and V_{CCI} can be implemented.

Low Power Mode

The 42MX devices have a power-saving feature enabled by a special Low Power pin (LP). In this mode, the device consumes very minimal power, with standby current as low as 500µA (see "Electrical Specifications" on page 13 and 14). All µ I/Os are tristated, all input buffers are turned off, and the core of the device is turned off. Since the core is turned off, the state of the registers and the contents of the SRAM are lost. The device enters low power mode 800ns after the LP pin is set High. It will resume normal operation 200µs after the LP pin is driven to a logic Low.

MX Architectural Overview

The 40MX and 42MX devices are composed of fine-grained building blocks that enable fast, efficient logic designs. All devices within these families are composed of logic modules, I/O modules, routing resources, and clock networks, which are the building blocks for designing fast logic designs. In addition, the A42MX36 device contains embedded dual-port SRAM and wide decode modules. The dual-port SRAM modules are optimized for high-speed datapath functions such as FIFOs, LIFOs, and scratchpad memory. The "Product Profile" on page 1 lists the specific logic resources contained within each device.

Logic Modules

The 40MX logic module is an eight-input, one-output logic circuit designed to implement a wide range of logic functions with efficient use of interconnect routing resources (Figure 1).

The logic module can implement the four basic logic functions (NAND, AND, OR, and NOR) in gates of two, three, or four inputs. Each function may have many versions with different combinations of active LOW inputs. The logic module can also implement a variety of D-latches, exclusivity functions, AND-ORs, and OR-ANDs. No dedicated hard-wired latches or flip-flops are required in the array, since latches and flip-flops can be constructed from logic modules wherever needed in the application.
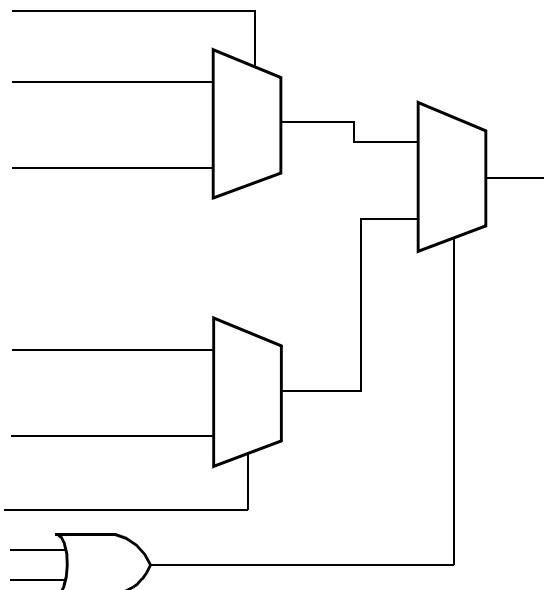

Figure 1 • 40MX Logic Module

The 42MX devices contain three types of logic modules: combinatorial (C-modules), sequential (S-modules), and decode (D-modules).

The C-module, shown in Figure 2, implements the following function:

Y=!S1*!S0*D00+!S1*S0*D01+S1*!S0*D10+S1*S0*D11

where

S0=A0*B0

S1=A1+B1

The S-module, shown in Figure 3, is designed to implement high-speed sequential functions within a single logic module. The S-module implements the same combinatorial logic function as the C-module while adding a sequential element. The sequential element can be configured as either a D flip-flop or a transparent latch. To increase flexibility, the S-module register can be bypassed so that it implements purely combinatorial logic.
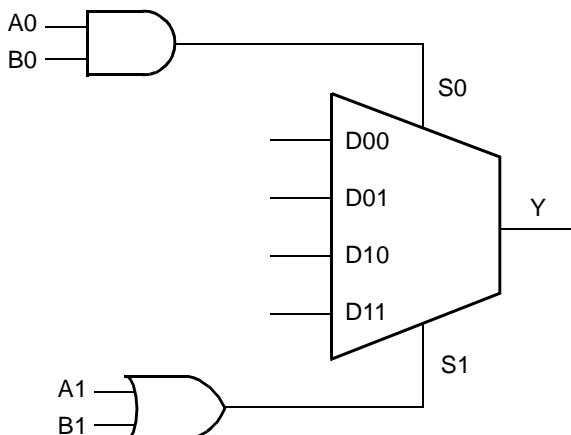
***Figure 2*** • *C-Module Implementation*
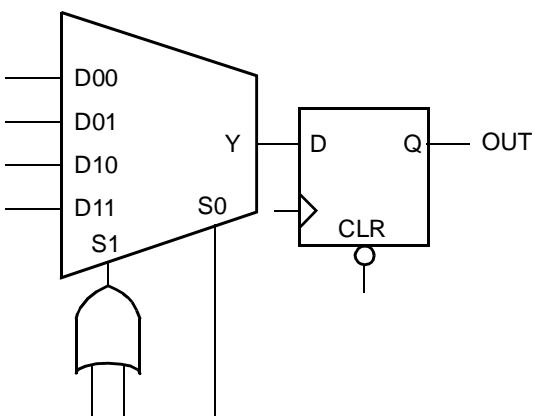
Up to 7-Input Function Plus D-Type Flip-Flop with Clear
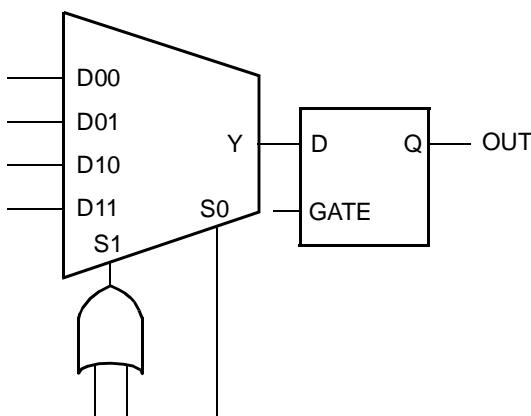
Up to 7-Input Function Plus Latch
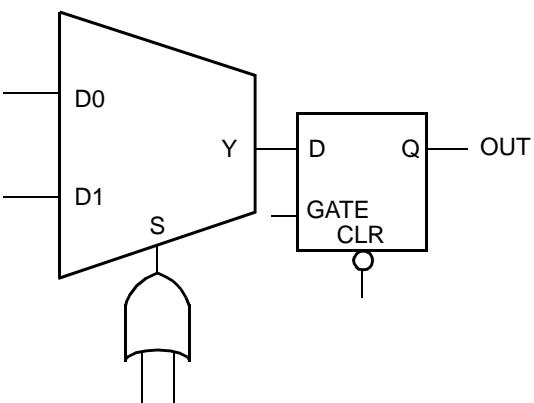
Up to 4-Input Function Plus Latch with Clear
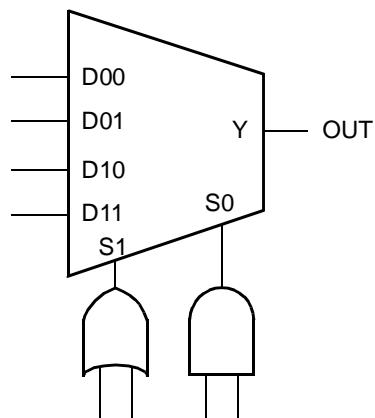
Up to 8-Input Function Same as C-Module)

Figure 3 • *S-Module Implementation*

Some of the 42MX devices contain D-modules, which are arranged around the periphery of the devices. D-modules contain wide-decode circuitry, which provides a fast, wide-input AND function similar to that found in product-term architectures (Figure 4). The D-module allows 42MX devices to perform wide-decode functions at speeds comparable to CPLDs and PALs. The output of the D-module has a programmable inverter for active HIGH or LOW assertion. The D-module output is hard-wired to an output pin, but it can also be fed back into the array to be incorporated into other logic.

Dual-Port SRAM Modules

The A42MX36 device contains dual-port SRAM modules that have been optimized for synchronous or asynchronous applications. The SRAM modules are arranged in 256-bit blocks that can be configured as 32x8 or 64x4. SRAM modules can be cascaded together to form memory spaces of user-definable width and depth. A block diagram of the 42MX dual-port SRAM block is shown in Figure 5.

The 42MX SRAM modules are true dual-port structures containing independent read and write ports. Each SRAM module contains six bits of read and write addressing (RDAD[5:0] and WRAD[5:0], respectively) for 64x4-bit blocks. When configured in byte mode, the highest order address bits (RDAD5 and WRAD5) are not used. The read and write ports of the SRAM block contain independent clocks (RCLK and WCLK) with programmable polarities

offering active HIGH or LOW implementation. The SRAM block contains eight data inputs (WD[7:0]), and eight outputs (RD[7:0]) which are connected to segmented vertical routing tracks.

The 42MX dual-port SRAM blocks provide an optimal solution for high-speed buffered applications requiring fast FIFO and LIFO queues. Actel's ACTgen Macro Builder provides the capability to quickly design memory functions, such as FIFOs, LIFOs, and RAM arrays. In addition, unused SRAM blocks can be used to implement registers for other logic within the design.
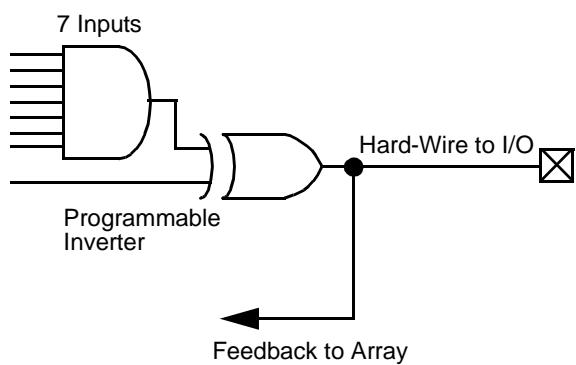

Figure 4 • D-Module Implementation
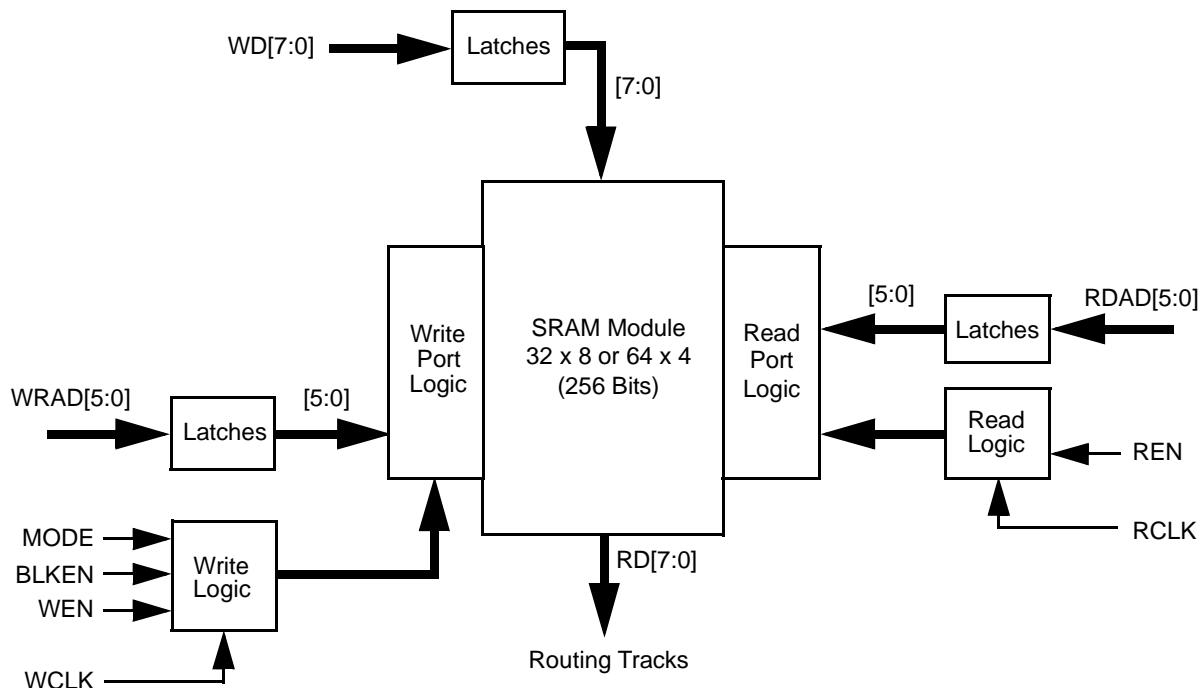
Figure 5 • 42MX Dual-Port SRAM Block

MultiPlex I/O Modules

MultiPlex I/O supports the most common voltage standards today: pure 5.0V operation, pure 3.3V operation, and mixed 3.3V operation with 5.0V I/O tolerance for maximum performance. Internal array performance is retained in 3.3V systems by using complimentary pass gates that operate as fast as they do at 5.0V at 3.3V.

MultiPlex I/O includes selectable PCI output drives in certain 42MX devices, enabling 100% PCI-compliance for both 5.0V and 3.3V systems. For low-power systems, MultiPlex I/O is used to turn off all inputs and outputs to cut current consumption to below 100μA.

The MultiPlex I/O modules provide the interface between the device pins and the logic array. The top of Figure 6 is a block diagram of the 42MX I/O module. A variety of user functions, determined by a library macro selection, can be implemented in the module. (Refer to the *Macro Library Guide* for more information.) All 42MX I/O modules contain tristate buffers, with input and output latches that can be configured for input, output, or bi-directional operation.

All 42MX devices contain flexible I/O structures (Figure 7 on page 9), where each output pin has a dedicated output-enable control. The I/O module can be used to latch input or output data, or both, providing a fast set-up time. In addition, the Actel Designer Series software tools can build a D-type flip-flop using a C-module to register input and output signals. To achieve 5.0V or 3.3V PCI-compliant output drives on A42MX24 and A42MX36 devices, a chip-wide PCI fuse is programmed. When the PCI fuse is not programmed, the output drive is standard. (See the bottom portion of Figure 6.)

Actel's Designer Series development tools provide a design library of I/O macrofunctions that can implement all I/O configurations supported by the MX FPGAs.

Routing Structure

The MX architecture uses vertical and horizontal routing tracks to interconnect the various logic and I/O modules. These routing tracks are metal interconnects that may be either of continuous length or broken into pieces called segments. Varying segment lengths allows the interconnect of over 90% of design tracks to occur with only two antifuse connections. Segments can be joined together at the ends using antifuses to increase their lengths up to the full length of the track. All interconnects can be accomplished with a maximum of four antifuses.

Horizontal Routing

Horizontal channels are located between the rows of modules and are composed of several routing tracks. The horizontal routing tracks within the channel are divided into one or more segments. The minimum horizontal segment length is the width of a module pair, and the maximum horizontal segment length is the full length of the channel. Any segment that spans more than one-third at the row length is considered a long horizontal segment. A typical channel is shown in Figure 8 on page 9. Non-dedicated horizontal routing tracks are used to route signal nets; dedicated routing tracks are used for global clock networks and for power and ground tie-off tracks.
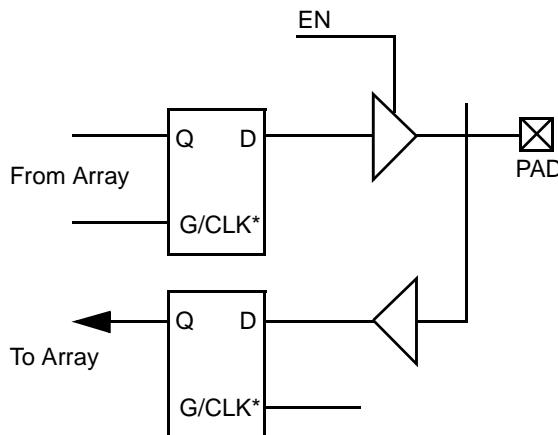
* Can be Configured as a Latch or D Flip-Flop (Using C-Module)
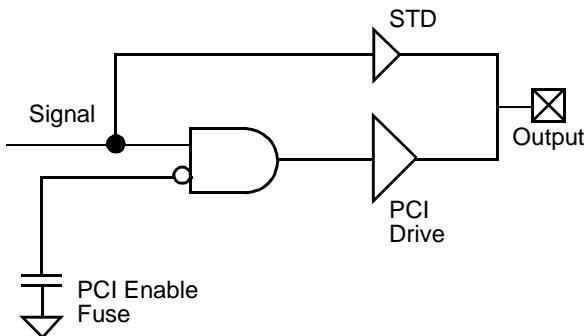
Figure 6 • *42MX I/O Module*

Vertical Routing

Another set of routing tracks run vertically through the module. There are three types of vertical tracks: input, output, and long, which are also divided into one or more segments. Each segment in an input track is dedicated to the input of a particular module; each segment in an output track is dedicated to the output of a particular module. Long segments are uncommitted and can be assigned during
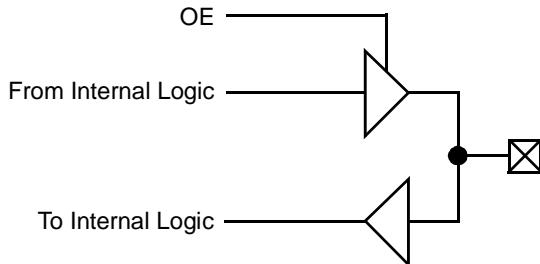
Figure 7 • *40MX I/O Module*

routing. Each output segment spans four channels (two above and two below), except near the top and bottom of the array, where edge effects occur. Long vertical tracks contain either one or two segments. An example of vertical routing tracks and segments is shown in Figure 8.

Antifuse Structures

An antifuse is a "normally open" structure as opposed to the normally connected fuse structure used in PROMs or PALs. The use of antifuses to implement a programmable logic device results in highly testable structures as well as efficient programming algorithms. The structure is highly-testable because there are no pre-existing connections; therefore, temporary connections can be made using pass transistors. These temporary connections can isolate individual antifuses to be programmed and individual circuit structures to be tested, which can be done before and after programming. For example, all metal tracks can be tested for continuity and shorts between adjacent tracks, and the functionality of all logic modules can be verified.

Clock Networks

The 40MX devices have one global clock distribution network (CLK). Two low-skew, high-fanout clock distribution networks are provided in each 42MX device. These networks are referred to as *CLK0* and *CLK1*. Each network has a clock module (CLKMOD) that selects the source of the clock signal and may be driven as follows:

- Externally from the CLKA pad
- Externally from the CLKB pad
- Internally from the CLKINTA input
- Internally from the CLKINTB input

The clock modules are located in the top row of I/O modules. Clock drivers and a dedicated horizontal clock track are located in each horizontal routing channel.

The user controls the clock module by selecting one of two clock macros from the macro library. The macro CLKBUF is used to connect one of the two external clock pins to a clock network, and the macro CLKINT is used to connect an

internally-generated clock signal to a clock network. Since both clock networks are identical, it does not matter whether CLK0 or CLK1 is being used. The clock input pads can also be used as normal I/Os, bypassing the clock networks (Figure 9).

The A42MX36 device has four additional register control resources, called quadrant clock networks (Figure 10 on page 10). Each quadrant clock provides a local, high-fanout resource to the contiguous logic modules within its quadrant of the device. Quadrant clock signals can originate from specific I/O pins or from the internal array and can be used as a secondary register clock, register clear, or output enable.
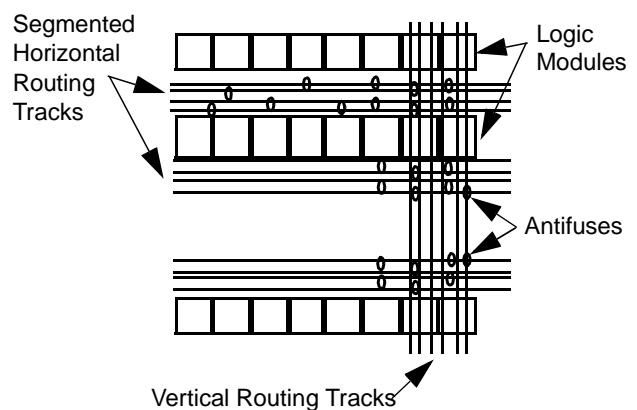
Figure 8 • *Routing Structure*
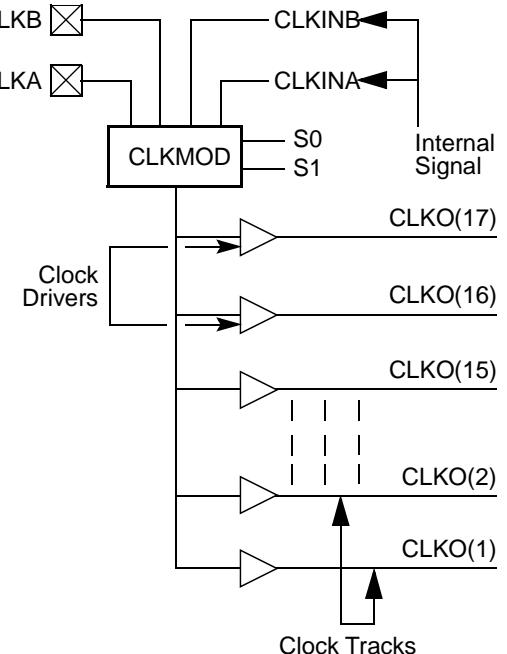
Figure 9 • *Clock Networks*

Test Circuitry

All devices contain Actel's ActionProbe test circuitry which test and debug a design once it is programmed into a device. Once a device has been programmed, the ActionProbe test circuitry allows the designer to probe any internal node during device operation to aid in debugging a design. In addition, 42MX devices contain IEEE Standard 1149.1 boundary scan test circuitry.

IEEE Standard 1149.1 Boundary Scan Testing (BST)

IEEE Standard 1149.1 defines a four-pin Test Access Port (TAP) interface for testing integrated circuits in a system. The 42MX family provides five BST pins: Test Data In (TDI), Test Data Out (TDO), Test Clock (TCK), and Test Mode Select Test Reset (TRST) (42MX24A only). Devices are configured in a test "chain" where BST data can be transmitted serially between devices via TDO-to-TDI interconnections. The TMS and TCK signals are shared among all devices in the test chain so that all components operate in the same state.

The 42MX family implements a subset of the IEEE Standard 1149.1 BST instruction in addition to a private instruction, which allows the use of Actel's ActionProbe facility with BST. Refer to the IEEE Standard 1149.1 specification for detailed information regarding BST.

Boundary Scan Circuitry

The 42MX boundary scan circuitry consists of a Test Access Port (TAP) controller, test instruction register, a JPROBE register, a bypass register, and a boundary scan register. Figure 11 on page 11 shows a block diagram of the 42MX boundary scan circuitry.
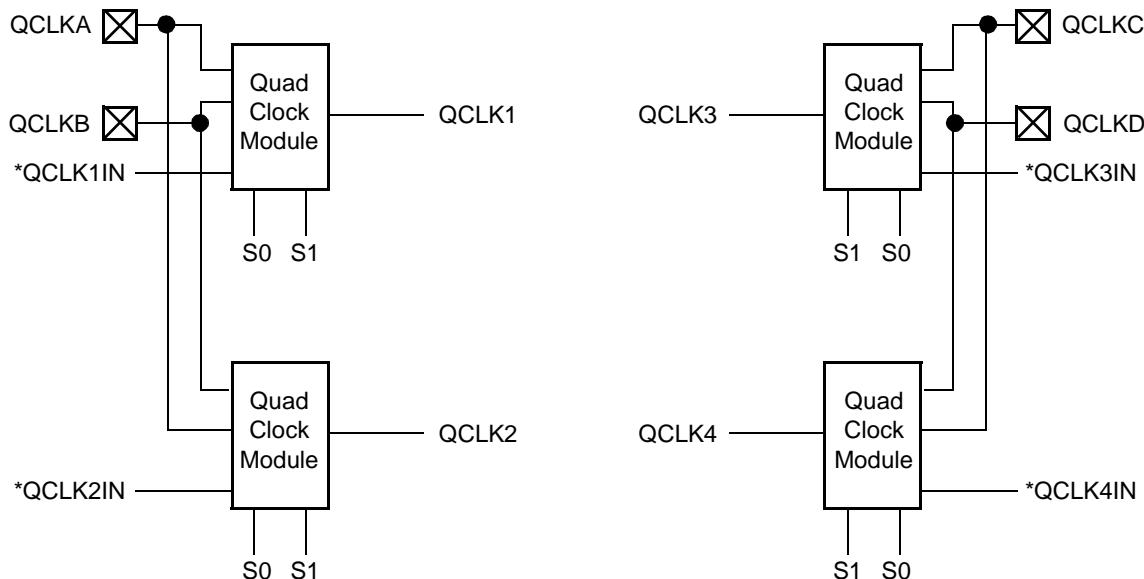
QCLK1IN, QCLK2IN, QCLK3IN, and QCLK4IN are internally-generated signals.

Figure 10 • Quadrant Clock Network
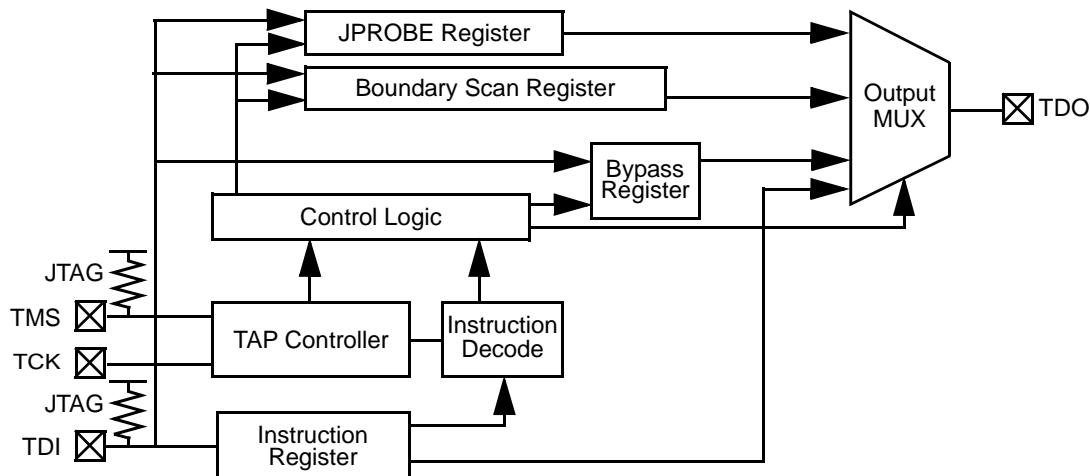
Figure 11 • *42MX IEEE 1149.1 Boundary Scan Circuitry*

When a device is operating in BST mode, four I/O pins are used for the TDI, TDO, TMS, and TCK signals. An active reset (nTRST) pin is not supported; however, the 42MX device contain power-on circuitry that resets the boundary scan circuitry upon power-up. Table 1 summarizes the functions of the IEEE 1149.1 BST signals.

Table 1 • *IEEE 1149.1 BST Signals*

Signal	Name	Function
TDI	Test Data In	Serial data input for BST instructions and data. Data is shifted in on the rising edge of TCK.
TDO	Test Data Out	Serial data output for BST instructions and test data.
TMS	Test Mode Select	Serial data input for BST mode. Data is shifted in on the rising edge of TCK.
TCK	Test Clock	Clock signal to shift the BST data into the device.

JTAG

All SX-A devices are IEEE 1149.1 (JTAG) compliant. SX-A devices offer superior diagnostic and testing capabilities by providing JTAG and probing capabilites. These functions are controlled through the special JTAG pins in conjunction with the program fuse.

JTAG fuse programmed:

- TCK must be terminated—logical high or low doesn't matter (to avoid floating input)

- TDI, TMS may float or at logical high (internal pull-up is present)

- TDO may float or connect to TDI of another device (it's an output)

JTAG fuse not programmed:

- TCK, TDI, TDO, TMS are user I/O. If not used, they will be configured as tristated output.

BST Instructions

Boundary scan testing within the 42MX devices is controlled by a Test Access Port (TAP) state machine. The TAP controller drives the three-bit instruction register, a bypass register, and the boundary scan data registers within the device. The TAP controller uses the TMS signal to control the testing of the device. The BST mode is determined by the bitstream entered on the TMS pin. Table 2 describes the test instructions supported by the 42MX devices.

Reset

The TMS pin is equipped with an internal pull-up resistor. This allows the TAP controller to remain in or return to the Test-Logic-Reset state when there is no input or when a logical 1 is on the TMS pin. To reset the controller, TMS must be HIGH for at least five TCK cycles.

Table 2 • BST Instructions

Test Mode	Code	Description
EXTEST	000	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test results at the input pins.
SAMPLE/ PRELOAD	001	Allows a snapshot of the signals at the device pins to be captured and examined during device operation.
JPROBE	011	A private instruction allowing the user to connect Actel's Micro Probe registers to the test chain.
USER INSTRUCTION	100	Allows the user to build application-specific instructions such as RAM READ and RAM WRITE.
HIGH Z	101	Refer to the IEEE Standard 1149.1 specification.
CLAMP	110	Refer to the IEEE Standard 1149.1 specification.
BYPASS	111	Enables the bypass register between the TDI and TDO pins. The test data passes through the selected device to adjacent devices in the test chain.

5.0V Operating Conditionsand Mixed 5.0V/3.3V Operating Conditions

Absolute Maximum Ratings[1]

Free Air Temperature Range

Symbol	Parameter	Limits	Units
V_{CCA}/V_{CCI}	DC Supply Voltage	–0.5 to +7.0	V
V_I	Input Voltage	–0.5 to V_{CC} +0.5	V
V_O	Output Voltage	–0.5 to V_{CC} +0.5	V
T_{STG}	Storage Temperature	–65 to +150	°C

Notes:

1. *Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Devices should not be operated outside the Recommended Operating Conditions.*

2. *Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than $V_{CCA} + 0.5V$ or less than GND – 0.5V, the internal protection diode will be forward-biased and can draw excessive current.*

Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range[1]	0 to +70	–40 to +85	–55 to +125	°C
Power Supply Tolerance	±5	±10	±10	%V_{CC}
V_{CCI}	4.75 to 5.25	4.5 to 5.5	4.5 to 5.5	V
V_{CCA}	4.75 to 5.25	4.5 to 5.5	4.5 to 5.5	V
V_{CCI}[2]	3.14 to 3.47	3.0 to 3.6	3.0 to 3.6	V

Notes:

1. *Ambient temperature (T_A) is used for commercial and industrial; case temperature (T_C) is used for military.*

2. *Operating condition for I/Os in mixed voltage mode.*

Electrical Specifications

Symbol	Parameter	Commercial		Commercial '–F'		Industrial		Military		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V_{OH}[1]	(I_{OH} = –10 mA) [2] TTL	2.4		2.4						V
	(I_{OH} = –6 mA) TTL									V
	(I_{OH} = –4 mA) TTL					3.7		3.7		V
V_{OL}[1]	(I_{OL} = 10 mA) [2] TTL		0.5		0.5					V
	(I_{OL} = 6 mA) TTL						0.40		0.40	V
V_{IL}		–0.3	0.8	–0.3	0.8	–0.3	0.8	–0.3	0.8	V
V_{IH}		2.0	V_{CCI} + 0.3	2.0	V_{CCI} + 0.3	2.0	V_{CCI} + 0.3	2.0	V_{CCI} + 0.3	V
I_{IL}	(V_{IN} = 0.5)		–10		–10		–10		–10	µA
I_{IH}	(V_{IN} = 2.7)		–10		–10		–10		–10	µA
Input Transition Time t_R, t_F[2]			500		500		500		500	ns
C_{IO} I/O Capacitance[2, 3]			10		10		10		10	pF
Standby Current, I_{CC}[4]			Notes 5 & 6		25.0		Notes 6 & 7		25	mA
$I_{CC(D)}$ Dynamic V_{CCI} Supply Current		See the "Power Dissipation" section on page 18.								
Low Power Mode Standby Current			Note 8		I_{CC} – 0.5		I_{CC} – 0.5		I_{CC} – 0.5	mA

Notes:

1. *Only one output tested at a time. V_{CCI} = min.*

2. *Not tested, for information only.*

3. *Includes worst-case 84-pin PLCC package capacitance. V_{OUT} = 0 V, f = 1 MHz.*

4. *All outputs unloaded. All inputs = V_{CCI} or GND. I_{CC} limit includes I_{PP} and I_{SV} during normal operation.*

5. *A40MX02 and A40MX04 I_{CC} = 3 mA, A42MX09 I_{CC} = 5 mA, A42MX16 I_{CC} = 6 mA, A42MX24, A42MX24A, and A42MX36 I_{CC} = 25 mA.*

6. *I_{CC} Max = 2 mA is available by special request. Contact your local Actel Sales representative for additional information.*

7. *A40MX02 and A40MX04 I_{CC} = 10 mA, A42MX09, A42MX16, A42MX24, A42MX24A, and A42MX36 I_{CC} = 25 mA.*

8. *In Low Power Mode, A40MX09, A42MX16, A42MX24, and A42MX36 ICC = 500 µA; A40MX02 and A40MX04 = N/A.*

3.3V Operating Conditions

Absolute Maximum Ratings[1]

$V_{CC} = V_{CCA}$ and V_{CCI}
Free Air Temperature Range

Symbol	Parameter	Limits	Units
V_{CC}	DC Supply Voltage	−0.5 to +7.0	V
V_I	Input Voltage	−0.5 to V_{CC} +0.5	V
V_O	Output Voltage	−0.5 to V_{CC} +0.5	V
I_{IO}	I/O Source Sink Current[2]	±20	mA
T_{STG}	Storage Temperature	−65 to +150	°C

Notes:

1. *Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Devices should not be operated outside the Recommended Operating Conditions.*

2. *Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than V_{CC} + 0.5V or less than GND – 0.5V, the internal protection diodes will forward-bias and can draw excessive current.*

Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range[1]	0 to +70	−40 to +85	−55 to +125	°C
Power Supply Tolerance	±5	±10	±10	%V
V_{CCI}	3.0 to 3.6	3.0 to 3.6	3.0 to 3.6	V
V_{CCA}	3.0 to 3.6	3.0 to 3.6	3.0 to 3.6	V

Note:

1. *Ambient temperature (T_A) is used for commercial, and industrial; case temperature (T_C) is used for military.*

Electrical Specifications

Parameter		Commercial		Commercial '–F'		Industrial		Military		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V_{OH}[1]	(I_{OH} = −4 mA)	2.15		2.15		2.4		2.4		V
	(I_{OH} = −3.2 mA)	2.4		2.4						V
V_{OL}[1]	(I_{OL} = 6 mA)		0.4		0.4		0.48		0.48	V
V_{IL}		−0.3	0.8	−0.3	0.8	−0.3	0.8	−0.3	0.8	V
V_{IH}		2.0	V_{CC} + 0.3	2.0	V_{CC} + 0.3	2.0	V_{CC} + 0.3	2.0	V_{CC} + 0.3	V
I_{IL}			−10		−10		−10		−10	µA
I_{IH}			−10		−10		−10		−10	µA
Input Transition Time t_R, t_F[2]			500		500		500		500	ns
C_{IO} I/O Capacitance[2, 3]			10		10		10		10	pF
Standby Current, I_{CC}[4]			Notes 5 & 6		25		Notes 6 & 7		25	mA
$I_{CC(D)}$ Dynamic V_{CC} Supply Current		See the "Power Dissipation" section on page 18.								
Low Power Mode Standby Current			Note 8		I_{CC} − 5.0		I_{CC} − 5.0		I_{CC} − 5.0	mA

Notes:

1. *Only one output IV curve tested at a time. V_{CC} = min.*

2. *Not tested, for information only.*

3. *Includes worst-case 84-pin PLCC package capacitance. V_{OUT} = 0 V, f = 1 MHz.*

4. *All outputs unloaded. All inputs = V_{CC} or GND.*

5. *A40MX02 and A40MX04 I_{CC} = 3 mA, A42MX09 I_{CC} = 5 mA, A42MX16 I_{CC} = 6 mA, A42MX24 and A42MX36 I_{CC} = 25 mA.*

6. *I_{CC} Max = 1.5mA is available by special request. Contact your Actel Sales representative for additional information.*

7. *A40MX02 and A40MX04 I_{CC} = 10 mA, A42MX09, A42MX16, A42MX24, and A42MX36 I_{CC} = 25 mA.*

8. *In Low Power Mode, A42MX09, A42MX16, A42MX24, A42MX36 I_{CC} = 50 µA. A40MX02 and A40MX04 = N/A.*

Output Drive Characteristics for 5.0V PCI Signaling

MX PCI device I/O drivers were designed specifically for high-performance PCI systems. Figure 12 on page 17 shows the typical output drive characteristics of the MX devices. MX output drivers are compliant with the PCI Local Bus Specification.

DC Specification (5.0V PCI Signaling)[1]

Symbol	Parameter	Condition	PCI Minimum	PCI Maximum	MX Minimum	MX Maximum	Units
V_{CC}	Supply Voltage		4.75	5.25	4.75	5.25^2	V
V_{IH}	Input High Voltage		2.0	$V_{CC} + 0.5$	2.0	$V_{CC} + 0.3$	V
V_{IL}	Input Low Voltage		−0.5	0.8	−0.3	0.8	V
I_{IH}	Input High Leakage Current	$V_{IN} = 2.7$		70	—	10	µA
I_{IL}	Input Low Leakage Current	$V_{IN} = 0.5$		−70	—	−10	µA
V_{OH}	Output High Voltage	$I_{OUT} = -2$ mA / $I_{OUT} = -6$ mA	2.4		3.84		V
V_{OL}	Output Low Voltage	$I_{OUT} = 3$ mA, 6 mA		0.55	—	0.33	V
C_{IN}	Input Pin Capacitance			10	—	10	pF
C_{CLK}	CLK Pin Capacitance		5	12	—	10	pF
L_{PIN}	Pin Inductance			20	—	< 8 nH^3	nH

Notes:

1. *PCI Local Bus Specification Section 4.2.1.1.*

2. *Maximum rating for V_{CC} −0.5V to 7.0V.*

3. *Dependent upon the chosen package. PCI recommends QFP and BGA packaging to reduce pin inductance and capacitance.*

AC Specifications (5.0V PCI Signaling)[1]

Symbol	Parameter	Condition	PCI Minimum	PCI Maximum	MX Minimum	MX Maximum	Units
I_{CL}	Low Clamp Current	$-5 < V_{IN} \leq -1$	$-25 + (V_{IN} +1) /0.015$		−60	−10	mA
Slew (r)	Output Rise Slew Rate	0.4V to 2.4V load	1	5	1.8	2.8	V/ns
Slew (f)	Output Fall Slew Rate	2.4V to 0.4V load	1	5	2.8	4.3	V/ns

Note:

1. *PCI Local Bus Specification Section 4.2.1.2.*

Output Drive Characteristics for 3.3V PCI Signaling

DC Specification (3.3V PCI Signaling)[1]

Symbol	Parameter	Condition	PCI		MX		Units
			Minimum	Maximum	Minimum	Maximum	
V_{CC}	Supply Voltage		3.0	3.6	3.0	3.6	V
V_{IH}	Input High Voltage		0.5	V_{CC} + 0.5	0.5	V_{CC} + 0.3	V
V_{IL}	Input Low Voltage		−0.5	0.8	−0.3	0.8	V
I_{IH}	Input High Leakage Current	$V_{IN} = 2.7$		70		10	μA
I_{IL}	Input Leakage Current			−70		−10	μA
V_{OH}	Output High Voltage	$I_{OUT} = −2$ mA	0.9		3.3		V
V_{OL}	Output Low Voltage	$I_{OUT} = 3$ mA, 6 mA		0.1		0.1 V_{CC}	V
C_{IN}	Input Pin Capacitance			10		10	pF
C_{CLK}	CLK Pin Capacitance		5	12		10	pF
L_{PIN}	Pin Inductance			20		< 8 nH[3]	nH

Notes:

1. *PCI Local Bus Specification Section 4.2.2.1.*

2. *Maximum rating for V_{CC} −0.5V to 7.0V.*

3. *Dependent upon the chosen package. PCI recommends QFP and BGA packaging to reduce pin inductance and capacitance.*

AC Specifications for (3.3V PCI Signaling)[1]

Symbol	Parameter	Condition	PCI		MX		Units
			Minimum	Maximum	Minimum	Maximum	
I_{CL}	Low Clamp Current	−5 < V_{IN} ≤ −1	−25 + (V_{IN} +1) /0.015		−60	−10	mA
Slew (r)	Output Rise Slew Rate	0.2V to 0.6V load	1	4	1.8	2.8	V/ns
Slew (f)	Output Fall Slew Rate	0.6V to 0.2V load	1	4	2.8	4.0	V/ns

Note:

1. *PCI Local Bus Specification Section 4.2.2.2.*
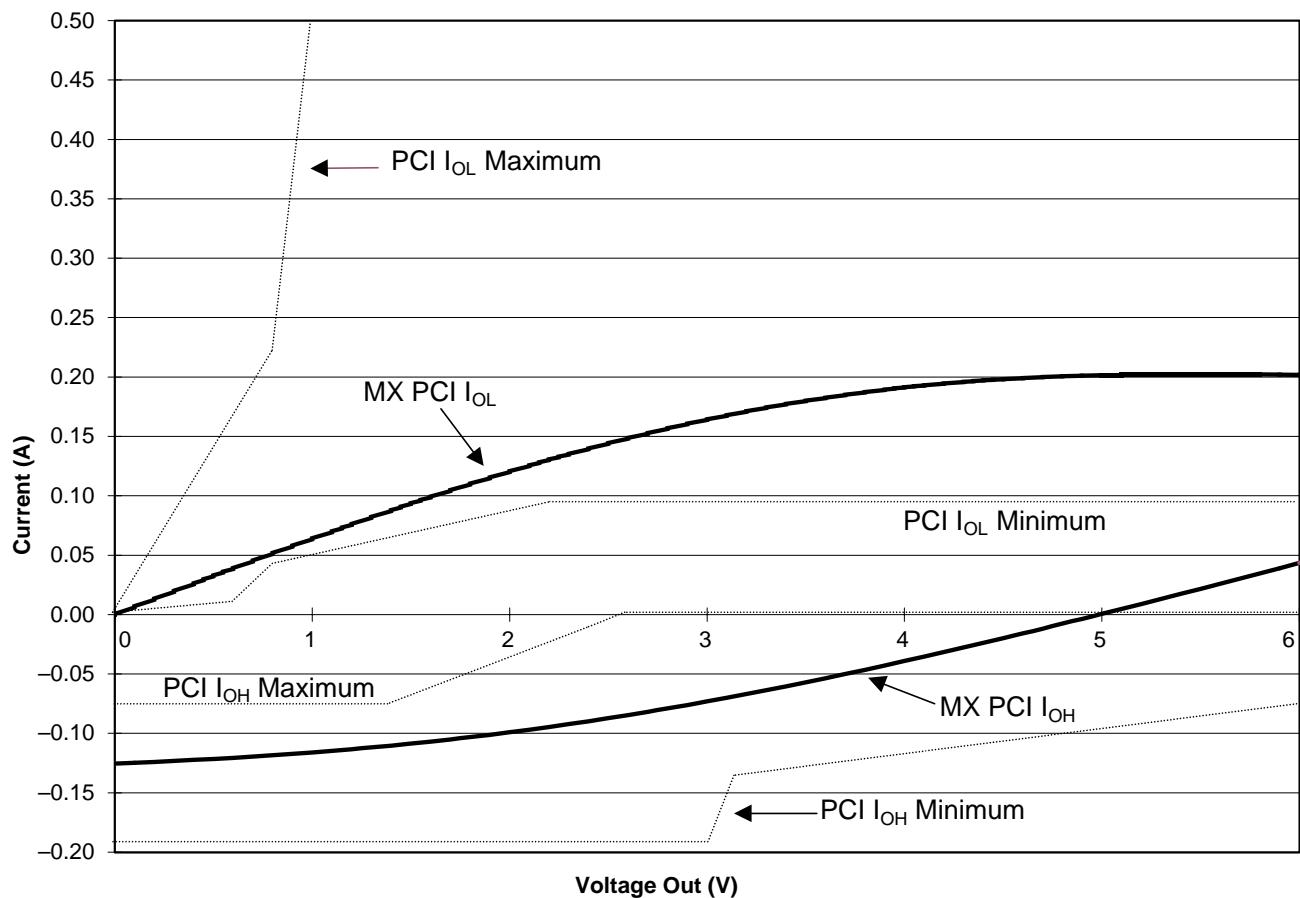
Figure 12 • *Typical Output Drive Characteristics (Based upon measured data)*

Package Thermal Characteristics

The device junction-to-case thermal characteristic is θ_{jc}, and the junction-to-ambient air characteristic is θ_{ja}. The thermal characteristics for θ_{ja} are shown with two different air flow rates. Ambient temperature (T_A) is used for commercial and industrial; case temperature (T_C) is used for military.

Maximum junction temperature is 150°C.

A sample calculation of the absolute maximum power dissipation allowed for a PQFP 160-pin package at commercial temperature is as follows:

$$\frac{\text{Max. junction temp. (°C)} - \text{Max. commercial temp.}}{\theta_{ja} \text{ (°C/W)}} = \frac{150°C - 70°C}{32°C/W} = 2.5\,W$$

Plastic Packages	Pin Count	θ_{jc}	θ_{ja}	
			Still Air	300 ft/min
Plastic Quad Flat Pack	100	12	34°C/W	31°C/W
Plastic Quad Flat Pack	160	10	32°C/W	24°C/W
Plastic Quad Flat Pack	208	8	30°C/W	23°C/W
Plastic Quad Flat Pack	240	3.5	19°C/W	16°C/W
Plastic Leaded Chip Carrier	44	16	43°C/W	31°C/W
Plastic Leaded Chip Carrier	68	13	36°C/W	25°C/W
Plastic Leaded Chip Carrier	84	12	32°C/W	22°C/W
Thin Plastic Quad Flat Pack	176	11	28°C/W	21°C/W
Very Thin Plastic Quad Flat Pack	80	12	39°C/W	33°C/W
Very Thin Plastic Quad Flat Pack	100	10	38°C/W	32°C/W
Plastic Ball Grid Array	272	3	20°C/W	14.5°C/W

Ceramic Packages	Pin Count	θ_{jc}	θ_{ja} Still Air
Ceramic Quad Flat Pack	208	6.3	22°C/W
Ceramic Quad Flat Pack	256	6.2	20°C/W

Power Dissipation

General Power Equation

$$P = [I_{CC}\text{standby} + I_{CC}\text{active}] * V_{CCI} + I_{OL} * V_{OL} * N \\ + I_{OH} * (V_{CCI} - V_{OH}) * M$$

where:

I_{CC}standby is the current flowing when no inputs or outputs are changing.

I_{CC}active is the current flowing due to CMOS switching.

I_{OL}, I_{OH} are TTL sink/source currents.

V_{OL}, V_{OH} are TTL level output voltages.

N equals the number of outputs driving TTL loads to V_{OL}.

M equals the number of outputs driving TTL loads to V_{OH}.

Accurate values for N and M are difficult to determine because they depend on the family type, on design details, and on the system I/O. The power can be divided into two components: static and active.

Static Power Component

Actel FPGAs have small static power components that result in power dissipation lower than PALs or CPLDs. By integrating multiple PALs/CPLDs into one FPGA, an even greater reduction in board-level power dissipation can be achieved.

The power due to standby current is typically a small component of the overall power. Standby power is calculated for commercial, worst-case conditions:

I_{CC}	V_{CCA}	Power
2 mA	5.25 V	10.5 mW

The static power dissipation by TTL loads depends on the number of outputs driving HIGH or LOW, and on the DC load current. Again, this number is typically small. For instance, a 32-bit bus sinking 4 mA at 0.33V will generate 42 mW with all outputs driving LOW, and 140 mW with all outputs driving HIGH. The actual dissipation will average somewhere in between, as I/Os switch states with time.

Active Power Component

Power dissipation in CMOS devices is usually dominated by the active (dynamic) power dissipation. This component is frequency-dependent and a function of the logic and the external I/O. Active power dissipation results from charging internal chip capacitances of the interconnect, unprogrammed antifuses, module inputs, and module outputs, plus external capacitance due to PC board traces and load device inputs. An additional component of the active power dissipation is the totem pole current in the CMOS transistor pairs. The net effect can be associated with an equivalent capacitance that can be combined with frequency and voltage to represent active power dissipation.

Equivalent Capacitance

The power dissipated by a CMOS circuit can be expressed by the equation:

$$\text{Power } (\mu W) = C_{EQ} * V_{CCA}^2 * F \qquad (1)$$

where:

C_{EQ} = Equivalent capacitance expressed in picofarads (pF)

V_{CCA} = Power supply in volts (V)

F = Switching frequency in megahertz (MHz)

Equivalent capacitance is calculated by measuring I_{CC}active at a specified frequency and voltage for each circuit component of interest. Measurements have been made over a range of frequencies at a fixed value of $\vee_{CC}$. Equivalent capacitance is frequency-independent, so the results can be used over a wide range of operating conditions. Equivalent capacitance values are shown below.

C_{EQ} Values for Actel MX FPGAs

Modules (C_{EQM})	3.5
Input Buffers (C_{EQI})	6.9
Output Buffers (C_{EQO})	18.2
Routed Array Clock Buffer Loads (C_{EQCR})	1.4

To calculate the active power dissipated from the complete design, the switching frequency of each part of the logic must be known. The equation below shows a piece-wise linear summation over all components.

$\text{Power} = V_{CCA}^2 * [(m \times C_{EQM} * f_m)_{Modules} +$
$(n * C_{EQI} * f_n)_{Inputs} + (p * (C_{EQO} + C_L) * f_p)_{outputs} +$
$0.5 * (q_1 * C_{EQCR} * f_{q1})_{routed\_Clk1} + (r_1 * f_{q1})_{routed\_Clk1} +$
$0.5 * (q_2 * C_{EQCR} * f_{q2})_{routed\_Clk2} + (r_2 * f_{q2})_{routed\_Clk2} \qquad (2)$

where:

m = Number of logic modules switching at frequency f_m

n = Number of input buffers switching at frequency f_n

p = Number of output buffers switching at frequency f_p

q_1 = Number of clock loads on the first routed array clock

q_2 = Number of clock loads on the second routed array clock

r_1 = Fixed capacitance due to first routed array clock

r_2 = Fixed capacitance due to second routed array clock

C_{EQM} = Equivalent capacitance of logic modules in pF

C_{EQI} = Equivalent capacitance of input buffers in pF

C_{EQO} = Equivalent capacitance of output buffers in pF

C_{EQCR} = Equivalent capacitance of routed array clock in pF

C_L = Output load capacitance in p

f_m = Average logic module switching rate in MHz

f_n = Average input buffer switching rate in MHz

f_p = Average output buffer switching rate in MHz

f_{q1} = Average first routed array clock rate in MHz

f_{q2} = Average second routed array clock rate in MHz

Fixed Capacitance Values for MX FPGAs (pF)

Device Type	r_1 routed_Clk1	r_2 routed_Clk2
A40MX02	41.4	N/A
A40MX04	68.6	N/A
A42MX09	118	118
A42MX16	165	165
A42MX24	185	185
A42MX36	220	220

Determining Average Switching Frequency

To determine the switching frequency for a design, the data input values to the circuit must be clearly understood. The following guidelines represent worst-case scenarios; these can be used to generally predict the upper limits of power dissipation.

Logic Modules (m)	=	80% of Combinatorial Modules
Inputs Switching (n)	=	# of Inputs/4
Outputs Switching (p)	=	# of Outputs/4
First Routed Array Clock Loads (q_1)	=	40% of Sequential Modules
Second Routed Array Clock Loads (q_2)	=	40% of Sequential Modules
Load Capacitance (C_L)	=	35 pF

Logic Modules (m)	=	80% of Combinatorial Modules
Average Logic Module Switching Rate (f_m)	=	F/10
Average Input Switching Rate (f_n)	=	F/5
Average Output Switching Rate (f_p)	=	F/10
Average First Routed Array Clock Rate (f_{q1})	=	F
Average Second Routed Array Clock Rate (f_{q2})	=	F/2

40MX Timing Model*
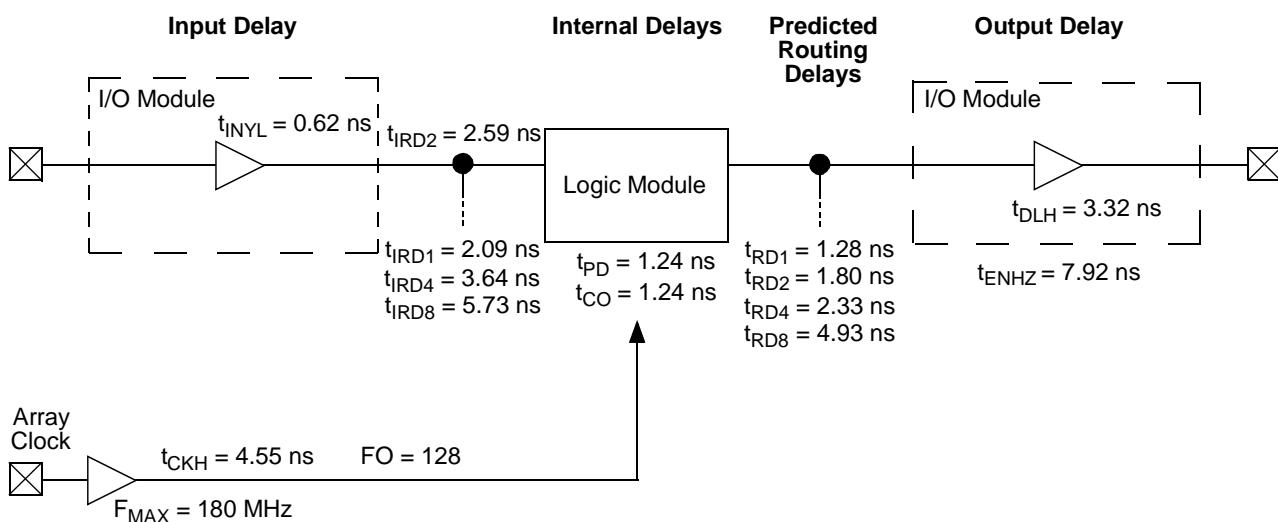
Values are shown for 40MX '–3' speed devices at 5.0V worst-case commercial conditions.

42MX Timing Model*

Input Delays   **Internal Delays**   **Predicted Routing Delays**   **Output Delays**

I/O Module

t_{INYL} = 1.16 ns

t_{IRD1} = 2.24 ns†

Combinatorial Logic Module

t_{PD} = 1.55 ns

D Q

G

t_{INH} = 0.00 ns
t_{INSU} = 0.54 ns
t_{INGL} = 1.40 ns

t_{RD1} = 0.80 ns
t_{RD2} = 1.00 ns
t_{RD4} = 1.50 ns
t_{RD8} = 2.50 ns

I/O Module

t_{DLH} = 2.70 ns

I/O Module

t_{DLH} = 2.70 ns

Sequential Logic Module

Combinatorial Logic included in t_{SUD}

D Q

t_{RD1} = 0.80 ns

D Q

G

t_{ENHZ} = 5.40 ns

t_{SUD} = 0.36 ns
t_{HD} = 0.00 ns

t_{CO} = 1.37 ns

t_{OUTH} = 0.00 ns
t_{OUTSU} = 0.30 ns
t_{GLH} = 2.90 ns

Array Clocks

t_{CKH} = 2.70 ns   FO = 32

F_{MAX} = 245 MHz

t_{LCO} = 5.60 ns (light loads, pad-to-pad)

Values are shown for A42MX09 '–2' at 5.0V worst-case commercial conditions

† Input module predicted routing delay

42MX Timing Model (Logic Functions using Quadrant Clocks)*

Input Delays

Internal Delays

Predicted Routing Delays

Output Delays

I/O Module

$t_{INPY} = 1.14$ ns

$t_{IRD1} = 2.18$ ns

Combinatorial Module

$t_{PD} = 1.46$ ns

$t_{INH} = 0.00$ ns
$t_{INSU} = 0.53$ ns
$t_{INGO} = 1.55$ ns

Decode Module

$t_{PDD} = 1.78$ ns

$t_{RD1} = 1.04$ ns
$t_{RD2} = 1.42$ ns
$t_{RD4} = 2.18$ ns

I/O Module

$t_{DLH} = 2.84$ ns

$t_{RDD} = 0.38$ ns

Sequential Logic Module

Combinatorial Logic included in t_{SUD}

$t_{SUD} = 0.30$ ns
$t_{HD} = 0.00$ ns

$t_{CO} = 1.43$ ns

$t_{RD1} = 1.04$ ns

I/O Module

$t_{DLH} = 2.84$ ns

$t_{ENHZ} = 5.80$ ns

$t_{LH} = 0.00$ ns
$t_{LSU} = 0.53$ ns
$t_{GHL} = 3.27$ ns

Quadrant Clocks

$t_{CKH} = 3.03$ ns**

$F_{MAX} = 163$ MHz

Preliminary values are shown for A42MX36 '–2' at 5.0V worst-case commercial conditions

**Load-dependent*

42MX Timing Model (SRAM Functions)*

Input Delays

I/O Module

$t_{INPY} = 1.14$ ns $t_{IRD1} = 2.18$ ns

D   Q

G

$t_{INSU} = 0.53$ ns
$t_{INH} = 0.00$ ns
$t_{INGO} = 1.55$ ns

Predicted
Routing
Delays

I/O Module
$t_{DLH} = 2.84$ ns

WD [7:0]   RD [7:0]

WRAD [5:0]   RDAD [5:0]

BLKEN   REN

WEN

WCLK   RCLK

$t_{RD1} = 1.04$ ns

D   Q

G

$t_{ADSU} = 1.80$ ns
$t_{ADH} = 0.00$ ns
$t_{WENSU} = 2.90$ ns
$t_{BENS} = 2.90$ ns

$t_{ADSU} = 1.80$ ns
$t_{ADH} = 0.00$ ns
$t_{RENSU} = 0.80$ ns
$t_{RCO} = 3.80$ ns

$t_{GHL} = 5.50$ ns
$t_{LSU} = 0.30$ ns
$t_{LH} = 0.00$ ns

Array
Clocks

$F_{MAX} = 151$ MHz
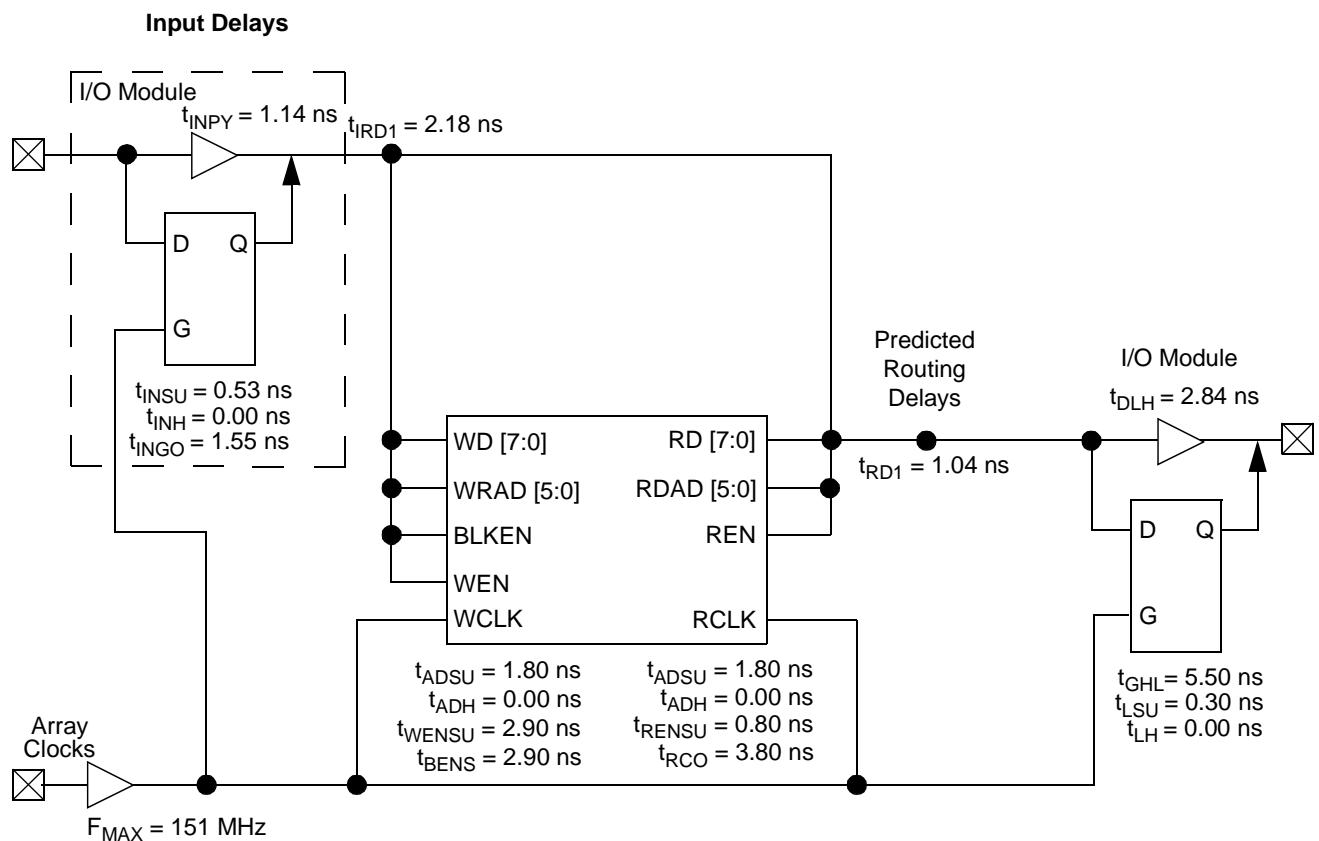
Values are shown for A42MX36 '–2' at 5.0V worst-case commercial conditions.

Parameter Measurement

Output Buffer Delays

AC Test Loads

Load 1
(Used to measure propagation delay)

To the output under test

35 pF

Load 2
(Used to measure rising/falling edges)

V_{CCI} GND

R to V_{CCI} for t_{PLZ}/t_{PZL}
R to GND for t_{PHZ}/t_{PZH}
R = 1 kΩ

To the output under test

35 pF
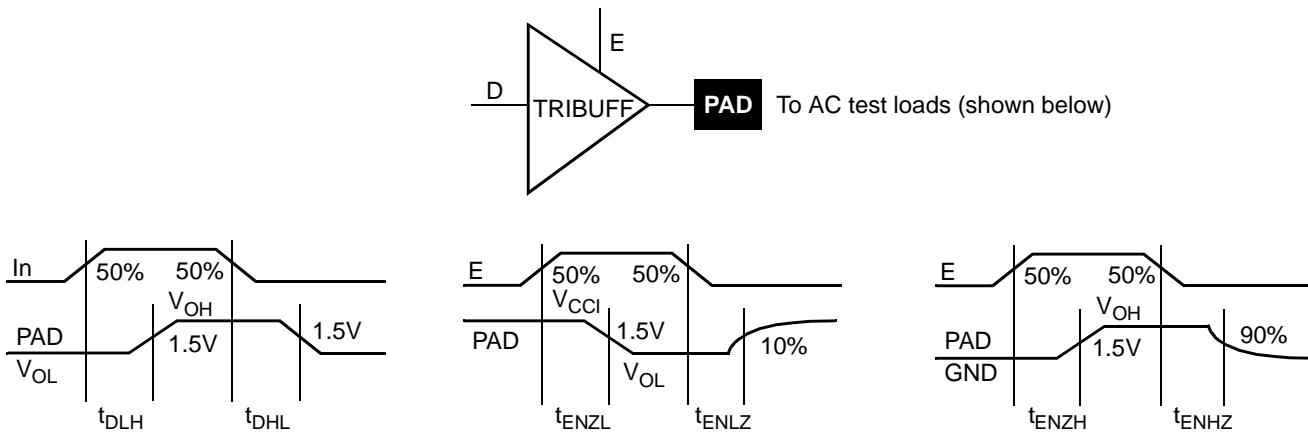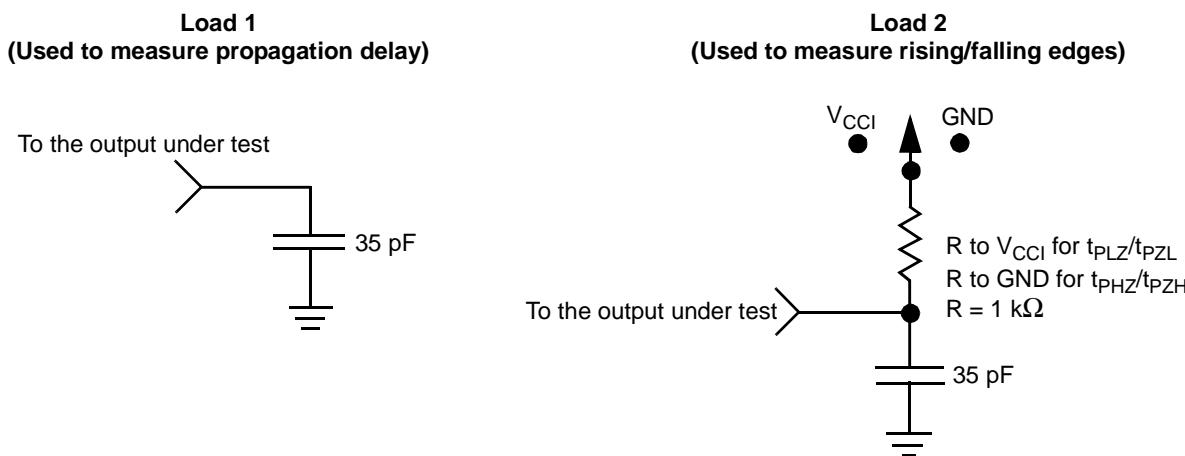
Input Buffer Delays
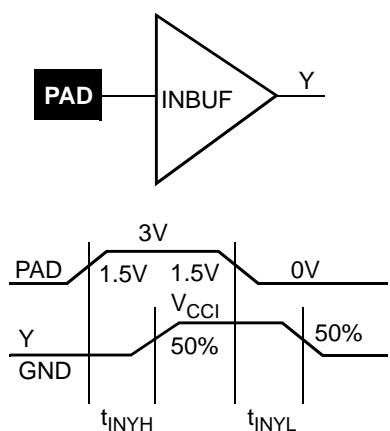
Module Delays
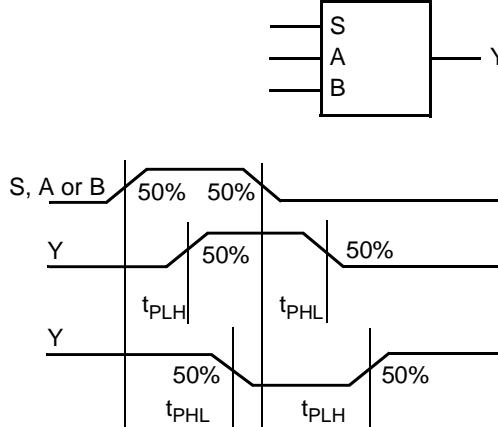
Sequential Module Timing Characteristics

Flip-Flops and Latches

(Positive Edge-Triggered)
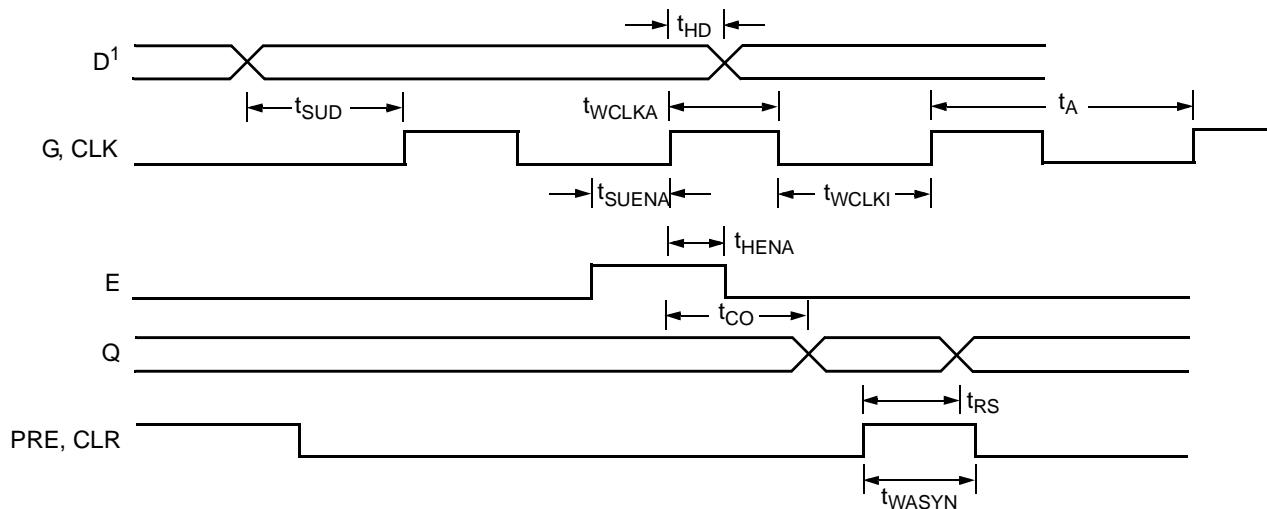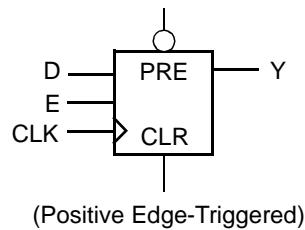
Note: *D represents all data functions involving A, B, and S for multiplexed flip-flops.*

Sequential Timing Characteristics (continued)

Input Buffer Latches
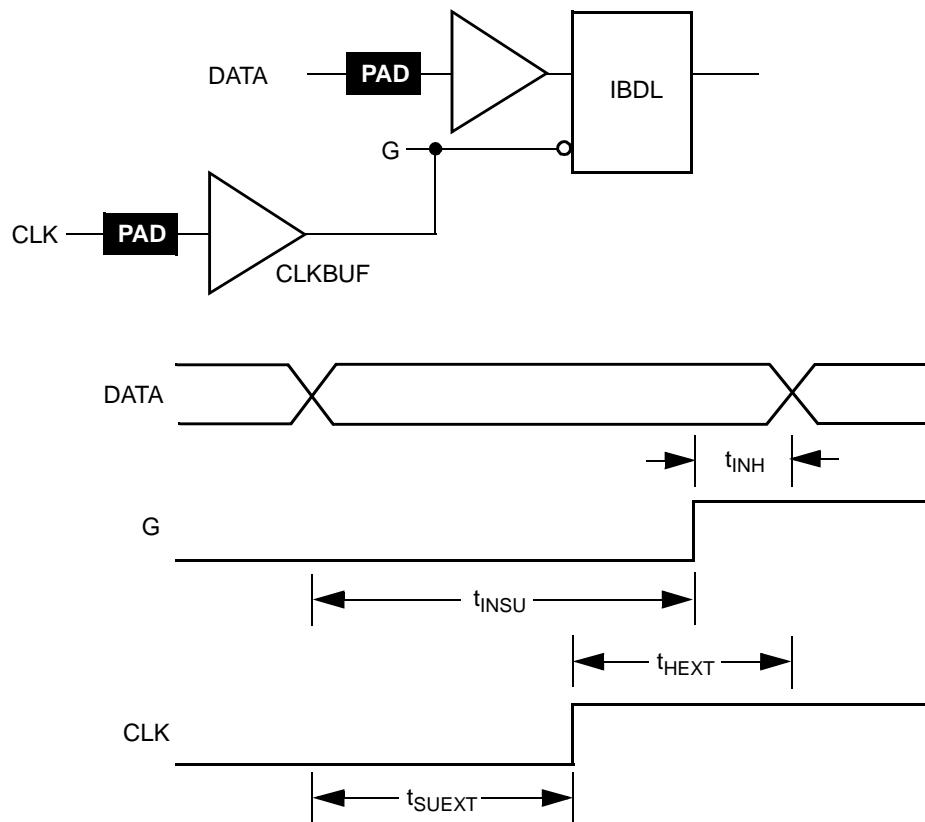
Output Buffer Latches
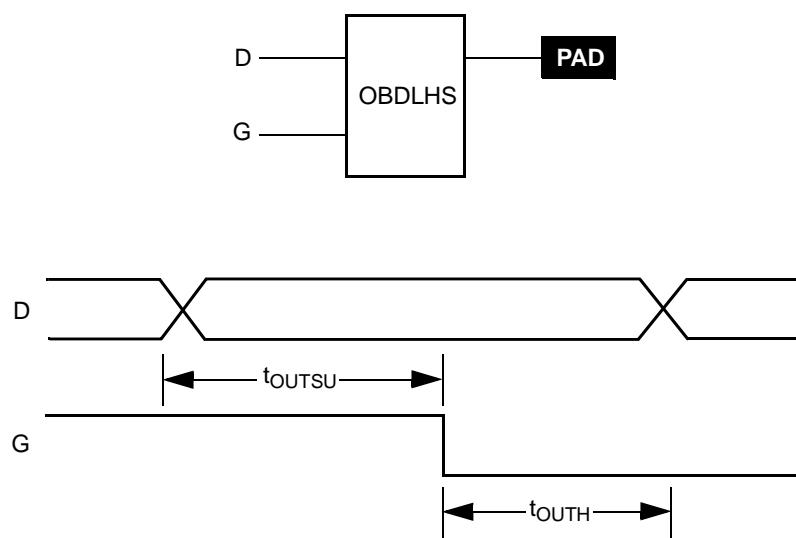
Decode Module Timing
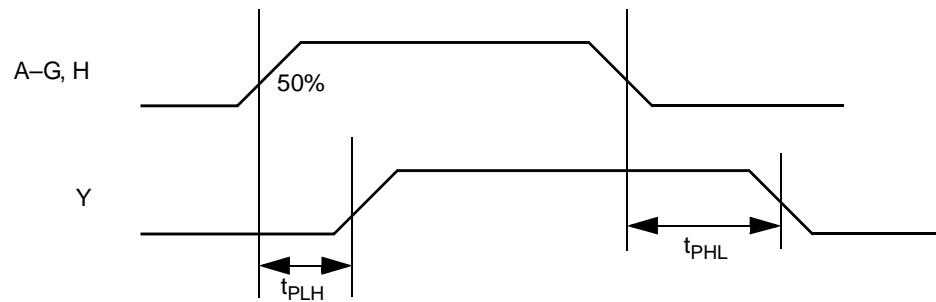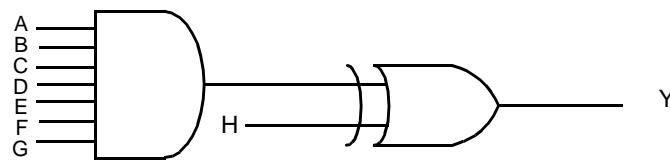
SRAM Timing Characteristics
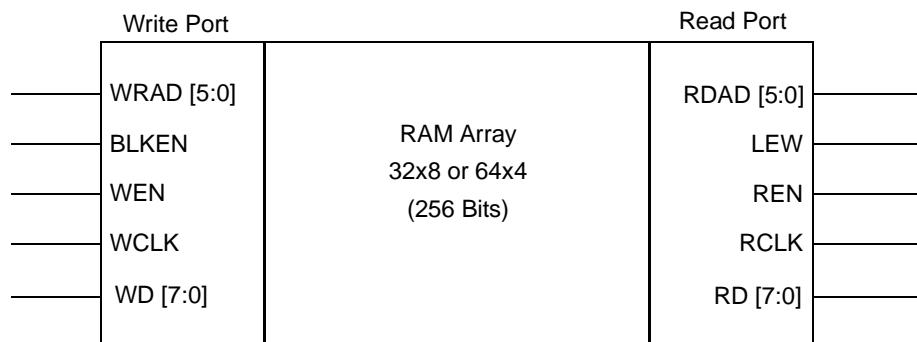
Dual-Port SRAM Timing Waveforms

42MX SRAM Write Operation
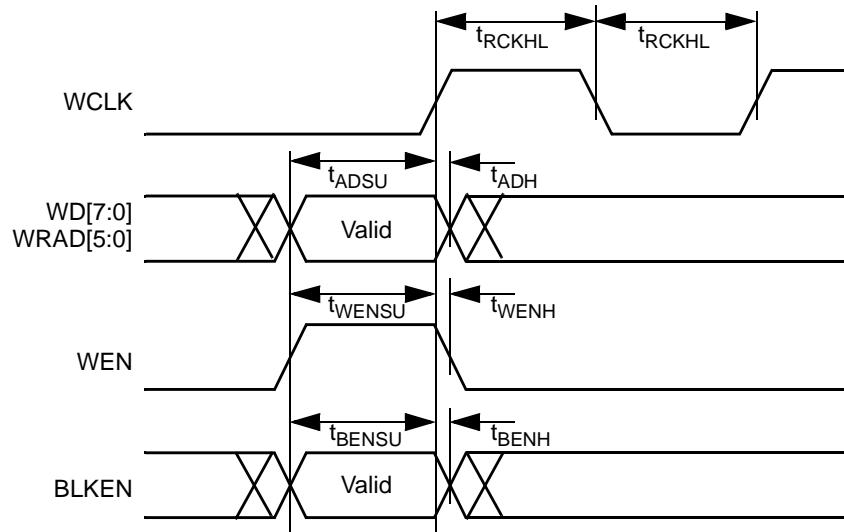
Note: Identical timing for falling edge clock.

42MX SRAM Synchronous Read Operation
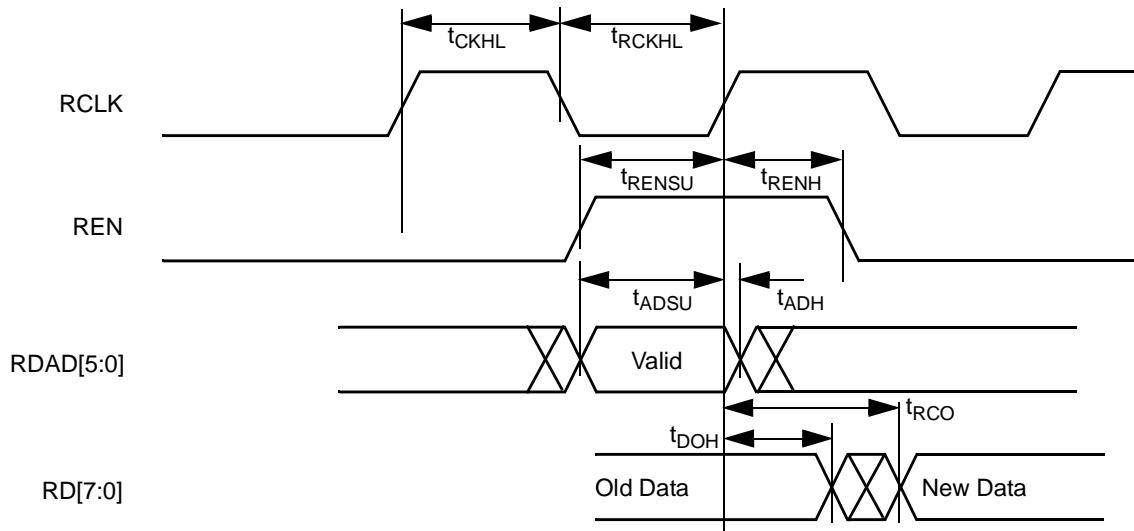
Note: Identical timing for falling edge clock.

42MX SRAM Asynchronous Read Operation—Type 1

(Read Address Controlled)

RDAD[5:0]

t_{RDADV}

ADDR1   ADDR2

t_{RPD}

t_{DOH}

RD[7:0]   Data 1   Data 2
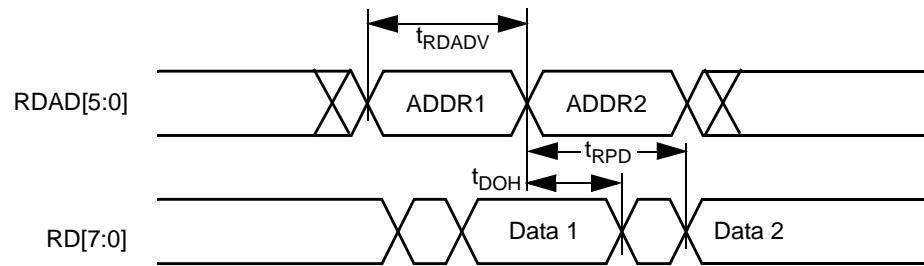
42MX SRAM Asynchronous Read Operation—Type 2

(Write Address Controlled)

WEN

t_{WENSU} t_{WENH}

WD[7:0]
WRAD[5:0]
BLKEN

Valid

t_{ADSU} t_{ADH}

WCLK

t_{RPD}

t_{DOH}

RD[7:0]   Old Data   New Data
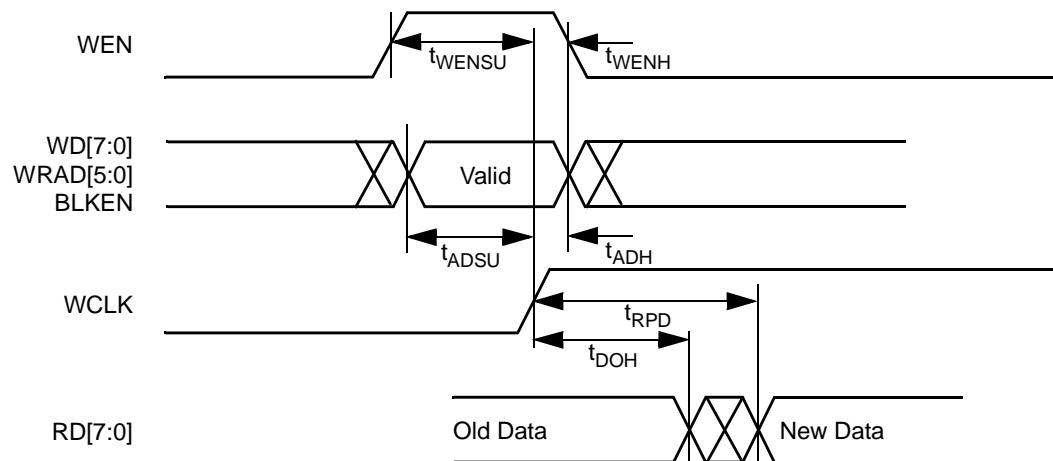
Predictable Performance: Tight Delay Distributions

Propagation delay between logic modules depends on the resistive and capacitive loading of the routing tracks, the interconnect elements, and the module inputs being driven. Propagation delay increases as the length of routing tracks, the number of interconnect elements, or the number of inputs increases.

From a design perspective, the propagation delay can be statistically correlated or modeled by the fanout (number of loads) driven by a module. Higher fanout usually requires some paths to have longer routing tracks.

The MX FPGAs deliver a tight fanout delay distribution, which is achieved in two ways: by decreasing the delay of the interconnect elements and by decreasing the number of interconnect elements per path.

Actel's patented antifuse offers a very low resistive/capacitive interconnect. The antifuses, fabricated in 0.45 µ lithography, offer nominal levels of 100 ¾ resistance and 7.0 femtofarad (fF) capacitance per antifuse.

MX fanout distribution is also tight due to the low number of antifuses required for each interconnect path. The proprietary architecture limits the number of antifuses per path to a maximum of four, with 90 percent of interconnects using only two antifuses.

Timing Characteristics

Device timing characteristics fall into three categories: family-dependent, device-dependent, and design-dependent. The input and output buffer characteristics are common to all MX devices. For mixed voltage of the A42MX devices, the timing numbers are defined in the 3.3V section for I/Os while for the internal logic resources, the timing numbers are defined in the 5.0V section. Internal routing delays are device-dependent. Design dependency means actual delays are not determined until after place-and-route of the user's design is complete. Delay values may then be determined by using the Designer Series utility or by performing simulation with post-layout delays.

Critical Nets and Typical Nets

Propagation delays in this data sheet apply to typical nets. The abundant routing resources in the MX architecture allows for deterministic timing using Actel's Designer Series development tools, which include TDPR, a timing-driven place-and-route tool. Using Timer, the designer can specify timing-critical nets and system clock frequency. Using these timing specifications, the place-and-route software optimizes the layout of the design to meet the user's specifications.

Long Tracks

Some nets in the design use long tracks, which are special routing resources that span multiple rows, columns, or modules. Long tracks employ three and sometimes four antifuse connections, which increase capacitance and resistance, resulting in longer net delays for macros connected to long tracks. Typically, up to 6 percent of nets in a fully utilized device require long tracks. Long tracks add approximately a 3 ns to a 6 ns delay, which is represented statistically in higher fanout (FO=8) routing delays in the data sheet specifications section, beginning on .

Timing Derating

A timing derating factor of 0.45 is used to reflect best-case processing. Note that this factor is relative to the standard speed timing parameters and must be multiplied by the appropriate voltage and temperature derating factors for a given application.

Timing Derating Factors

Commercial to Industrial

	Industrial	
	Min.	Max.
(Commercial Specification) x	0.69	1.11

Commercial Worst-Case to Typical

	Commerical Typical (T_J = 25°C, V_{CC} = 5.0V)
(Commercial, Worst-Case Condition) x	0.85

Note: *This derating factor applies to all routing and propagation delays.*

42MX Temperature and Voltage Derating Factors

(Normalized to T$_J$ = 25°C, V$_{CCA}$/V$_{CCI}$ = 5.0V)

42MX Voltage	Temperature						
	−55°C	**−40°C**	**0°C**	**25°C**	**70°C**	**85°C**	**125°C**
4.50	0.93	0.95	1.05	1.09	1.25	1.29	1.41
4.75	0.88	0.90	1.00	1.03	1.18	1.22	1.34
5.00	0.85	0.87	0.96	1.00	1.15	1.18	1.29
5.25	0.84	0.86	0.95	0.97	1.12	1.14	1.28
5.50	0.83	0.85	0.94	0.96	1.10	1.13	1.26

(Normalized to T$_J$ = 25°C, V$_{CCA}$/V$_{CCI}$ = 5.0V)
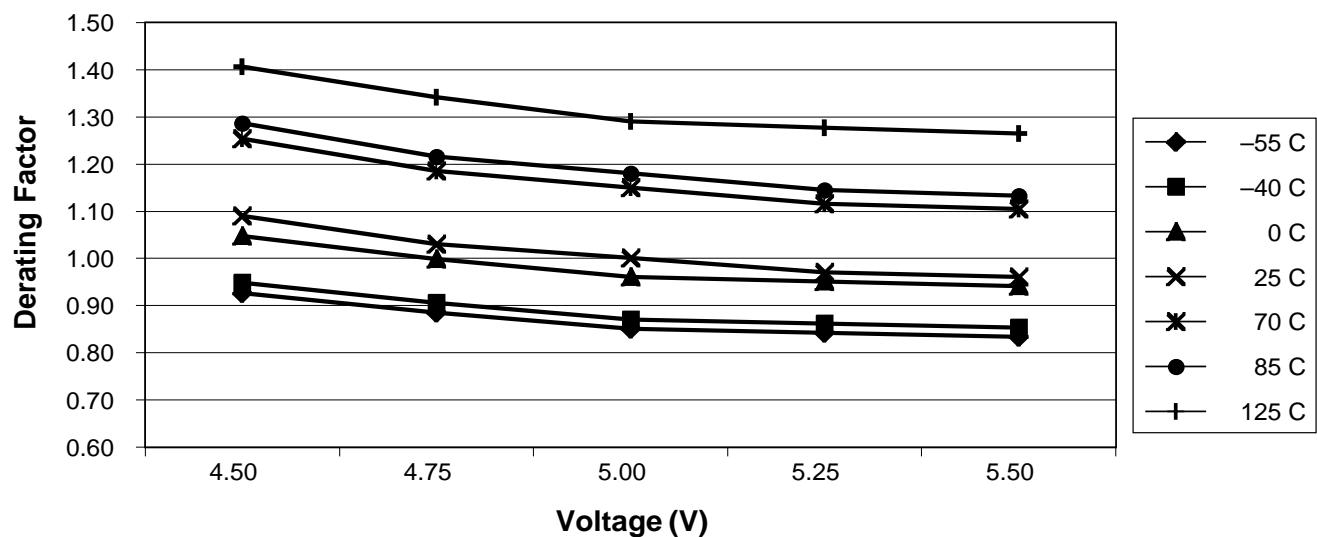
Note: *This derating factor applies to all routing and propagation delays.*

40MX Temperature and Voltage Derating Factors

(Normalized to T$_J$ = 25°C, V$_{CCA}$/V$_{CCI}$ = 5.0V)

40MX Voltage	Temperature						
	−55°C	−40°C	0°C	25°C	70°C	85°C	125°C
4.50	0.89	0.93	1.02	1.09	1.25	1.31	1.45
4.75	0.84	0.88	0.97	1.03	1.18	1.24	1.37
5.00	0.82	0.85	0.94	1.00	1.15	1.20	1.33
5.25	0.80	0.82	0.91	0.97	1.12	1.16	1.29
5.50	0.79	0.82	0.90	0.96	1.10	1.15	1.28

40MX Junction Temperature and Voltage Derating Curves
(Normalized to T$_J$ = 25°C, V$_{CCA}$/V$_{CCI}$ = 5.0V)
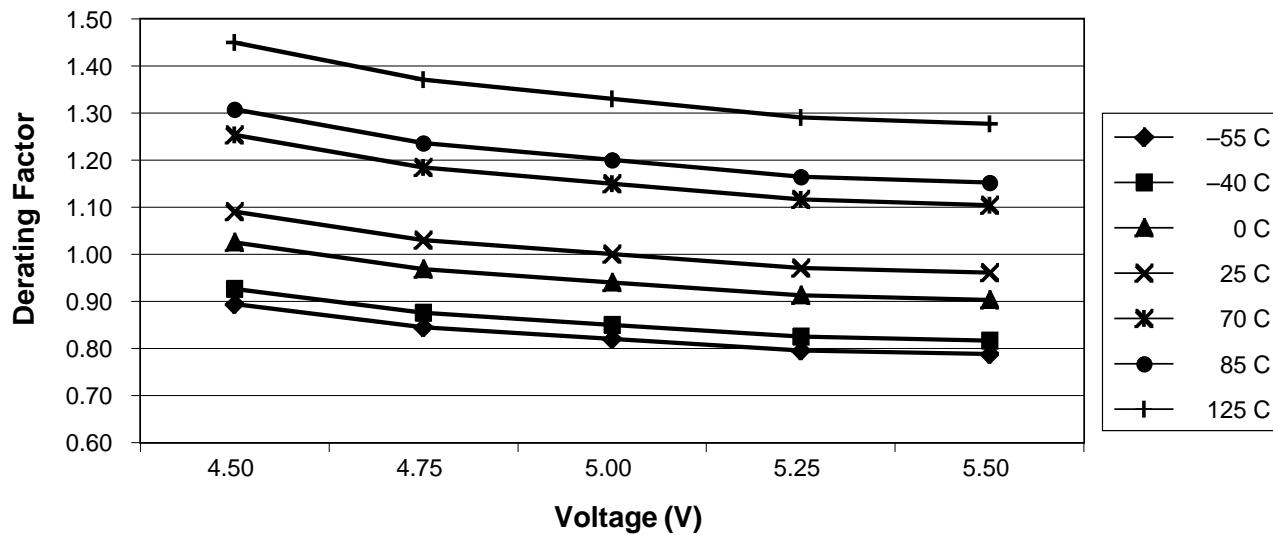
Note: *This derating factor applies to all routing and propagation delays.*

PCI System Timing Specification

Table 3 and Table 4 list the critical PCI timing parameters and the corresponding timing parameter for the MX PCI-compliant devices.

PCI Models

Actel provides synthesizable VHDL and Verilog-HDL models for a PCI Target interface, a PCI Target and Target+DMA Master interface. Contact your Actel sales representative for more details.

Table 3 • Clock Specification for 33 MHz PCI

Symbol	Parameter	PCI		A42MX24		A42MX36		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
T_{CYC}	CLK Cycle Time	30	—	4.0	—	4.0	—	ns
T_{HIGH}	CLK High Time	11	—	1.9	—	1.9	—	ns
T_{LOW}	CLK Low Time	11	—	1.9	—	1.9	—	ns

Table 4 • Timing Parameters for 33 MHz PCI

Symbol	Parameter	PCI		A42MX24		A42MX36		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
T_{VAL}	CLK to Signal Valid—Bused Signals	2	11	2.0	9.0	2.0	9.0	ns
$T_{VAL(PTP)}$	CLK to Signal Valid—Point-to-Point	2	12	2.0	9.0	2.0	9.0	ns
T_{ON}	Float to Active	2	—	2.0	4.0	2.0	4.0	ns
T_{OFF}	Active to Float	—	28	—	8.3[1]	—	8.3[1]	ns
T_{SU}	Input Set-Up Time to CLK—Bused Signals	7	—	1.5	—	1.5	—	ns
$T_{SU(PTP)}$	Input Set-Up Time to CLK—Point-to-Point	10, 12	—	1.5	—	1.5	—	ns
T_H	Input Hold to CLK	0	—	0	—	0	—	ns

Note:

1. T_{OFF} is system dependent. MX PCI devices have 7.4 ns turn-off time, reflection is typically an additional 10 ns.

A40MX02 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays												
t_{PD1}	Single Module		1.2		1.4		1.6		1.9		2.7	ns
t_{PD2}	Dual-Module Macros		2.7		3.1		3.5		4.1		5.7	ns
t_{CO}	Sequential Clock-to-Q		1.2		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch G-to-Q		1.2		1.4		1.6		1.9		2.7	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.2		1.4		1.6		1.9		2.7	ns
Logic Module Predicted Routing Delays[1]												
t_{RD1}	FO=1 Routing Delay		1.3		1.5		1.7		2.0		2.8	ns
t_{RD2}	FO=2 Routing Delay		1.8		2.1		2.4		2.8		3.9	ns
t_{RD3}	FO=3 Routing Delay		2.3		2.7		3.0		3.6		5.0	ns
t_{RD4}	FO=4 Routing Delay		2.9		3.3		3.7		4.4		6.1	ns
t_{RD8}	FO=8 Routing Delay		4.9		5.7		6.5		7.6		10.6	ns
Logic Module Sequential Timing[2]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	3.1		3.5		4.0		4.7		6.6		ns
t_{HD}[3]	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	3.1		3.5		4.0		4.7		6.6		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.3		3.8		4.3		5.0		7.0		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	3.3		3.8		4.3		5.0		7.0		ns
t_A	Flip-Flop Clock Input Period	4.8		5.6		6.3		7.5		10.4		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)		181		168		154		134		80	MHz

Notes:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
2. *Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility.*
3. *The hold time for the DFME1A macro may be greater than 0 ns. Use the Series or later Timer to check the hold time for this macro.*

A40MX02 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			0.7		0.8		0.9		1.1		1.5	ns
t_{INYL}	Pad-to-Y LOW			0.6		0.7		0.8		1.0		1.3	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.1		2.4		2.2		3.2		4.5	ns
t_{IRD2}	FO=2 Routing Delay			2.6		3.0		3.4		4.0		5.6	ns
t_{IRD3}	FO=3 Routing Delay			3.1		3.6		4.1		4.8		6.7	ns
t_{IRD4}	FO=4 Routing Delay			3.6		4.2		4.8		5.6		7.8	ns
t_{IRD8}	FO=8 Routing Delay			5.7		6.6		7.5		8.8		12.4	ns
Global Clock Network													
t_{CKH}	Input Low to HIGH	FO = 16		4.6		5.3		6.0		7.0		9.8	
		FO = 128		4.6		5.3		6.0		7.0		9.8	ns
t_{CKL}	Input High to LOW	FO = 16		4.8		5.6		6.3		7.4		10.4	
		FO = 128		4.8		5.6		6.3		7.4		10.4	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 16	2.2		2.6		2.9		3.4		4.8		
		FO = 128	2.4		2.7		3.1		3.6		5.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 16	2.2		2.6		2.9		3.4		4.8		
		FO = 128	2.4		2.7		3.01		3.6		5.1		ns
t_{CKSW}	Maximum Skew	FO = 16		0.4		0.5		0.5		0.6		0.8	
		FO = 128		0.5		0.6		0.7		0.8		1.2	ns
t_P	Minimum Period	FO = 16	4.7		5.4		6.1		7.2		10.0		
		FO = 128	4.8		5.6		6.3		7.5		10.4		ns
f_{MAX}	Maximum Frequency	FO = 16		188		175		160		139		83	
		FO = 128		181		168		154		134		80	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A40MX02 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.3		3.8		4.3		5.1		7.2	ns
t_{DHL}	Data-to-Pad LOW		4.0		4.6		5.2		6.1		8.6	ns
t_{ENZH}	Enable Pad Z to HIGH		3.7		4.3		4.9		5.8		8.0	ns
t_{ENZL}	Enable Pad Z to LOW		4.7		5.4		6.1		7.2		10.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.9		9.1		10.4		12.2		17.1	ns
t_{ENLZ}	Enable Pad LOW to Z		5.9		6.8		7.7		9.0		12.6	ns
d_{TLH}	Delta LOW to HIGH		0.02		0.02		0.03		0.03		0.04	ns/pF
d_{THL}	Delta HIGH to LOW		0.03		0.03		0.03		0.04		0.06	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.9		4.5		5.1		6.05		8.5	ns
t_{DHL}	Data-to-Pad LOW		3.4		3.9		4.4		5.2		7.3	ns
t_{ENZH}	Enable Pad Z to HIGH		3.4		3.9		4.4		5.2		7.3	ns
t_{ENZL}	Enable Pad Z to LOW		4.9		5.6		6.4		7.5		10.5	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.9		9.1		10.4		12.2		17.0	ns
t_{ENLZ}	Enable Pad LOW to Z		5.9		6.8		7.7		9.0		12.6	ns
d_{TLH}	Delta LOW to HIGH		0.03		0.04		0.04		0.05		0.07	ns/pF
d_{THL}	Delta HIGH to LOW		0.02		0.02		0.03		0.03		0.04	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A40MX02 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays												
t_{PD1}	Single Module		1.7		2.0		2.3		2.7		3.7	ns
t_{PD2}	Dual-Module Macros		3.7		4.3		4.9		5.7		8.0	ns
t_{CO}	Sequential Clock-to-Q		1.7		2.0		2.3		2.7		3.7	ns
t_{GO}	Latch G-to-Q		1.7		2.0		2.3		2.7		3.7	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.7		2.0		2.3		2.7		3.7	ns
Logic Module Predicted Routing Delays[1]												
t_{RD1}	FO=1 Routing Delay		2.0		2.2		2.5		3.0		4.2	ns
t_{RD2}	FO=2 Routing Delay		2.7		3.1		3.5		4.1		5.7	ns
t_{RD3}	FO=3 Routing Delay		3.4		3.9		4.4		5.2		7.3	ns
t_{RD4}	FO=4 Routing Delay		4.2		4.8		5.4		6.3		8.9	ns
t_{RD8}	FO=8 Routing Delay		7.1		8.2		9.2		10.9		15.2	ns
Logic Module Sequential Timing[2]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	4.3		4.9		5.6		6.6		9.2		ns
t_{HD}[3]	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	4.3		4.9		5.6		6.6		9.2		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.6		5.3		6.0		7.0		9.8		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.6		5.3		6.0		7.0		9.8		ns
t_A	Flip-Flop Clock Input Period	6.8		7.8		8.9		10.4		14.6		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)		109		101		92		80		48	MHz

Notes:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
2. *Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility.*
3. *The hold time for the DFME1A macro may be greater than 0 ns. Use the Series or later Timer to check the hold time for this macro.*

A40MX02 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.0		1.1		1.3		1.5		2.1	ns
t_{INYL}	Pad-to-Y LOW			0.9		1.0		1.1		1.3		1.9	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.9		3.4		3.8		4.5		6.3	ns
t_{IRD2}	FO=2 Routing Delay			3.6		4.2		4.8		5.6		7.8	ns
t_{IRD3}	FO=3 Routing Delay			4.4		5.0		5.7		6.7		9.4	ns
t_{IRD4}	FO=4 Routing Delay			5.1		5.9		6.7		7.8		11.0	ns
t_{IRD8}	FO=8 Routing Delay			8.0		9.26		10.5		12.6		17.3	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 16 FO = 128		6.4 6.4		7.4 7.4		8.3 8.3		9.8 9.8		13.7 13.7	ns
t_{CKL}	Input HIGH to LOW	FO = 16 FO = 128		6.7 6.7		7.8 7.8		8.8 8.8		10.4 10.4		14.5 14.5	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 16 FO = 128	3.1 3.3		3.6 3.8		4.1 4.3		4.8 5.1		6.7 7.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 16 FO = 128	3.1 3.3		3.6 3.8		4.1 4.3		4.8 5.1		6.7 7.1		ns
t_{CKSW}	Maximum Skew	FO = 16 FO = 128		0.6 0.8		0.6 0.9		0.7 1.0		0.8 1.2		1.2 1.6	ns
t_P	Minimum Period	FO = 16 FO = 128	6.5 6.8		7.5 7.8		8.5 8.9		10.1 10.4		14.1 14.6		ns
f_{MAX}	Maximum Frequency	FO = 16 FO = 128		113 109		105 101		96 92		83 80		50 48	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A40MX02 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		4.7		5.4		6.1		7.2		10.0	ns
t_{DHL}	Data-to-Pad LOW		5.6		6.4		7.3		8.6		12.0	ns
t_{ENZH}	Enable Pad Z to HIGH		5.2		6.0		6.8		8.1		11.3	ns
t_{ENZL}	Enable Pad Z to LOW		6.6		7.6		8.6		10.1		14.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		11.1		12.8		14.5		17.1		23.9	ns
t_{ENLZ}	Enable Pad LOW to Z		8.2		9.5		10.7		12.6		17.7	ns
d_{TLH}	Delta LOW to HIGH		0.03		0.03		0.04		0.04		0.06	ns/pF
d_{THL}	Delta HIGH to LOW		0.04		0.04		0.05		0.06		0.08	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		5.5		6.4		7.2		8.5		11.9	ns
t_{DHL}	Data-to-Pad LOW		4.8		5.5		6.2		7.3		10.2	ns
t_{ENZH}	Enable Pad Z to HIGH		4.7		5.5		6.2		7.3		10.2	ns
t_{ENZL}	Enable Pad Z to LOW		6.8		7.9		8.9		10.5		14.7	ns
t_{ENHZ}	Enable Pad HIGH to Z		11.1		12.8		14.5		17.1		23.9	ns
t_{ENLZ}	Enable Pad LOW to Z		8.2		9.5		10.7		12.6		17.7	ns
d_{TLH}	Delta LOW to HIGH		0.05		0.05		0.06		0.07		0.10	ns/pF
d_{THL}	Delta HIGH to LOW		0.03		0.03		0.04		0.04		0.06	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A40MX04 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays												
t_{PD1}	Single Module		1.2		1.4		1.6		1.9		2.7	ns
t_{PD2}	Dual-Module Macros		2.3		3.1		3.5		4.1		5.7	ns
t_{CO}	Sequential Clock-to-Q		1.2		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch G-to-Q		1.2		1.4		1.6		1.9		2.7	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.2		1.4		1.6		1.9		2.7	ns
Logic Module Predicted Routing Delays[1]												
t_{RD1}	FO=1 Routing Delay		1.2		1.6		1.8		2.1		3.0	ns
t_{RD2}	FO=2 Routing Delay		1.9		2.2		2.5		2.9		4.1	ns
t_{RD3}	FO=3 Routing Delay		2.4		2.8		3.2		3.7		5.2	ns
t_{RD4}	FO=4 Routing Delay		2.9		3.4		3.9		4.5		6.3	ns
t_{RD8}	FO=8 Routing Delay		5.0		5.8		6.6		7.8		10.9	ns
Logic Module Sequential Timing[2]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	3.1		3.5		4.0		4.7		6.6		ns
t_{HD}[3]	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	3.1		3.5		4.0		4.7		6.6		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.3		3.8		4.3		5.0		7.0		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	3.3		3.8		4.3		5.0		7.0		ns
t_A	Flip-Flop Clock Input Period	4.8		5.6		6.3		7.5		10.4		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)		181		167		154		134		80	MHz

Notes:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

2. *Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility.*

3. *The hold time for the DFME1A macro may be greater than 0 ns. Use the Series or later Timer to check the hold time for this macro.*

A40MX04 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			0.7		0.8		0.9		1.1		1.5	ns
t_{INYL}	Pad-to-Y LOW			0.6		0.7		0.8		1.0		1.3	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.1		2.4		2.2		3.2		4.5	ns
t_{IRD2}	FO=2 Routing Delay			2.6		3.0		3.4		4.0		5.6	ns
t_{IRD3}	FO=3 Routing Delay			3.1		3.6		4.1		4.8		6.7	ns
t_{IRD4}	FO=4 Routing Delay			3.6		4.2		4.8		5.6		7.8	ns
t_{IRD8}	FO=8 Routing Delay			5.7		6.6		7.5		8.8		12.4	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 16 FO = 128		4.6 4.6		5.3 5.3		6.0 6.0		7.1 7.1		9.9 9.9	ns
t_{CKL}	Input HIGH to LOW	FO = 16 FO = 128		4.8 4.8		5.6 5.6		6.3 6.3		7.5 7.5		10.4 10.4	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 16 FO = 128	2.2 2.4		2.6 2.7		2.9 3.1		3.4 3.6		4.8 5.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 16 FO = 128	2.2 2.4		2.6 2.7		2.9 3.1		3.4 3.6		4.8 5.1		ns
t_{CKSW}	Maximum Skew	FO = 16 FO = 128		0.4 0.5		0.5 0.6		0.5 0.7		0.6 0.8		0.8 1.2	ns
t_P	Minimum Period	FO = 16 FO = 128	4.7 4.8		5.4 5.6		6.1 6.3		7.2 7.5		10.1 10.4		ns
f_{MAX}	Maximum Frequency	FO = 16 FO = 128		188 181		175 168		160 154		139 134		83 80	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A40MX04 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.3		3.8		4.3		5.1		7.2	ns
t_{DHL}	Data-to-Pad LOW		4.0		4.6		5.2		6.1		8.6	ns
t_{ENZH}	Enable Pad Z to HIGH		3.7		4.3		4.9		5.8		8.1	ns
t_{ENZL}	Enable Pad Z to LOW		4.7		5.4		6.1		7.2		10.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.9		9.1		10.4		12.2		17.1	ns
t_{ENLZ}	Enable Pad LOW to Z		5.9		6.8		7.7		9.0		12.6	ns
d_{TLH}	Delta LOW to HIGH		0.02		0.02		0.03		0.03		0.04	ns/pF
d_{THL}	Delta HIGH to LOW		0.02		0.03		0.03		0.04		0.06	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.9		4.5		5.1		6.1		8.5	ns
t_{DHL}	Data-to-Pad LOW		3.4		3.9		4.4		5.2		7.3	ns
t_{ENZH}	Enable Pad Z to HIGH		3.4		3.9		4.4		5.2		7.3	ns
t_{ENZL}	Enable Pad Z to LOW		4.9		5.6		6.4		7.5		10.5	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.9		9.1		10.4		12.2		17.1	ns
t_{ENLZ}	Enable Pad LOW to Z		5.0		6.8		7.7		9.0		12.6	ns
d_{TLH}	Delta LOW to HIGH		0.03		0.04		0.04		0.05		0.07	ns/pF
d_{THL}	Delta HIGH to LOW		0.02		0.02		0.03		0.03		0.04	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A40MX04 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays												
t_{PD1}	Single Module		1.7		2.0		2.3		2.7		3.7	ns
t_{PD2}	Dual-Module Macros		3.7		4.3		4.9		5.7		8.0	ns
t_{CO}	Sequential Clock-to-Q		1.7		2.0		2.3		2.7		3.7	ns
t_{GO}	Latch G-to-Q		1.7		2.0		2.3		2.7		3.7	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.7		2.0		2.3		2.7		3.7	ns
Logic Module Predicted Routing Delays[1]												
t_{RD1}	FO=1 Routing Delay		1.9		2.2		2.5		3.0		4.2	ns
t_{RD2}	FO=2 Routing Delay		2.7		3.1		3.5		4.1		5.7	ns
t_{RD3}	FO=3 Routing Delay		3.4		3.9		4.4		5.2		7.3	ns
t_{RD4}	FO=4 Routing Delay		4.1		4.8		5.4		6.3		8.9	ns
t_{RD8}	FO=8 Routing Delay		7.1		8.1		9.2		10.9		15.2	ns
Logic Module Sequential Timing[2]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	4.3		5.0		5.6		6.6		9.2		ns
t_{HD}[3]	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	4.3		5.0		5.6		6.6		9.2		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.6		5.3		5.6		7.0		9.8		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.6		5.3		5.6		7.0		9.8		ns
t_A	Flip-Flop Clock Input Period	6.8		7.8		8.9		10.4		14.6		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)		109		101		92		80		48	MHz

Notes:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
2. *Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility.*
3. *The hold time for the DFME1A macro may be greater than 0 ns. Use the Series or later Timer to check the hold time for this macro.*

A40MX04 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.0		1.1		1.3		1.5		2.1	ns
t_{INYL}	Pad-to-Y LOW			0.9		1.0		1.1		1.3		1.9	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.9		3.34		3.8		4.5		6.3	ns
t_{IRD2}	FO=2 Routing Delay			3.6		4.2		4.8		5.6		7.8	ns
t_{IRD3}	FO=3 Routing Delay			4.4		5.0		5.7		6.7		9.4	ns
t_{IRD4}	FO=4 Routing Delay			5.1		5.9		6.7		7.8		11.0	ns
t_{IRD8}	FO=8 Routing Delay			8.0		9.3		10.5		12.4		17.2	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 16		6.4		7.4		8.4		9.9		13.8	
		FO = 128		6.4		7.4		8.4		9.9		13.8	ns
t_{CKL}	Input HIGH to LOW	FO = 16		6.8		7.8		8.9		10.4		14.6	
		FO = 128		6.8		7.8		8.9		10.4		14.6	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 16	3.1		3.6		4.1		4.8		6.7		
		FO = 128	3.3		3.8		4.3		5.1		7.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 16	3.1		3.6		4.1		4.8		6.7		
		FO = 128	3.3		3.8		4.3		5.1		7.1		ns
t_{CKSW}	Maximum Skew	FO = 16		0.6		0.6		0.7		0.8		1.2	
		FO = 128		0.8		0.9		1.0		1.2		1.6	ns
t_P	Minimum Period	FO = 16	6.5		7.5		8.5		10.1		14.1		
		FO = 128	6.8		7.8		8.9		10.4		14.6		ns
f_{MAX}	Maximum Frequency	FO = 16		113		105		96		83		50	
		FO = 128		109		101		92		80		48	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A40MX04 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		4.7		5.4		6.1		7.2		10.0	ns
t_{DHL}	Data-to-Pad LOW		5.6		6.4		7.3		8.6		12.0	ns
t_{ENZH}	Enable Pad Z to HIGH		5.2		6.0		6.9		8.1		11.3	ns
t_{ENZL}	Enable Pad Z to LOW		6.6		7.6		8.6		10.1		14.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		11.1		12.8		14.5		17.1		23.9	ns
t_{ENLZ}	Enable Pad LOW to Z		8.2		9.5		10.7		12.6		17.7	ns
d_{TLH}	Delta LOW to HIGH		0.03		0.03		0.04		0.04		0.06	ns/pF
d_{THL}	Delta HIGH to LOW		0.04		0.04		0.05		0.06		0.08	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		5.5		6.4		7.2		8.5		11.9	ns
t_{DHL}	Data-to-Pad LOW		4.8		5.5		6.2		7.3		10.2	ns
t_{ENZH}	Enable Pad Z to HIGH		4.7		5.5		6.2		7.3		10.2	ns
t_{ENZL}	Enable Pad Z to LOW		6.8		7.9		8.9		10.5		14.7	ns
t_{ENHZ}	Enable Pad HIGH to Z		11.1		12.8		14.5		17.1		23.9	ns
t_{ENLZ}	Enable Pad LOW to Z		8.2		9.5		10.7		12.6		17.7	ns
d_{TLH}	Delta LOW to HIGH		0.05		0.05		0.06		0.07		0.10	ns/pF
d_{THL}	Delta HIGH to LOW		0.03		0.03		0.04		0.04		0.06	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX09 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays[1]												
t_{PD1}	Single Module		1.2		1.3		1.5		1.8		2.5	ns
t_{CO}	Sequential Clock-to-Q		1.3		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch G-to-Q		1.2		1.4		1.6		1.8		2.6	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.2		1.6		1.8		2.1		2.9	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		0.7		0.8		0.9		1.0		1.4	ns
t_{RD2}	FO=2 Routing Delay		0.9		1.0		1.2		1.4		1.9	ns
t_{RD3}	FO=3 Routing Delay		1.2		1.3		1.5		1.7		2.4	ns
t_{RD4}	FO=4 Routing Delay		1.4		1.5		1.7		2.0		2.9	ns
t_{RD8}	FO=8 Routing Delay		2.3		2.6		2.9		3.4		4.8	ns
Logic Module Sequential Timing[3, 4]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.3		0.4		0.4		0.5		0.7		ns
t_{HD}	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.4		0.5		0.5		0.6		0.8		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.4		3.8		4.3		5.0		7.0		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.5		4.9		5.6		6.6		9.2		ns
t_A	Flip-Flop Clock Input Period	3.5		3.8		4.3		5.1		7.1		ns
t_{INH}	Input Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Buffer Latch Set-Up	0.3		0.3		0.4		0.4		0.6		ns
t_{OUTH}	Output Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{OUTSU}	Output Buffer Latch Set-Up	0.3		0.3		0.4		0.4		0.6		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency		268		244		224		195		117	MHz

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*
2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*
4. *Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX09 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.0		1.2		1.3		1.6		2.2	ns
t_{INYL}	Pad-to-Y LOW			0.8		0.9		1.0		1.2		1.7	ns
t_{INGH}	G to Y HIGH			1.3		1.4		1.6		1.9		2.7	ns
t_{INGL}	G to Y LOW			1.3		1.4		1.6		1.9		2.7	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.0		2.2		2.5		3.0		4.2	ns
t_{IRD2}	FO=2 Routing Delay			2.3		2.5		2.9		3.4		4.7	ns
t_{IRD3}	FO=3 Routing Delay			2.5		2.8		3.2		3.7		5.2	ns
t_{IRD4}	FO=4 Routing Delay			2.8		3.1		3.5		4.1		5.7	ns
t_{IRD8}	FO=8 Routing Delay			3.7		4.1		4.7		5.5		7.7	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 32		2.4		2.7		3.0		3.6		5.0	ns
		FO = 256		2.7		3.0		3.4		4.0		5.5	ns
t_{CKL}	Input HIGH to LOW	FO = 32		3.5		3.9		4.4		5.2		7.3	ns
		FO = 256		3.9		4.3		4.9		5.7		8.0	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 32	1.2		1.4		1.5		1.8		2.5		ns
		FO = 256	1.3		1.5		1.7		2.0		2.7		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 32	1.2		1.4		1.5		1.8		2.5		ns
		FO = 256	1.3		1.5		1.7		2.0		2.7		ns
t_{CKSW}	Maximum Skew	FO = 32		0.3		0.3		0.4		0.5		0.6	ns
		FO = 256		0.3		0.3		0.4		0.5		0.6	ns
t_{SUEXT}	Input Latch External Set-Up	FO = 32	0.0		0.0		0.0		0.0		0.0		ns
		FO = 256	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO = 32	2.3		2.6		3.0		3.5		4.9		ns
		FO = 256	2.2		2.4		3.3		3.9		5.5		ns
t_P	Minimum Period	FO = 32	3.4		3.7		4.0		4.7		7.8		ns
		FO = 256	3.7		4.1		4.5		5.2		8.6		ns
f_{MAX}	Maximum Frequency	FO = 32		296		269		247		215		129	MHz
		FO = 256		268		244		224		195		117	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX09 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		2.5		2.7		3.1		3.6		5.1	ns
t_{DHL}	Data-to-Pad LOW		2.9		3.2		3.6		4.3		6.0	ns
t_{ENZH}	Enable Pad Z to HIGH		2.6		2.9		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		2.9		3.2		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		4.9		5.4		6.2		7.3		10.2	ns
t_{ENLZ}	Enable Pad LOW to Z		5.3		5.9		6.7		7.9		11.1	ns
t_{GLH}	G-to-Pad HIGH		2.6		2.9		3.3		3.8		5.3	ns
t_{GHL}	G-to-Pad LOW		2.6		2.9		3.3		3.8		5.3	ns
t_{LSU}	I/O Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		5.2		5.8		6.6		7.7		10.8	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		7.4		8.2		9.3		10.9		15.3	ns
d_{TLH}	Capacity Loading, LOW to HIGH		0.03		0.03		0.03		0.04		0.06	ns/pF
d_{THL}	Capacity Loading, HIGH to LOW		0.04		0.04		0.04		0.05		0.07	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		2.4		2.7		3.1		3.6		5.1	ns
t_{DHL}	Data-to-Pad LOW		2.9		3.2		3.6		4.3		6.0	ns
t_{ENZH}	Enable Pad Z to HIGH		2.7		2.9		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		2.9		3.2		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		4.9		5.4		6.2		7.3		10.2	ns
t_{ENLZ}	Enable Pad LOW to Z		5.3		5.9		6.7		7.9		11.1	ns
t_{GLH}	G-to-Pad HIGH		4.2		4.6		5.2		6.1		8.6	ns
t_{GHL}	G-to-Pad LOW		4.2		4.6		5.2		6.1		8.6	ns
t_{LSU}	I/O Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		5.2		5.8		6.6		7.7		10.8	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		7.4		8.2		9.3		10.9		15.3	ns
d_{TLH}	Capacity Loading, LOW to HIGH		0.03		0.03		0.03		0.04		0.06	ns/pF
d_{THL}	Capacity Loading, HIGH to LOW		0.04		0.04		0.04		0.05		0.07	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX09 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays[1]												
t_{PD1}	Single Module		1.6		1.8		2.1		2.5		3.5	ns
t_{CO}	Sequential Clock-to-Q		1.8		2.0		2.3		2.7		3.8	ns
t_{GO}	Latch G-to-Q		1.7		1.9		2.1		2.5		3.5	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		2.0		2.2		2.5		2.9		4.1	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		1.0		1.1		1.2		1.4		2.0	ns
t_{RD2}	FO=2 Routing Delay		1.3		1.4		1.6		1.9		2.7	ns
t_{RD3}	FO=3 Routing Delay		1.6		1.8		2.0		2.4		3.3	ns
t_{RD4}	FO=4 Routing Delay		1.9		2.1		2.4		2.9		4.0	ns
t_{RD8}	FO=8 Routing Delay		3.2		3.6		4.1		4.8		6.7	ns
Logic Module Sequential Timing [3, 4]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.5		0.5		0.6		0.7		0.9		ns
t_{HD}	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.6		0.6		0.7		0.8		1.2		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.7		5.3		6.0		7.0		9.8		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.2		6.9		7.8		9.2		12.9		ns
t_A	Flip-Flop Clock Input Period	5.0		5.6		6.2		7.1		9.9		ns
t_{INH}	Input Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Buffer Latch Set-Up	0.3		0.3		0.3		0.4		0.6		ns
t_{OUTH}	Output Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{OUTSU}	Output Buffer Latch Set-Up	0.3		0.3		0.3		0.4		0.6		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency		161		146		135		117		70	MHz

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX09 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.5		1.6		1.8		2.17		3.0	ns
t_{INYL}	Pad-to-Y LOW			1.2		1.3		1.4		1.7		2.4	ns
t_{INGH}	G to Y HIGH			1.8		2.0		2.3		2.7		3.7	ns
t_{INGL}	G to Y LOW			1.8		2.0		2.3		2.7		3.7	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.8		3.2		3.6		4.2		5.9	ns
t_{IRD2}	FO=2 Routing Delay			3.2		3.5		4.0		4.7		6.6	ns
t_{IRD3}	FO=3 Routing Delay			3.5		3.9		4.4		5.2		7.3	ns
t_{IRD4}	FO=4 Routing Delay			3.9		4.3		4.9		5.7		8.0	ns
t_{IRD8}	FO=8 Routing Delay			5.2		5.8		6.6		7.7		10.8	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 32		4.1		4.5		5.1		6.0		8.4	ns
		FO = 256		4.5		5.0		5.6		6.7		9.3	ns
t_{CKL}	Input HIGH to LOW	FO = 32		5.0		5.5		6.2		7.3		10.2	ns
		FO = 256		5.4		6.0		6.8		8.0		11.2	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 32	1.7		1.9		2.1		2.5		3.5		ns
		FO = 256	1.9		2.1		2.3		2.7		3.8		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 32	1.7		1.9		2.1		2.5		3.5		ns
		FO = 256	1.9		2.1		2.3		2.7		3.8		ns
t_{CKSW}	Maximum Skew	FO = 32		0.4		0.5		0.5		0.6		0.9	ns
		FO = 256		0.4		0.5		0.5		0.6		0.9	ns
t_{SUEXT}	Input Latch External Set-Up	FO = 32	0.0		0.0		0.0		0.0		0.0		ns
		FO = 256	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO = 32	3.3		3.7		4.2		4.9		6.9		ns
		FO = 256	3.7		4.1		4.6		5.5		7.6		ns
t_P	Minimum Period	FO = 32	5.6		6.2		6.7		7.8		12.9		ns
		FO = 256	6.1		6.8		7.4		8.5		14.2		ns
f_{MAX}	Maximum Frequency	FO = 32		177		161		148		129		77	MHz
		FO = 256		161		146		135		117		70	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX09 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.4		3.8		4.3		5.1		7.1	ns
t_{DHL}	Data-to-Pad LOW		4.0		4.5		5.1		6.1		8.3	ns
t_{ENZH}	Enable Pad Z to HIGH		3.7		4.1		4.6		5.5		7.6	ns
t_{ENZL}	Enable Pad Z to LOW		4.1		4.5		5.1		6.1		8.5	ns
t_{ENHZ}	Enable Pad HIGH to Z		6.9		7.6		8.6		10.2		14.2	ns
t_{ENLZ}	Enable Pad LOW to Z		7.5		8.3		9.4		11.1		15.5	ns
t_{GLH}	G-to-Pad HIGH		5.8		6.5		7.3		8.6		12.0	ns
t_{GHL}	G-to-Pad LOW		5.8		6.5		7.3		8.6		12.0	ns
t_{LSU}	I/O Latch Set-Up	0.7		0.8		0.9		1.0		1.4		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.7		9.7		10.9		12.9		18.0	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		12.2		13.5		15.4		18.1		25.3	ns
d_{TLH}	Capacity Loading, LOW to HIGH		0.00		0.00		0.00		0.10		0.01	ns/pF
d_{THL}	Capacity Loading, HIGH to LOW		0.09		0.10		0.10		0.10		0.10	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.4		3.8		5.5		6.4		9.0	ns
t_{DHL}	Data-to-Pad LOW		4.1		4.5		4.2		5.0		7.0	ns
t_{ENZH}	Enable Pad Z to HIGH		3.7		4.1		4.6		5.5		7.6	ns
t_{ENZL}	Enable Pad Z to LOW		4.1		4.5		5.1		6.1		8.5	ns
t_{ENHZ}	Enable Pad HIGH to Z		6.9		7.6		8.6		10.2		14.2	ns
t_{ENLZ}	Enable Pad LOW to Z		7.5		8.3		9.4		11.1		15.5	ns
t_{GLH}	G-to-Pad HIGH		5.8		6.5		7.3		8.6		12.0	ns
t_{GHL}	G-to-Pad LOW		5.8		6.5		7.3		8.6		12.0	ns
t_{LSU}	I/O Latch Set-Up	0.7		0.8		0.9		1.0		1.4		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.7		9.7		10.9		12.9		18.0	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		12.2		13.5		15.4		18.1		25.3	ns
d_{TLH}	Capacity Loading, LOW to HIGH		0.04		0.04		0.05		0.06		0.08	ns/pF
d_{THL}	Capacity Loading, HIGH to LOW		0.05		0.05		0.06		0.07		0.10	ns/pF

Note:

1. Delays based on 35 pF loading.

A42MX16 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays[1]												
t_{PD1}	Single Module		1.4		1.5		1.7		2.0		2.8	ns
t_{CO}	Sequential Clock-to-Q		1.4		1.6		1.8		2.1		3.0	ns
t_{GO}	Latch G-to-Q		1.4		1.5		1.7		2.0		2.8	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		1.6		1.7		2.0		2.3		3.3	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		0.8		0.9		1.0		1.2		1.6	ns
t_{RD2}	FO=2 Routing Delay		1.0		1.2		1.3		1.5		2.1	ns
t_{RD3}	FO=3 Routing Delay		1.3		1.4		1.6		1.9		2.7	ns
t_{RD4}	FO=4 Routing Delay		1.6		1.7		2.0		2.3		3.2	ns
t_{RD8}	FO=8 Routing Delay		2.6		2.9		3.2		3.8		5.3	ns
Logic Module Sequential Timing[3,4]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.3		0.4		0.4		0.5		0.7		ns
t_{HD}	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.7		0.8		0.9		1.0		1.4		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.4		3.8		4.3		5.0		7.1		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.5		5.0		5.6		6.6		9.2		ns
t_A	Flip-Flop Clock Input Period	6.8		7.6		8.6		10.1		14.1		ns
t_{INH}	Input Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Buffer Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{OUTH}	Output Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{OUTSU}	Output Buffer Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency		215		1955		1795		1565		94	MHz

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, point and position whichever is appropriate.*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX16 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.1		1.2		1.3		1.6		2.2	ns
t_{INYL}	Pad-to-Y LOW			0.8		0.9		1.0		1.2		1.7	ns
t_{INGH}	G to Y HIGH			1.4		1.6		1.8		2.1		2.9	ns
t_{INGL}	G to Y LOW			1.4		1.6		1.8		2.1		2.9	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			1.8		2.0		2.3		2.7		4.0	ns
t_{IRD2}	FO=2 Routing Delay			2.1		2.3		2.6		3.1		4.3	ns
t_{IRD3}	FO=3 Routing Delay			2.3		2.6		3.0		3.5		4.9	ns
t_{IRD4}	FO=4 Routing Delay			2.6		3.0		3.3		3.9		5.4	ns
t_{IRD8}	FO=8 Routing Delay			3.6		4.0		4.6		5.4		7.5	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 32		2.6		2.9		3.3		3.9		5.4	ns
		FO = 384		2.9		3.2		3.6		4.3		6.0	ns
t_{CKL}	Input HIGH to LOW	FO = 32		3.8		4.2		4.8		5.6		7.8	ns
		FO = 384		4.5		5.0		5.6		6.6		9.2	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 32	3.2		3.5		4.0		4.7		6.6		ns
		FO = 384	3.7		4.1		4.59		5.4		7.6		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 32	3.2		3.5		4.0		4.7		6.6		ns
		FO = 384	3.7		4.1		4.6		5.4		7.6		ns
t_{CKSW}	Maximum Skew	FO = 32		0.3		0.4		0.4		0.5		0.7	ns
		FO = 384		0.3		0.4		0.4		0.5		0.7	ns
t_{SUEXT}	Input Latch External Set-Up	FO = 32	0.0		0.0		0.0		0.0		0.0		ns
		FO = 384	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO = 32	2.8		3.1		5.5		4.1		5.7		ns
		FO = 384	3.2		3.5		4.0		4.7		6.6		ns
t_P	Minimum Period	FO = 32	4.2		4.67		5.1		5.8		9.7		ns
		FO = 384	4.6		5.1		5.6		6.4		10.7		ns
f_{MAX}	Maximum Frequency	FO = 32		237		215		198		172		103	MHz
		FO = 384		215		195		179		156		94	MHz

Note:

1. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.

A42MX16 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		2.5		2.8		3.2		3.7		5.2	ns
t_{DHL}	Data-to-Pad LOW		3.0		3.3		3.7		4.4		6.1	ns
t_{ENZH}	Enable Pad Z to HIGH		2.7		3.0		3.4		4.0		5.6	ns
t_{ENZL}	Enable Pad Z to LOW		3.0		3.3		3.8		4.4		6.2	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.4		6.0		6.8		8.0		11.2	ns
t_{ENLZ}	Enable Pad LOW to Z		5.0		5.6		6.3		7.4		10.4	ns
t_{GLH}	G-to-Pad HIGH		2.9		3.2		3.6		4.3		6.0	ns
t_{GHL}	G-to-Pad LOW		2.9		3.2		3.6		4.3		6.0	ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		5.7		6.3		7.1		8.4		11.9	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.0		8.9		10.1		11.9		16.7	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.03		0.03		0.03		0.04		0.06	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.04		0.04		0.04		0.05		0.07	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.2		3.6		4.0		4.7		6.6	ns
t_{DHL}	Data-to-Pad LOW		2.5		2.7		3.1		3.6		5.1	ns
t_{ENZH}	Enable Pad Z to HIGH		2.7		3.0		3.4		4.0		5.6	ns
t_{ENZL}	Enable Pad Z to LOW		3.0		3.3		3.8		4.4		6.2	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.4		6.0		6.8		8.0		11.2	ns
t_{ENLZ}	Enable Pad LOW to Z		5.0		5.6		6.3		7.4		10.4	ns
t_{GLH}	G-to-Pad HIGH		5.1		5.6		6.4		7.5		10.5	ns
t_{GHL}	G-to-Pad LOW		5.1		5.6		6.4		7.5		10.5	ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		5.7		6.3		7.1		8.4		11.9	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.0		8.9		10.1		11.9		16.7	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.03		0.03		0.03		0.04		0.06	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.04		0.04		0.04		0.05		0.07	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX16 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Propagation Delays[1]												
t_{PD1}	Single Module		1.9		2.1		2.4		2.8		4.0	ns
t_{CO}	Sequential Clock-to-Q		2.0		2.2		2.5		3.0		4.2	ns
t_{GO}	Latch G-to-Q		1.9		2.1		2.4		2.8		4.0	ns
t_{RS}	Flip-Flop (Latch) Reset-to-Q		2.2		2.4		2.8		3.3		4.6	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		1.1		1.2		1.4		1.6		2.3	ns
t_{RD2}	FO=2 Routing Delay		1.5		1.6		1.8		2.1		3.0	ns
t_{RD3}	FO=3 Routing Delay		1.8		2.0		2.3		2.7		3.8	ns
t_{RD4}	FO=4 Routing Delay		2.2		2.4		2.7		3.2		4.5	ns
t_{RD8}	FO=8 Routing Delay		3.6		4.0		4.5		5.3		7.5	ns
Logic Module Sequential Timing[3, 4]												
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.5		0.5		0.6		0.7		0.9		ns
t_{HD}	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	1.0		1.1		1.2		1.4		2.0		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.8		5.3		6.0		7.1		9.9		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.2		6.9		7.9		9.2		12.9		ns
t_A	Flip-Flop Clock Input Period	9.5		10.6		12.0		14.1		19.8		ns
t_{INH}	Input Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Buffer Latch Set-Up	0.7		0.8		0.9		1.01		1.4		ns
t_{OUTH}	Output Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{OUTSU}	Output Buffer Latch Set-Up	0.7		0.8		0.89		1.01		1.4		ns
f_{MAX}	Flip-Flop (Latch) Clock Frequency		129		117		108		94		56	MHz

Notes:

1. *For dual-module macros use tPD1 + tRD1 + tPDn , tCO + tRD1 + tPDn , or tPD1 + tRD1 + tSUD , whichever is appropriate.*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX16 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INYH}	Pad-to-Y HIGH			1.5		1.6		1.9		2.2		3.1	ns
t_{INYL}	Pad-to-Y LOW			1.1		1.3		1.4		1.7		2.4	ns
t_{INGH}	G to Y HIGH			2.0		2.2		2.5		2.9		4.1	ns
t_{INGL}	G to Y LOW			2.0		2.2		2.5		2.9		4.1	ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.6		2.9		3.2		3.8		5.3	ns
t_{IRD2}	FO=2 Routing Delay			2.9		3.2		3.7		4.3		6.1	ns
t_{IRD3}	FO=3 Routing Delay			3.3		3.6		4.1		4.9		6.8	ns
t_{IRD4}	FO=4 Routing Delay			3.6		4.0		4.6		5.4		7.6	ns
t_{IRD8}	FO=8 Routing Delay			5.1		5.6		6.4		7.5		10.5	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO = 32		4.4		4.8		5.5		6.5		9.0	ns
		FO = 384		4.8		5.3		6.0		7.1		9.9	ns
t_{CKL}	Input HIGH to LOW	FO = 32		5.3		5.9		6.7		7.8		11.0	ns
		FO = 384		6.2		6.9		7.9		9.2		12.9	ns
t_{PWH}	Minimum Pulse Width HIGH	FO = 32	5.7		6.3		7.1		8.4		11.8		ns
		FO = 384	6.6		7.4		8.3		9.8		13.7		ns
t_{PWL}	Minimum Pulse Width LOW	FO = 32	5.3		5.9		6.7		7.8		11.0		ns
		FO = 384	6.2		6.9		7.9		9.2		12.9		ns
t_{CKSW}	Maximum Skew	FO = 32		0.5		0.5		0.6		0.7		1.0	ns
		FO = 384		2.2		2.4		2.7		3.2		4.5	ns
t_{SUEXT}	Input Latch External Set-Up	FO = 32	0.0		0.0		0.0		0.0		0.0		ns
		FO = 384	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO = 32	3.9		4.3		4.9		5.7		8.0		ns
		FO = 384	4.5		4.9		5.6		6.6		9.2		ns
t_P	Minimum Period	FO = 32	7.0		7.8		8.4		9.7		16.2		ns
		FO = 384	7.7		8.6		9.3		10.7		17.8		ns
f_{MAX}	Maximum Frequency	FO = 32		142		129		119		103		62	MHz
		FO = 384		129		117		108		94		56	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX16 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		
Parameter	**Description**	**Min.**	**Max.**	**Min.**	**Max.**	**Min.**	**Max.**	**Min.**	**Max.**	**Min.**	**Max.**	**Units**
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.5		3.9		4.4		5.2		7.3	ns
t_{DHL}	Data-to-Pad LOW		4.1		4.6		5.2		6.1		8.6	ns
t_{ENZH}	Enable Pad Z to HIGH		3.8		4.2		4.8		5.6		7.8	ns
t_{ENZL}	Enable Pad Z to LOW		4.2		4.6		5.3		6.2		8.7	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.6		8.4		9.5		11.2		15.7	ns
t_{ENLZ}	Enable Pad LOW to Z		7.0		7.8		8.8		10.4		14.5	ns
t_{GLH}	G-to-Pad HIGH		4.8		5.3		6.0		7.2		10.0	ns
t_{GHL}	G-to-Pad LOW		4.8		5.3		6.0		7.2		10.0	ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.0		8.9		10.1		11.9		16.7	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		11.3		12.5		14.2		16.7		23.3	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.04		0.04		0.05		0.06		0.08	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.05		0.05		0.06		0.07		0.10	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		4.5		5.0		5.6		6.6		9.3	ns
t_{DHL}	Data-to-Pad LOW		3.4		3.8		4.3		5.1		7.1	ns
t_{ENZH}	Enable Pad Z to HIGH		3.8		4.2		4.8		5.6		7.8	ns
t_{ENZL}	Enable Pad Z to LOW		4.2		4.6		5.3		6.2		8.7	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.6		8.4		9.5		11.2		15.7	ns
t_{ENLZ}	Enable Pad LOW to Z		7.0		7.8		8.8		10.4		14.5	ns
t_{GLH}	G-to-Pad HIGH		7.1		7.9		8.9		10.5		14.7	ns
t_{GHL}	G-to-Pad LOW		7.1		7.9		8.9		10.5		14.7	ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.0		8.9		10.1		11.9		16.7	ns
t_{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		11.3		12.5		14.2		16.7		23.3	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.04		0.04		0.05		0.06		0.08	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.05		0.05		0.06		0.07		0.10	ns/pF

Note:

1. Delays based on 35 pF loading.

A42MX24 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Combinatorial Functions[1]												
t_{PD}	Internal Array Module Delay		1.2		1.3		1.5		1.8		2.5	ns
t_{PDD}	Internal Decode Module Delay		1.4		1.6		1.8		2.1		3.0	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		0.8		0.9		1.0		1.2		1.7	ns
t_{RD2}	FO=2 Routing Delay		1.0		1.2		1.3		1.5		2.1	ns
t_{RD3}	FO=3 Routing Delay		1.3		1.4		1.6		1.9		2.6	ns
t_{RD4}	FO=4 Routing Delay		1.5		1.7		1.9		2.2		3.1	ns
t_{RD5}	FO=8 Routing Delay		2.4		2.7		3.0		3.6		5.0	ns
Logic Module Sequential Timing[3, 4]												
t_{CO}	Flip-Flop Clock-to-Output		1.3		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch Gate-to-Output		1.2		1.3		1.5		1.8		2.5	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.3		0.4		0.4		0.5		0.7		ns
t_H	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		1.4		1.6		1.8		2.1		2.9	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.4		0.5		0.5		0.6		0.8		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.3		3.7		4.2		4.9		6.9		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.4		4.8		5.3		6.5		9.0		ns

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*
2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*
4. *Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX24 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INPY}	Input Data Pad-to-Y			1.0		1.1		1.3		1.5		2.1	ns
t_{INGO}	Input Latch Gate-to-Output			1.3		1.4		1.6		1.9		2.6	ns
t_{INH}	Input Latch Hold		0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Latch Set-Up		0.5		0.5		0.6		0.7		1.0		ns
t_{ILA}	Latch Active Pulse Width		4.7		5.2		5.9		6.9		9.7		ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			1.8		2.0		2.3		2.7		3.8	ns
t_{IRD2}	FO=2 Routing Delay			2.1		2.3		2.6		3.1		4.3	ns
t_{IRD3}	FO=3 Routing Delay			2.3		2.5		2.9		3.4		4.8	ns
t_{IRD4}	FO=4 Routing Delay			2.5		2.8		3.2		3.7		5.2	ns
t_{IRD8}	FO=8 Routing Delay			3.4		3.8		4.3		5.1		7.1	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO=32		2.6		2.9		3.3		3.9		5.4	ns
		FO=486		2.9		3.2		3.6		4.3		5.9	ns
t_{CKL}	Input HIGH to LOW	FO=32		3.7		4.1		4.6		5.4		7.6	ns
		FO=486		4.3		4.7		5.4		6.3		8.8	ns
t_{PWH}	Minimum Pulse Width HIGH	FO=32	2.2		2.4		2.7		3.2		4.5		ns
		FO=486	2.4		2.6		3.0		3.5		4.9		ns
t_{PWL}	Minimum Pulse Width LOW	FO=32	2.2		2.4		2.7		3.2		4.5		ns
		FO=486	2.4		2.6		3.0		3.5		4.9		ns
t_{CKSW}	Maximum Skew	FO=32		0.5		0.6		0.7		0.8		1.1	ns
		FO=486		0.5		0.6		0.7		0.8		1.1	ns
t_{SUEXT}	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		0.0		0.0		ns
		FO=486	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO=32	2.8		3.1		3.5		4.1		5.7		ns
		FO=486	3.3		3.7		4.2		4.9		6.9		ns
t_{P}	Minimum Period (1/f_{MAX})	FO=32	4.7		5.2		5.7		6.5		10.9		ns
		FO=486	5.1		5.7		6.2		7.1		11.9		ns
f_{MAX}	Maximum Datapath Frequency	FO=32		210		191		176		153		92	MHz
		FO=486		193		175		161		140		84	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX24 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		2.4		2.7		3.1		3.6		5.1	ns
t_{DHL}	Data-to-Pad LOW		2.8		3.2		3.6		4.2		5.9	ns
t_{ENZH}	Enable Pad Z to HIGH		2.5		2.8		3.2		3.8		5.3	ns
t_{ENZL}	Enable Pad Z to LOW		2.8		3.1		3.5		4.2		5.9	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.2		5.7		6.5		7.6		10.7	ns
t_{ENLZ}	Enable Pad LOW to Z		4.8		5.3		6.0		7.1		9.9	ns
t_{GLH}	G-to-Pad HIGH		2.9		3.2		3.6		4.3		6.0	ns
t_{GHL}	G-to-Pad LOW		2.9		3.2		3.6		4.3		6.0	ns
t_{LSU}	I/O Latch Output Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Output Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		5.6		6.1		6.9		8.1		11.4	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.6		11.8		13.4		15.7		22.0	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.04		0.04		0.04		0.05		0.07	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.03		0.03		0.03		0.04		0.06	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.1		3.5		3.9		4.6		6.4	ns
t_{DHL}	Data-to-Pad LOW		2.4		2.6		3.0		3.5		4.9	ns
t_{ENZH}	Enable Pad Z to HIGH		2.5		2.8		3.2		3.8		5.3	ns
t_{ENZL}	Enable Pad Z to LOW		2.8		3.1		3.5		4.2		5.8	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.2		5.7		6.5		7.6		10.7	ns
t_{ENLZ}	Enable Pad LOW to Z		4.8		5.3		6.0		7.1		9.9	ns
t_{GLH}	G-to-Pad HIGH		4.9		5.4		6.2		7.2		10.1	ns
t_{GHL}	G-to-Pad LOW		4.9		5.4		6.2		7.2		10.1	ns
t_{LSU}	I/O Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		5.5		6.1		6.9		8.1		11.3	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.6		11.8		13.4		15.7		22.0	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.04		0.04		0.04		0.05		0.07	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.03		0.03		0.03		0.04		0.06	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX24 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Combinatorial Functions[1]												
t_{PD}	Internal Array Module Delay		2.0		1.8		2.1		2.5		3.4	ns
t_{PDD}	Internal Decode Module Delay		1.1		2.2		2.5		3.0		4.2	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		1.7		1.3		1.4		1.7		2.3	ns
t_{RD2}	FO=2 Routing Delay		2.0		1.6		1.8		2.1		3.0	ns
t_{RD3}	FO=3 Routing Delay		1.1		2.0		2.2		2.6		3.7	ns
t_{RD4}	FO=4 Routing Delay		1.5		2.3		2.6		3.1		4.3	ns
t_{RD5}	FO=8 Routing Delay		1.8		3.7		4.2		5.0		7.0	ns
Logic Module Sequential Timing[3, 4]												
t_{CO}	Flip-Flop Clock-to-Output		2.1		2.0		2.3		2.7		3.7	ns
t_{GO}	Latch Gate-to-Output		3.4		1.9		2.1		2.5		3.4	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.4		0.5		0.6		0.7		0.9		ns
t_H	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		2.0		2.2		2.5		2.9		4.1	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.6		0.6		0.7		0.8		1.2		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.6		5.2		5.8		6.9		9.6		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.1		6.8		7.7		9.0		12.6		ns

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX24 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INPY}	Input Data Pad-to-Y			1.4		1.6		1.8		2.2		3.0	ns
t_{INGO}	Input Latch Gate-to-Output			1.8		1.9		2.2		2.6		3.6	ns
t_{INH}	Input Latch Hold		0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Latch Set-Up		0.7		0.7		0.8		1.0		1.4		ns
t_{ILA}	Latch Active Pulse Width		6.5		7.3		8.2		9.7		13.5		ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.6		2.9		3.2		3.8		5.3	ns
t_{IRD2}	FO=2 Routing Delay			2.9		3.2		3.6		4.3		6.0	ns
t_{IRD3}	FO=3 Routing Delay			3.2		3.6		4.0		4.8		6.6	ns
t_{IRD4}	FO=4 Routing Delay			3.5		3.9		4.4		5.2		7.3	ns
t_{IRD8}	FO=8 Routing Delay			4.8		5.3		6.1		7.1		10.0	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO=32		4.4		4.8		5.5		6.5		9.1	ns
		FO=486		4.8		5.3		6.0		7.1		10.0	ns
t_{CKL}	Input HIGH to LOW	FO=32		5.1		5.7		6.4		7.6		10.6	ns
		FO=486		6.0		6.6		7.5		8.8		12.4	ns
t_{PWH}	Minimum Pulse Width HIGH	FO=32	3.0		3.3		3.8		4.5		6.3		ns
		FO=486	3.3		3.7		4.2		4.9		6.9		ns
t_{PWL}	Minimum Pulse Width LOW	FO=32	3.0		3.4		3.8		4.5		6.3		ns
		FO=486	3.3		3.7		4.2		4.9		6.9		ns
t_{CKSW}	Maximum Skew	FO=32		0.8		0.8		1.0		1.1		1.6	ns
		FO=486		0.8		0.8		1.0		1.1		1.6	ns
t_{SUEXT}	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		0.0		0.0		ns
		FO=486	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO=32	3.9		4.3		4.9		5.7		8.1		ns
		FO=486	4.6		5.2		5.8		6.9		9.6		ns
t_P	Minimum Period (1/f_{MAX})	FO=32	7.8		8.7		9.47		10.8		18.2		ns
		FO=486	8.6		9.5		10.4		11.9		19.9		ns
f_{MAX}	Maximum Datapath Frequency	FO=32		126		115		106		92		55	MHz
		FO=486		116		105		97		84		50	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX24 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3 Speed Min.	'–3 Speed Max.	'–2 Speed Min.	'–2 Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.4		3.8		4.3		5.0		7.1	ns
t_{DHL}	Data-to-Pad LOW		4.0		4.4		5.0		5.9		8.3	ns
t_{ENZH}	Enable Pad Z to HIGH		3.6		4.0		4.5		5.3		7.4	ns
t_{ENZL}	Enable Pad Z to LOW		3.9		4.4		5.0		5.8		8.2	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.2		8.0		9.07		10.7		14.9	ns
t_{ENLZ}	Enable Pad LOW to Z		6.7		7.5		8.5		9.9		13.9	ns
t_{GLH}	G-to-Pad HIGH		4.8		5.3		6.0		7.2		10.0	ns
t_{GHL}	G-to-Pad LOW		4.8		5.3		6.0		7.2		10.0	ns
t_{LSU}	I/O Latch Output Set-Up	0.7		0.7		0.8		1.0		1.4		ns
t_{LH}	I/O Latch Output Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.67		8.5		9.6		11.3		15.9	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		14.8		16.5		18.7		22.0		30.8	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.05		0.05		0.06		0.07		0.10	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.04		0.04		0.05		0.06		0.08	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		4.8		5.3		5.5		6.4		9.0	ns
t_{DHL}	Data-to-Pad LOW		3.5		3.9		4.1		4.9		6.8	ns
t_{ENZH}	Enable Pad Z to HIGH		3.6		4.0		4.5		5.3		7.4	ns
t_{ENZL}	Enable Pad Z to LOW		3.4		4.0		5.0		5.8		8.2	ns
t_{ENHZ}	Enable Pad HIGH to Z		7.2		8.0		9.01		10.7		14.9	ns
t_{ENLZ}	Enable Pad LOW to Z		6.7		7.5		8.5		9.9		13.9	ns
t_{GLH}	G-to-Pad HIGH		6.8		7.6		8.6		10.1		14.2	ns
t_{GHL}	G-to-Pad LOW		6.8		7.6		8.6		10.1		14.2	ns
t_{LSU}	I/O Latch Set-Up	0.7		0.7		0.8		1.0		1.4		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.7		8.5		9.6		11.3		15.9	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		14.8		16.5		18.7		22.0		30.8	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.05		0.05		0.06		0.07		0.10	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.04		0.04		0.05		0.06		0.08	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Combinatorial Functions[1]												
t_{PD}	Internal Array Module Delay		1.3		1.5		1.7		2.0		2.7	ns
t_{PDD}	Internal Decode Module Delay		1.6		1.8		2.0		2.4		3.3	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		0.9		1.0		1.2		1.4		2.0	ns
t_{RD2}	FO=2 Routing Delay		1.3		1.4		1.6		1.9		2.7	ns
t_{RD3}	FO=3 Routing Delay		1.6		1.8		2.0		2.4		3.4	ns
t_{RD4}	FO=4 Routing Delay		2.0		2.2		2.5		2.9		4.1	ns
t_{RD5}	FO=8 Routing Delay		3.3		3.7		4.2		4.9		6.9	ns
t_{RDD}	Decode-to-Output Routing Delay		0.3		0.4		0.4		0.5		0.7	ns
Logic Module Sequential Timing[3, 4]												
t_{CO}	Flip-Flop Clock-to-Output		1.3		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch Gate-to-Output		1.3		1.4		1.6		1.9		2.7	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.3		0.34		0.4		0.5		0.7		ns
t_{H}	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		1.6		1.7		2.0		2.3		3.2	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.7		0.8		0.9		1.0		1.4		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.3		3.7		4.2		4.9		6.9		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.4		4.8		5.5		6.4		9.0		ns

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Logic Module Timing		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
Synchronous SRAM Operations												
t_{RC}	Read Cycle Time	6.8		7.5		8.5		10.0		14.0		ns
t_{WC}	Write Cycle Time	6.8		7.5		8.5		10.0		14.0		ns
t_{RCKHL}	Clock HIGH/LOW Time	3.4		3.8		4.3		5.0		7.0		ns
t_{RCO}	Data Valid After Clock HIGH/LOW		3.4		3.78		4.3		5.0		7.0	ns
t_{ADSU}	Address/Data Set-Up Time	1.6		1.8		2.0		2.4		3.4		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RENSU}	Read Enable Set-Up	0.6		0.7		0.8		0.9		1.3		ns
t_{RENH}	Read Enable Hold	3.4		3.8		4.3		5.0		7.0		ns
t_{WENSU}	Write Enable Set-Up	2.7		3.0		3.4		4.0		5.6		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{BENS}	Block Enable Set-Up	2.8		3.1		3.5		4.1		5.7		ns
t_{BENH}	Block Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
Asynchronous SRAM Operations												
t_{RPD}	Asynchronous Access Time		8.1		9.0		10.2		12.0		16.8	ns
t_{RDADV}	Read Address Valid	8.8		9.8		11.1		13.0		18.2		ns
t_{ADSU}	Address/Data Set-Up Time	1.6		1.8		2.0		2.4		3.4		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RENSUA}	Read Enable Set-Up to Address Valid	0.6		0.7		0.8		0.9		1.3		ns
t_{RENHA}	Read Enable Hold	3.4		3.8		4.3		5.0		7.0		ns
t_{WENSU}	Write Enable Set-Up	2.7		3.0		3.4		4.0		5.6		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{DOH}	Data Out Hold Time		1.2		1.34		1.5		1.8		2.5	ns

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays													
t_{INPY}	Input Data Pad-to-Y			1.0		1.1		1.3		1.5		2.1	ns
t_{INGO}	Input Latch Gate-to-Output			1.4		1.6		1.8		2.1		2.9	ns
t_{INH}	Input Latch Hold		0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Latch Set-Up		0.5		0.5		0.6		0.7		1.0		ns
t_{ILA}	Latch Active Pulse Width		4.7		5.2		5.9		6.9		9.7		ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.0		2.2		2.5		2.9		4.1	ns
t_{IRD2}	FO=2 Routing Delay			2.3		2.6		2.9		3.4		4.8	ns
t_{IRD3}	FO=3 Routing Delay			2.6		2.9		3.3		3.9		5.5	ns
t_{IRD4}	FO=4 Routing Delay			3.0		3.3		3.8		4.4		6.2	ns
t_{IRD8}	FO=8 Routing Delay			4.3		4.8		5.5		6.4		9.0	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO=32		2.7		3.0		3.4		4.0		5.6	ns
		FO=635		3.0		3.3		3.8		4.4		6.2	ns
t_{CKL}	Input HIGH to LOW	FO=32		3.8		4.2		4.8		5.6		7.8	ns
		FO=635		4.9		5.4		6.1		7.2		10.1	ns
t_{PWH}	Minimum Pulse Width HIGH	FO=32	1.8		2.0		2.2		2.6		3.6		ns
		FO=635	2.0		2.2		2.5		2.9		4.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO=32	1.8		2.0		2.2		2.6		3.6		ns
		FO=635	2.0		2.2		2.5		2.9		4.1		ns
t_{CKSW}	Maximum Skew	FO=32		0.8		0.8		0.9		1.0		1.4	ns
		FO=635		0.8		0.8		0.9		1.0		1.4	ns
t_{SUEXT}	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		0.0		0.0		ns
		FO=635	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO=32	2.8		3.2		3.6		4.2		5.9		ns
		FO=635	3.3		3.7		4.2		4.9		6.9		ns
t_P	Minimum Period (1/f_{MAX})	FO=32	5.5		6.1		6.6		7.6		12.7		ns
		FO=635	6.0		6.6		7.2		8.3		13.8		ns
f_{HMAX}	Maximum Datapath Frequency	FO=32		180		164		151		131		79	MHz
		FO=635		166		151		139		121		73	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 4.75V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
TTL Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		2.6		2.8		3.2		3.8		5.3	ns
t_{DHL}	Data-to-Pad LOW		3.0		3.3		3.7		4.4		6.2	ns
t_{ENZH}	Enable Pad Z to HIGH		2.7		3.0		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		3.0		3.3		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.3		5.8		6.6		7.8		10.9	ns
t_{ENLZ}	Enable Pad LOW to Z		4.9		5.5		6.2		7.3		10.2	ns
t_{GLH}	G-to-Pad HIGH		2.9		3.3		3.7		4.4		6.1	ns
t_{GHL}	G-to-Pad LOW		2.9		3.3		3.7		4.4		6.1	ns
t_{LSU}	I/O Latch Output Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Output Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		5.7		6.3		7.1		8.4		11.8	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.8		8.6		9.8		11.5		16.1	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.07		0.08		0.09		0.10		0.14	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.07		0.08		0.09		0.10		0.14	ns/pF
CMOS Output Module Timing[1]												
t_{DLH}	Data-to-Pad HIGH		3.5		3.9		4.5		5.2		7.3	ns
t_{DHL}	Data-to-Pad LOW		2.5		2.7		3.1		3.6		5.1	ns
t_{ENZH}	Enable Pad Z to HIGH		2.7		3.0		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		2.9		3.3		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.3		5.8		6.6		7.8		10.9	ns
t_{ENLZ}	Enable Pad LOW to Z		4.9		5.5		6.2		7.3		10.2	ns
t_{GLH}	G-to-Pad HIGH		5.0		5.6		6.3		7.5		10.4	ns
t_{GHL}	G-to-Pad LOW		5.0		5.6		6.3		7.5		10.4	ns
t_{LSU}	I/O Latch Set-Up	0.5		0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		5.7		6.3		7.1		8.4		11.8	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.78		8.6		9.8		11.5		16.1	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.07		0.08		0.09		0.10		0.14	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.07		0.08		0.09		0.10		0.14	ns/pF

Note:

1. *Delays based on 35 pF loading.*

A42MX36 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Combinatorial Functions[1]												
t_{PD}	Internal Array Module Delay		1.9		2.1		2.3		2.7		3.8	ns
t_{PDD}	Internal Decode Module Delay		2.2		2.5		2.8		3.3		4.7	ns
Logic Module Predicted Routing Delays[2]												
t_{RD1}	FO=1 Routing Delay		1.3		1.5		1.7		2.0		2.7	ns
t_{RD2}	FO=2 Routing Delay		1.8		2.0		2.3		2.7		3.7	ns
t_{RD3}	FO=3 Routing Delay		2.3		2.5		2.8		3.4		4.7	ns
t_{RD4}	FO=4 Routing Delay		2.8		3.1		3.5		4.1		5.7	ns
t_{RD5}	FO=8 Routing Delay		4.6		5.2		5.8		6.9		9.6	ns
t_{RDD}	Decode-to-Output Routing Delay		0.5		0.5		0.6		0.7		1.0	ns
Logic Module Sequential Timing[3, 4]												
t_{CO}	Flip-Flop Clock-to-Output		1.8		2.0		2.3		2.7		3.7	ns
t_{GO}	Latch Gate-to-Output		1.8		2.0		2.3		2.7		3.7	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.4		0.5		0.6		0.7		0.9		ns
t_H	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		2.2		2.4		2.7		3.2		4.5	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	1.0		1.1		1.2		1.4		2.0		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.6		5.2		5.8		6.9		9.6		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.1		6.8		7.7		9.0		12.6		ns

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.*
2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*
3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*
4. *Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Logic Module Timing		'–3' Speed		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
Synchronous SRAM Operations												
t_{RC}	Read Cycle Time	9.5		10.5		11.9		14.0		19.6		ns
t_{WC}	Write Cycle Time	9.5		10.5		11.9		14.0		19.6		ns
t_{RCKHL}	Clock HIGH/LOW Time	4.8		5.3		6.0		7.0		9.8		ns
t_{RCO}	Data Valid After Clock HIGH/LOW		4.8		5.3		6.0		7.0		9.8	ns
t_{ADSU}	Address/Data Set-Up Time	2.3		2.5		2.8		3.4		4.8		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RENSU}	Read Enable Set-Up	0.9		1.0		1.1		1.3		1.8		ns
t_{RENH}	Read Enable Hold	4.8		5.3		6.0		7.0		9.8		ns
t_{WENSU}	Write Enable Set-Up	3.8		4.2		4.8		5.6		7.8		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{BENS}	Block Enable Set-Up	3.9		4.3		4.9		5.7		8.0		ns
t_{BENH}	Block Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
Asynchronous SRAM Operations												
t_{RPD}	Asynchronous Access Time		11.3		12.6		14.3		16.8		23.5	ns
t_{RDADV}	Read Address Valid	12.3		13.7		15.5		18.2		25.5		ns
t_{ADSU}	Address/Data Set-Up Time	2.3		2.5		2.8		3.4		4.8		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		0.0		ns
t_{RENSUA}	Read Enable Set-Up to Address Valid	0.9		1.0		1.1		1.3		1.8		ns
t_{RENHA}	Read Enable Hold	4.8		5.3		6.0		7.0		9.8		ns
t_{WENSU}	Write Enable Set-Up	3.8		4.2		4.8		5.6		7.8		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		0.0		ns
t_{DOH}	Data Out Hold Time		1.8		2.0		2.1		2.5		3.5	ns

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V_{CC} = 3.0V, T_J = 70°C)

Parameter	Description		'–3' Speed Min.	Max.	'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	'–F' Speed Min.	Max.	Units
Input Module Propagation Delays													
t_{INPY}	Input Data Pad-to-Y			1.4		1.6		1.8		2.1		3.0	ns
t_{INGO}	Input Latch Gate-to-Output			2.0		2.2		2.5		2.9		4.1	ns
t_{INH}	Input Latch Hold		0.0		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Latch Set-Up		0.7		0.7		0.8		1.0		1.4		ns
t_{ILA}	Latch Active Pulse Width		6.5		7.3		8.2		9.7		13.5		ns
Input Module Predicted Routing Delays[1]													
t_{IRD1}	FO=1 Routing Delay			2.8		3.1		3.5		4.07		5.7	ns
t_{IRD2}	FO=2 Routing Delay			3.2		3.5		4.1		4.8		6.7	ns
t_{IRD3}	FO=3 Routing Delay			3.7		4.1		4.7		5.5		7.7	ns
t_{IRD4}	FO=4 Routing Delay			4.2		4.6		5.3		6.2		8.7	ns
t_{IRD8}	FO=8 Routing Delay			6.1		6.8		7.7		9.0		12.6	ns
Global Clock Network													
t_{CKH}	Input LOW to HIGH	FO=32		4.6		5.1		5.7		6.7		9.3	ns
		FO=635		5.0		5.6		6.3		7.4		10.3	ns
t_{CKL}	Input HIGH to LOW	FO=32		5.3		5.9		6.7		7.8		11.0	ns
		FO=635		6.8		7.6		8.6		10.1		14.1	ns
t_{PWH}	Minimum Pulse Width HIGH	FO=32	2.5		2.7		3.1		3.6		5.1		ns
		FO=635	2.8		3.1		3.5		4.1		5.7		ns
t_{PWL}	Minimum Pulse Width LOW	FO=32	2.5		2.7		3.1		3.6		5.1		ns
		FO=635	2.8		3.1		3.5		4.1		5.7		ns
t_{CKSW}	Maximum Skew	FO=32		1.0		1.2		1.3		1.5		2.2	ns
		FO=635		1.0		1.2		1.3		1.5		2.2	ns
t_{SUEXT}	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		0.0		0.0		ns
		FO=635	0.0		0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO=32	4.0		4.4		5.0		5.9		8.2		ns
		FO=635	4.6		5.2		5.9		6.9		9.6		ns
t_P	Minimum Period (1/f_{MAX})	FO=32	9.2		10.2		11.1		12.7		21.2		ns
		FO=635	9.9		11.0		12.0		13.8		23.0		ns
f_{HMAX}	Maximum Datapath Frequency	FO=32		108		98		90		79		47	MHz
		FO=635		100		91		83		73		44	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Commercial Conditions, V$_{CC}$ = 3.0V, T$_J$ = 70°C)

Parameter	Description	'–3' Speed Min.	'–3' Speed Max.	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]												
t$_{DLH}$	Data-to-Pad HIGH		3.6		4.0		4.5		5.3		7.4	ns
t$_{DHL}$	Data-to-Pad LOW		4.2		4.6		5.2		6.2		8.6	ns
t$_{ENZH}$	Enable Pad Z to HIGH		3.7		4.2		4.7		5.5		7.7	ns
t$_{ENZL}$	Enable Pad Z to LOW		4.1		4.6		5.2		6.1		8.5	ns
t$_{ENHZ}$	Enable Pad HIGH to Z		7.34		8.2		9.3		10.9		15.3	ns
t$_{ENLZ}$	Enable Pad LOW to Z		6.9		7.6		8.7		10.2		14.3	ns
t$_{GLH}$	G-to-Pad HIGH		4.9		5.5		6.2		7.3		10.2	ns
t$_{GHL}$	G-to-Pad LOW		4.9		5.5		6.2		7.3		10.2	ns
t$_{LSU}$	I/O Latch Output Set-Up	0.7		0.7		0.8		1.0		1.4		ns
t$_{LH}$	I/O Latch Output Hold	0.0		0.0		0.0		0.0		0.0		ns
t$_{LCO}$	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.9		8.8		10.0		11.8		16.5	ns
t$_{ACO}$	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.9		12.1		13.7		16.1		22.5	ns
d$_{TLH}$	Capacitive Loading, LOW to HIGH		0.10		0.11		0.12		0.14		0.20	ns/pF
d$_{THL}$	Capacitive Loading, HIGH to LOW		0.10		0.11		0.12		0.14		0.20	ns/pF
CMOS Output Module Timing[1]												
t$_{DLH}$	Data-to-Pad HIGH		4.9		5.5		6.2		7.3		10.3	ns
t$_{DHL}$	Data-to-Pad LOW		3.4		3.8		4.3		5.1		7.1	ns
t$_{ENZH}$	Enable Pad Z to HIGH		3.7		4.1		4.7		5.5		7.7	ns
t$_{ENZL}$	Enable Pad Z to LOW		4.1		4.6		5.2		6.1		8.5	ns
t$_{ENHZ}$	Enable Pad HIGH to Z		7.4		8.2		9.3		10.9		15.3	ns
t$_{ENLZ}$	Enable Pad LOW to Z		6.9		7.6		8.7		10.2		14.3	ns
t$_{GLH}$	G-to-Pad HIGH		7.0		7.8		8.9		10.4		14.6	ns
t$_{GHL}$	G-to-Pad LOW		7.0		7.8		8.9		10.4		14.6	ns
t$_{LSU}$	I/O Latch Set-Up	0.7		0.7		0.8		1.0		1.4		ns
t$_{LH}$	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0		ns
t$_{LCO}$	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		7.9		8.8		10.0		11.8		16.5	ns
t$_{ACO}$	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.9		12.1		13.7		16.1		22.5	ns
d$_{TLH}$	Capacitive Loading, LOW to HIGH		0.10		0.11		0.12		0.14		0.20	ns/pF
d$_{THL}$	Capacitive Loading, HIGH to LOW		0.10		0.11		0.12		0.14		0.20	ns/pF

Note:

1.   *Delays based on 35 pF loading.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation)

(Worst-Case Military Conditions, V_{CC} = 4.5V, T_J = 125°C)

Parameter	Description	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Logic Module Combinatorial Functions[1]										
t_{PD}	Internal Array Module Delay		1.5		1.7		2.0		2.7	ns
t_{PDD}	Internal Decode Module Delay		1.8		2.0		2.4		3.3	ns
Logic Module Predicted Routing Delays[2]										
t_{RD1}	FO=1 Routing Delay		1.0		1.2		1.4		2.0	ns
t_{RD2}	FO=2 Routing Delay		1.4		1.6		1.9		2.7	ns
t_{RD3}	FO=3 Routing Delay		1.8		2.0		2.4		3.4	ns
t_{RD4}	FO=4 Routing Delay		2.2		2.5		2.9		4.1	ns
t_{RD5}	FO=8 Routing Delay		3.7		4.2		4.9		6.9	ns
t_{RDD}	Decode-to-Output Routing Delay		0.4		0.4		0.5		0.7	ns
Logic Module Sequential Timing [3, 4]										
t_{CO}	Flip-Flop Clock-to-Output		1.4		1.6		1.9		2.7	ns
t_{GO}	Latch Gate-to-Output		1.4		1.6		1.9		2.7	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.4		0.4		0.5		0.7		ns
t_{H}	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		1.7		2.0		2.3		3.2	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.8		0.9		1.0		1.4		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.7		4.2		4.9		6.9		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.8		5.5		6.4		9.0		ns

Notes:

1. *For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate..*

2. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

3. *Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.*

4. *Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Military Conditions, V_{CC} = 4.5V, T_J = 125°C)

Logic Module Timing		'–2' Speed		'–1' Speed		'Std' Speed		'–F' Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
Synchronous SRAM Operations										
t_{RC}	Read Cycle Time	7.5		8.5		10.0		14.0		ns
t_{WC}	Write Cycle Time	7.5		8.5		10.0		14.0		ns
t_{RCKHL}	Clock HIGH/LOW Time	3.8		4.3		5.0		7.0		ns
t_{RCO}	Data Valid After Clock HIGH/LOW		3.8		4.3		5.0		7.0	ns
t_{ADSU}	Address/Data Set-Up Time	1.8		2.0		2.4		3.4		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		ns
t_{RENSU}	Read Enable Set-Up	0.7		0.8		0.9		1.3		ns
t_{RENH}	Read Enable Hold	3.8		4.3		5.0		7.0		ns
t_{WENSU}	Write Enable Set-Up	3.0		3.4		4.0		5.6		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		ns
t_{BENS}	Block Enable Set-Up	3.1		3.5		4.1		5.7		ns
t_{BENH}	Block Enable Hold	0.0		0.0		0.0		0.0		ns
Asynchronous SRAM Operations										
t_{RPD}	Asynchronous Access Time		9.0		10.2		12.0		16.8	ns
t_{RDADV}	Read Address Valid	9.8		11.1		13.0		18.2		ns
t_{ADSU}	Address/Data Set-Up Time	1.8		2.1		2.4		3.4		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		0.0		ns
t_{RENSUA}	Read Enable Set-Up to Address Valid	0.7		0.8		0.9		1.3		ns
t_{RENHA}	Read Enable Hold	3.8		4.3		5.0		7.0		ns
t_{WENSU}	Write Enable Set-Up	3.0		3.4		4.0		5.6		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		0.0		ns
t_{DOH}	Data Out Hold Time		1.4		1.5		1.8		2.5	ns

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Military Conditions, V_{CC} = 4.5V, T_J = 125°C)

Parameter	Description		'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
Input Module Propagation Delays											
t_{INPY}	Input Data Pad-to-Y			1.1		1.3		1.5		2.1	ns
t_{INGO}	Input Latch Gate-to-Output			1.6		1.8		2.1		2.9	ns
t_{INH}	Input Latch Hold		0.0		0.0		0.0		0.0		ns
t_{INSU}	Input Latch Set-Up		0.5		0.6		0.7		1.0		ns
t_{ILA}	Latch Active Pulse Width		5.2		5.9		6.9		9.7		ns
Input Module Predicted Routing Delays[1]											
t_{IRD1}	FO=1 Routing Delay			2.2		2.5		2.9		4.1	ns
t_{IRD2}	FO=2 Routing Delay			2.6		2.9		3.4		4.8	ns
t_{IRD3}	FO=3 Routing Delay			2.9		3.3		3.9		5.5	ns
t_{IRD4}	FO=4 Routing Delay			3.3		3.8		4.4		6.2	ns
t_{IRD8}	FO=8 Routing Delay			4.8		5.5		6.4		9.0	ns
Global Clock Network											
t_{CKH}	Input LOW to HIGH	FO=32		3.0		3.4		4.0		5.6	ns
		FO=635		3.3		3.8		4.4		6.2	ns
t_{CKL}	Input HIGH to LOW	FO=32		4.2		4.8		5.6		7.8	ns
		FO=635		5.4		6.1		7.2		10.1	ns
t_{PWH}	Minimum Pulse Width HIGH	FO=32	2.0		2.2		2.6		3.7		ns
		FO=635	2.2		2.5		2.9		4.1		ns
t_{PWL}	Minimum Pulse Width LOW	FO=32	2.0		2.2		2.6		3.7		ns
		FO=635	2.2		2.5		2.9		4.1		ns
t_{CKSW}	Maximum Skew	FO=32		0.8		0.9		1.0		1.4	ns
		FO=635		0.8		0.9		1.0		1.4	ns
t_{SUEXT}	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		0.0		ns
		FO=635	0.0		0.0		0.0		0.0		ns
t_{HEXT}	Input Latch External Hold	FO=32	3.2		3.6		4.2		5.9		ns
		FO=635	3.7		4.2		4.9		6.9		ns
t_P	Minimum Period (1/f_{MAX})	FO=32	6.1		6.6		7.6		12.7		ns
		FO=635	6.6		7.2		8.3		13.8		ns
f_{HMAX}	Maximum Datapath Frequency	FO=32		164		151		131		79	MHz
		FO=635		151		139		121		73	MHz

Note:

1. *Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.*

A42MX36 Timing Characteristics (Nominal 5.0V Operation) (continued)

(Worst-Case Military Conditions, V_{CC} = 4.5V, T_J = 125°C)

Parameter	Description	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	'–F' Speed Min.	'–F' Speed Max.	Units
TTL Output Module Timing[1]										
t_{DLH}	Data-to-Pad HIGH		2.8		3.2		3.8		5.3	ns
t_{DHL}	Data-to-Pad LOW		3.3		3.7		4.4		6.2	ns
t_{ENZH}	Enable Pad Z to HIGH		3.0		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		3.3		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.8		6.6		7.8		11.0	ns
t_{ENLZ}	Enable Pad LOW to Z		5.5		6.2		7.3		10.2	ns
t_{GLH}	G-to-Pad HIGH		3.3		3.7		4.4		6.1	ns
t_{GHL}	G-to-Pad LOW		3.3		3.7		4.4		6.1	ns
t_{LSU}	I/O Latch Output Set-Up	0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Output Hold	0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		6.3		7.1		8.4		11.8	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		8.6		9.8		11.5		16.1	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.08		0.09		0.10		0.14	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.08		0.09		0.10		0.14	ns/pF
CMOS Output Module Timing[1]										
t_{DLH}	Data-to-Pad HIGH		3.9		4.5		5.2		7.3	ns
t_{DHL}	Data-to-Pad LOW		2.7		3.1		3.7		5.1	ns
t_{ENZH}	Enable Pad Z to HIGH		3.0		3.3		3.9		5.5	ns
t_{ENZL}	Enable Pad Z to LOW		3.3		3.7		4.3		6.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		5.8		6.6		7.8		10.9	ns
t_{ENLZ}	Enable Pad LOW to Z		5.5		6.2		7.3		10.2	ns
t_{GLH}	G-to-Pad HIGH		5.6		6.3		7.5		10.4	ns
t_{GHL}	G-to-Pad LOW		5.6		6.3		7.5		10.4	ns
t_{LSU}	I/O Latch Set-Up	0.5		0.6		0.7		1.0		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		6.3		7.1		8.4		11.8	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		8.6		9.78		11.5		16.1	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.08		0.09		0.10		0.14	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.08		0.09		0.10		0.14	ns/pF

Note:

1.   *Delays based on 35 pF loading.*

A42MX36 Timing Characteristics (Nominal 3.3V Operation)

(Worst-Case Military Conditions, V_{CC} = 3.0V, T_J = 125°C)

Parameter	Description	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	Units
Logic Module Combinatorial Functions[1]								
t_{PD}	Internal Array Module Delay		2.4		2.7		3.2	ns
t_{PDD}	Internal Decode Module Delay		2.9		3.3		3.9	ns
Logic Module Predicted Routing Delays[2]								
t_{RD1}	FO=1 Routing Delay		1.7		2.0		2.3	ns
t_{RD2}	FO=2 Routing Delay		2.3		2.6		3.1	ns
t_{RD3}	FO=3 Routing Delay		2.9		3.3		3.9	ns
t_{RD4}	FO=4 Routing Delay		3.6		4.0		4.7	ns
t_{RD5}	FO=8 Routing Delay		6.0		6.8		8.0	ns
t_{RDD}	Decode-to-Output Routing Delay		6.7		0.8		0.9	ns
Logic Module Sequential Timing[3, 4]								
t_{CO}	Flip-Flop Clock-to-Output		2.4		2.7		3.1	ns
t_{GO}	Latch Gate-to-Output		2.4		2.7		3.1	ns
t_{SU}	Flip-Flop (Latch) Set-Up Time	0.6		0.7		0.8		ns
t_H	Flip-Flop (Latch) Hold Time	0.0		0.0		0.0		ns
t_{RO}	Flip-Flop (Latch) Reset-to-Output		2.9		3.2		3.8	ns
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	1.3		1.4		1.7		ns
t_{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		ns
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	6.0		6.8		8.0		ns
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	7.9		8.9		10.5		ns

Notes:

1. For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.

1. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance.   Post-route timing analysis or simulation is required to determine actual performance.

2. Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.

3. Set-up and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Military Conditions, V_{CC} = 3.0V, T_J = 125°C)

Logic Module Timing		'–2' Speed		'–1' Speed		'Std' Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
Synchronous SRAM Operations								
t_{RC}	Read Cycle Time	12.1		13.8		16.2		ns
t_{WC}	Write Cycle Time	12.1		13.8		16.2		ns
t_{RCKHL}	Clock HIGH/LOW Time	6.1		6.9		8.1		ns
t_{RCO}	Data Valid After Clock HIGH/LOW		6.2		7.0		8.2	ns
t_{ADSU}	Address/Data Set-Up Time	2.9		3.2		3.9		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		ns
t_{RENSU}	Read Enable Set-Up			1.2		1.5		ns
t_{RENH}	Read Enable Hold	6.1		6.9		8.1		ns
t_{WENSU}	Write Enable Set-Up	4.8		5.5		6.4		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		ns
t_{BENS}	Block Enable Set-Up	4.9		5.6		6.6		ns
t_{BENH}	Block Enable Hold	0.0		0.0		0.0		ns
Asynchronous SRAM Operations								
t_{RPD}	Asynchronous Access Time		14.7		16.6		19.5	ns
t_{RDADV}	Read Address Valid	15.9		18.0		21.1		ns
t_{ADSU}	Address/Data Set-Up Time	2.9		3.2		3.9		ns
t_{ADH}	Address/Data Hold Time	0.0		0.0		0.0		ns
t_{RENSUA}	Read Enable Set-Up to Address Valid	1.1		1.2		1.5		ns
t_{RENHA}	Read Enable Hold	6.1		6.9		8.1		ns
t_{WENSU}	Write Enable Set-Up	4.8		5.5		6.4		ns
t_{WENH}	Write Enable Hold	0.0		0.0		0.0		ns
t_{DOH}	Data Out Hold Time		2.4		2.5		2.9	ns

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Military Conditions, V$_{CC}$ = 3.0V, T$_J$ = 125°C)

Parameter	Description		'–2' Speed Min.	Max.	'–1' Speed Min.	Max.	'Std' Speed Min.	Max.	Units
Input Module Propagation Delays									
t$_{INPY}$	Input Data Pad-to-Y			1.9		2.1		2.5	ns
t$_{INGO}$	Input Latch Gate-to-Output			2.6		2.9		3.4	ns
t$_{INH}$	Input Latch Hold		0.0		0.0		0.0		ns
t$_{INSU}$	Input Latch Set-Up		0.8		0.9		1.1		ns
t$_{ILA}$	Latch Active Pulse Width		8.4		9.5		11.2		ns
Input Module Predicted Routing Delays[1]									
t$_{IRD1}$	FO=1 Routing Delay			3.6		4.0		4.8	ns
t$_{IRD2}$	FO=2 Routing Delay			4.2		4.7		5.6	ns
t$_{IRD3}$	FO=3 Routing Delay			4.8		5.4		6.4	ns
t$_{IRD4}$	FO=4 Routing Delay			5.4		6.1		7.2	ns
t$_{IRD8}$	FO=8 Routing Delay			7.9		8.9		10.5	ns
Global Clock Network									
t$_{CKH}$	Input LOW to HIGH	FO=32		5.9		6.7		7.8	ns
		FO=635		6.5		7.3		8.6	ns
t$_{CKL}$	Input HIGH to LOW	FO=32		6.9		7.8		9.1	ns
		FO=635		8.8		10.0		11.7	ns
t$_{PWH}$	Minimum Pulse Width HIGH	FO=32	3.1		3.5		4.2		ns
		FO=635	3.5		4.0		4.7		ns
t$_{PWL}$	Minimum Pulse Width LOW	FO=32	3.1		3.5		4.2		ns
		FO=635	3.5		4.0		4.7		ns
t$_{CKSW}$	Maximum Skew	FO=32		1.4		1.6		1.8	ns
		FO=635		1.4		1.6		1.8	ns
t$_{SUEXT}$	Input Latch External Set-Up	FO=32	0.0		0.0		0.0		ns
		FO=635	0.0		0.0		0.0		ns
t$_{HEXT}$	Input Latch External Hold	FO=32	5.1		5.8		6.8		ns
		FO=635	5.9		6.7		7.9		ns
t$_P$	Minimum Period (1/f$_{MAX}$)	FO=32	11.8		12.8		14.7		ns
		FO=635	12.7		13.8		15.9		ns
f$_{HMAX}$	Maximum Datapath Frequency	FO=32		85		78		67	MHz
		FO=635		78		71		62	MHz

Note:

1.   Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance.   Post-route timing analysis or simulation is required to determine actual performance.

A42MX36 Timing Characteristics (Nominal 3.3V Operation) (continued)

(Worst-Case Military Conditions, V_{CC} = 3.0V, T_J = 125°C)

Parameter	Description	'–2' Speed Min.	'–2' Speed Max.	'–1' Speed Min.	'–1' Speed Max.	'Std' Speed Min.	'Std' Speed Max.	Units
TTL Output Module Timing[1]								
t_{DLH}	Data-to-Pad HIGH		4.6		5.2		6.2	ns
t_{DHL}	Data-to-Pad LOW		5.3		6.1		7.2	ns
t_{ENZH}	Enable Pad Z to HIGH		4.8		5.4		6.4	ns
t_{ENZL}	Enable Pad Z to LOW		5.3		6.0		7.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		9.5		10.8		12.7	ns
t_{ENLZ}	Enable Pad LOW to Z		8.9		10.0		11.8	ns
t_{GLH}	G-to-Pad HIGH		6.3		7.2		8.4	ns
t_{GHL}	G-to-Pad LOW		6.3		7.2		8.4	ns
t_{LSU}	I/O Latch Output Set-Up	0.8		0.9		1.1		ns
t_{LH}	I/O Latch Output Hold	0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.2		11.6		13.7	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		14.0		15.9		18.7	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.13		0.14		0.16	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.13		0.14		0.16	ns/pF
CMOS Output Module Timing[1]								
t_{DLH}	Data-to-Pad HIGH		6.4		7.3		8.5	ns
t_{DHL}	Data-to-Pad LOW		4.5		5.1		5.9	ns
t_{ENZH}	Enable Pad Z to HIGH		4.8		5.5		6.4	ns
t_{ENZL}	Enable Pad Z to LOW		5.3		6.0		7.1	ns
t_{ENHZ}	Enable Pad HIGH to Z		9.5		10.8		12.7	ns
t_{ENLZ}	Enable Pad LOW to Z		8.9		10.0		11.8	ns
t_{GLH}	G-to-Pad HIGH		9.1		10.3		12.1	ns
t_{GHL}	G-to-Pad LOW		9.1		10.3		12.1	ns
t_{LSU}	I/O Latch Set-Up	0.8		0.9		1.1		ns
t_{LH}	I/O Latch Hold	0.0		0.0		0.0		ns
t_{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad) 32 I/O		10.2		13.7		13.7	ns
t_{ACO}	Array Latch Clock-to-Out (Pad-to-Pad) 32 I/O		14.0		18.7		18.7	ns
d_{TLH}	Capacitive Loading, LOW to HIGH		0.13		0.16		0.16	ns/pF
d_{THL}	Capacitive Loading, HIGH to LOW		0.13		0.16		0.16	ns/pF

Note:

1. *Delays based on 35 pF loading.*

Pin Descriptions

CLK, CLKA,
CLKB   Global Clock (Input)

TTL clock inputs for clock distribution networks. The clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

DCLK   Diagnostic Clock (Input)

TTL clock input for diagnostic probe and device programming. DCLK is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

GND   Ground (Input)

Input LOW supply voltage.

I/O   Input/Output (Input, Output)

Input, output, tri-state, or bi-directional buffer. Input and output levels are compatible with standard TTL and CMOS specifications. Unused I/O pins are automatically driven LOW by the Designer Series software.

LP   Low Power Mode

Controls the low power mode of all 42MX devices. This pin must be set HIGH to switch the device to low power mode. To exit the LOW power mode, the LP pin must be set LOW.

MODE   Mode (Input)

Controls the use of multifunction pins (DCLK, PRA, PRB, SDI, TDO). To provide verification capability, the MODE pin should be held HIGH. To facilitate this, the MODE pin should be terminated to GND through a 10K¾ resistor so that the MODE pin can be pulled HIGH when required.

NC   No Connection

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

PRA, I/O   Probe A (Output)

The Probe A pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe B pin to allow real-time diagnostic output of any signal path within the device. The Probe A pin can be used as a user-defined I/O when verification has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRA is accessible when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

PRB, I/O   Probe B (Output)

The Probe B pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe A pin to allow real-time diagnostic output of any signal path within the device. The Probe B pin can be used as a user-defined I/O when verification has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRB is

accessible when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

QCLKA,B,C,D Quadrant Clock (Input/Output)

Quadrant clock inputs. When not used as a register control signal, these pins can function as general-purpose I/Os.

SDI   Serial Data Input (Input)

Serial data input for diagnostic probe and device programming. SDI is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

SDO, TDO,
I/O   Serial Data (Output)

Serial data output for diagnostic probe and device programming. SDO is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW. SDO is not available for 40MX devices.

TCK   Test Clock

Clock signal to shift the Boundary Scan Test (BST) data into the device. This pin functions as an I/O when the test fuse is not programmed. BST pins are only available in the A42MX24, A42MX24A, and A42MX36 devices.

TDI   Test Data In

Serial data input for BST instructions and data. Data is shifted in on the rising edge of TCK. This pin functions as an I/O when the test fuse is not programmed. BST pins are only available in the A42MX24 and A42MX36 devices.

TDO   Test Data Out

Serial data output for BST instructions and test data. This pin functions as an I/O when the test fuse is not programmed. BST pins are only available in the A42MX24 and A42MX36 devices.

TMS   Test Mode Select

Serial data input for boundary scan test mode. Data is shifted in on the rising edge of TCK. This pin functions as an I/O when the test fuse is not programmed. BST pins are only available in the A42MX24 and A42MX36 devices.

V_{CC} Supply Voltage (Input)

Input HIGH supply voltage.

V_{CCA} Supply Voltage (Input)

Input HIGH supply voltage, supplies array core only.

V_{CCI} Supply Voltage (Input)

Input HIGH supply voltage, supplies I/O cells only.

WD   Wide Decode Output

When a wide decode module is used in a 42MX device, this pin can be used as a dedicated output from the wide decode module. This direct connection eliminates additional interconnect delays associated with regular logic modules. To implement the direct I/O connection, connect an output buffer of any type to the output of the wide decode macro and place this output on one of the reserved WD pins.

Package Pin Assignments

44-Pin PLCC
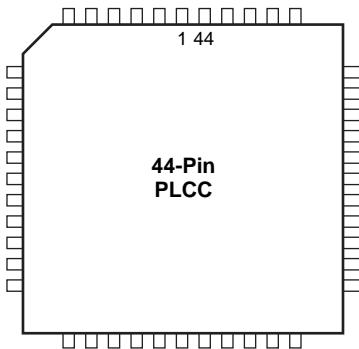
44-Pin
PLCC

44-pin PLCC

Pin Number	A40MX02 Function	A40MX04 Function	Pin Number	A40MX02 Function	A40MX04 Function
1	I/O	I/O	23	I/O	I/O
2	I/O	I/O	24	I/O	I/O
3	V_{CC}	V_{CC}	25	V_{CC}	V_{CC}
4	I/O	I/O	26	I/O	I/O
5	I/O	I/O	27	I/O	I/O
6	I/O	I/O	28	I/O	I/O
7	I/O	I/O	29	I/O	I/O
8	I/O	I/O	30	I/O	I/O
9	I/O	I/O	31	I/O	I/O
10	GND	GND	32	GND	GND
11	I/O	I/O	33	CLK, I/O	CLK, I/O
12	I/O	I/O	34	MODE	MODE
13	I/O	I/O	35	V_{CC}	V_{CC}
14	V_{CC}	V_{CC}	36	SDI, I/O	SDI, I/O
15	I/O	I/O	37	DCLK, I/O	DCLK, I/O
16	V_{CC}	V_{CC}	38	PRA, I/O	PRA, I/O
17	I/O	I/O	39	PRB, I/O	PRB, I/O
18	I/O	I/O	40	I/O	I/O
19	I/O	I/O	41	I/O	I/O
20	I/O	I/O	42	I/O	I/O
21	GND	GND	43	GND	GND
22	I/O	I/O	44	I/O	I/O

Package Pin Assignments

68-Pin PLCC

68-Pin
PLCC

1 68
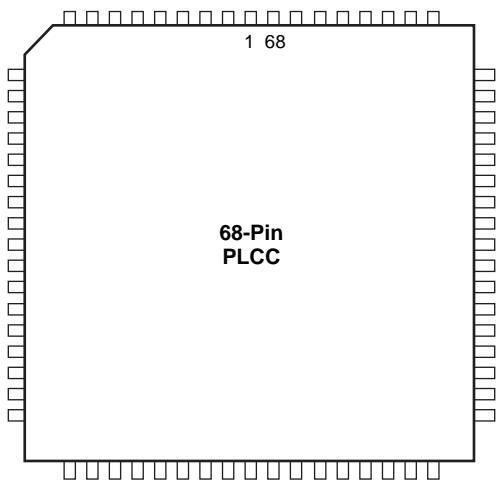
68-Pin PLCC

Pin Number	A40MX02 Function	A40MX04 Function	Pin Number	A40MX02 Function	A40MX04 Function	Pin Number	A40MX02 Function	A40MX04 Function
1	I/O	I/O	24	I/O	I/O	47	I/O	I/O
2	I/O	I/O	25	V_{CC}	V_{CC}	48	I/O	I/O
3	I/O	I/O	26	I/O	I/O	49	GND	GND
4	V_{CC}	V_{CC}	27	I/O	I/O	50	I/O	I/O
5	I/O	I/O	28	I/O	I/O	51	I/O	I/O
6	I/O	I/O	29	I/O	I/O	52	CLK, I/O	CLK, I/O
7	I/O	I/O	30	I/O	I/O	53	I/O	I/O
8	I/O	I/O	31	I/O	I/O	54	MODE	MODE
9	I/O	I/O	32	GND	GND	55	V_{CC}	V_{CC}
10	I/O	I/O	33	I/O	I/O	56	SDI, I/O	SDI, I/O
11	I/O	I/O	34	I/O	I/O	57	DCLK, I/O	DCLK, I/O
12	I/O	I/O	35	I/O	I/O	58	PRA, I/O	PRA, I/O
13	I/O	I/O	36	I/O	I/O	59	PRB, I/O	PRB, I/O
14	GND	GND	37	I/O	I/O	60	I/O	I/O
15	GND	GND	38	V_{CC}	V_{CC}	61	I/O	I/O
16	I/O	I/O	39	I/O	I/O	62	I/O	I/O
17	I/O	I/O	40	I/O	I/O	63	I/O	I/O
18	I/O	I/O	41	I/O	I/O	64	I/O	I/O
19	I/O	I/O	42	I/O	I/O	65	I/O	I/O
20	I/O	I/O	43	I/O	I/O	66	GND	GND
21	V_{CC}	V_{CC}	44	I/O	I/O	67	I/O	I/O
22	I/O	I/O	45	I/O	I/O	68	I/O	I/O
23	I/O	I/O	46	I/O	I/O			

Package Pin Assignments (continued)

84-Pin PLCC

**84-Pin
PLCC**

1   84
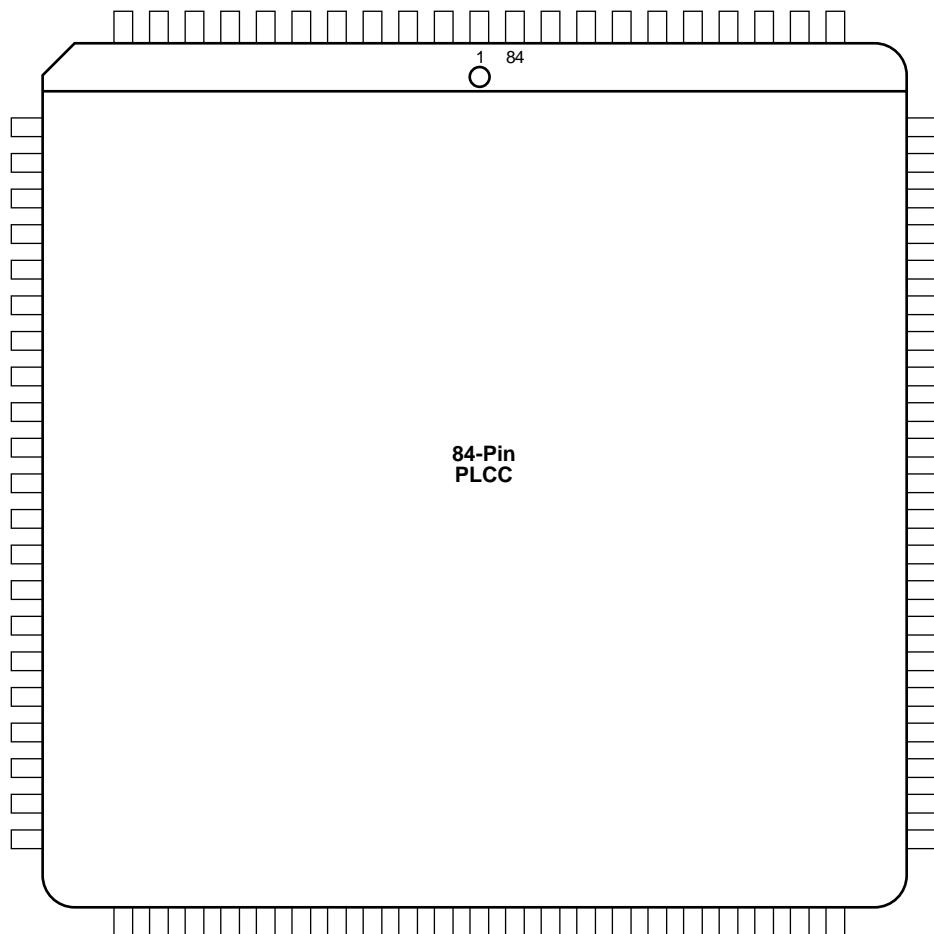
84-Pin PLCC

Pin Number	A40MX04 Function	A42MX09 Function	A42MX16 Function	A42MX24 Function	Pin Number	A40MX04 Function	A42MX09 Function	A42MX16 Function	A42MX24 Function
1	I/O	I/O	I/O	I/O	43	I/O	V_{CCA}	V_{CCA}	V_{CCA}
2	I/O	CLKB, I/O	CLKB, I/O	CLKB, I/O	44	I/O	I/O	I/O	I/O (WD)
3	I/O	I/O	I/O	I/O	45	I/O	I/O	I/O	I/O (WD)
4	V_{CC}	PRB, I/O	PRB, I/O	PRB, I/O	46	V_{CC}	I/O	I/O	I/O (WD)
5	I/O	I/O	I/O	I/O (WD)	47	I/O	I/O	I/O	I/O (WD)
6	I/O	GND	GND	GND	48	I/O	I/O	I/O	I/O
7	I/O	I/O	I/O	I/O	49	I/O	GND	GND	GND
8	I/O	I/O	I/O	I/O (WD)	50	I/O	I/O	I/O	I/O (WD)
9	I/O	I/O	I/O	I/O (WD)	51	I/O	I/O	I/O	I/O (WD)
10	I/O	DCLK, I/O	DCLK, I/O	DCLK, I/O	52	I/O	SDO, I/O	SDO, I/O	SDO, TDO (WD)
11	I/O	I/O	I/O	I/O	53	I/O	I/O	I/O	I/O
12	NC	MODE	MODE	MODE	54	I/O	I/O	I/O	I/O
13	I/O	I/O	I/O	I/O	55	I/O	I/O	I/O	I/O
14	I/O	I/O	I/O	I/O	56	I/O	I/O	I/O	I/O
15	I/O	I/O	I/O	I/O	57	I/O	I/O	I/O	I/O
16	I/O	I/O	I/O	I/O	58	I/O	I/O	I/O	I/O
17	I/O	I/O	I/O	I/O	59	I/O	I/O	I/O	I/O
18	GND	I/O	I/O	I/O	60	GND	I/O	I/O	I/O
19	GND	I/O	I/O	I/O	61	GND	I/O	I/O	I/O
20	I/O	I/O	I/O	I/O	62	I/O	I/O	I/O	TCK, I/O
21	I/O	I/O	I/O	I/O	63	I/O	GND (LP)	GND (LP)	GND (LP)
22	I/O	V_{CCA}	V_{CCI}	V_{CCI}	64	CLK, I/O	V_{CCA}	V_{CCA}	V_{CCA}
23	I/O	V_{CCI}	V_{CCA}	V_{CCA}	65	I/O	V_{CCI}	V_{CCI}	V_{CCI}
24	I/O	I/O	I/O	I/O	66	MODE	I/O	I/O	I/O
25	V_{CC}	I/O	I/O	I/O	67	V_{CC}	I/O	I/O	I/O
26	V_{CC}	I/O	I/O	I/O	68	V_{CC}	I/O	I/O	I/O
27	I/O	I/O	I/O	I/O	69	I/O	I/O	I/O	I/O
28	I/O	GND	GND	GND	70	I/O	GND	GND	GND
29	I/O	I/O	I/O	I/O	71	I/O	I/O	I/O	I/O
30	I/O	I/O	I/O	I/O	72	SDI, I/O	I/O	I/O	I/O
31	I/O	I/O	I/O	I/O	73	DCLK, I/O	I/O	I/O	I/O
32	I/O	I/O	I/O	I/O	74	PRA, I/O	I/O	I/O	I/O
33	V_{CC}	I/O	I/O	I/O	75	PRB, I/O	I/O	I/O	I/O
34	I/O	I/O	I/O	TMS, I/O	76	I/O	SDI, I/O	SDI, I/O	SDI, I/O
35	I/O	I/O	I/O	TDI, I/O	77	I/O	I/O	I/O	I/O
36	I/O	I/O	I/O	I/O (WD)	78	I/O	I/O	I/O	I/O (WD)
37	I/O	I/O	I/O	I/O	79	I/O	I/O	I/O	I/O (WD)
38	I/O	I/O	I/O	I/O (WD)	80	I/O	I/O	I/O	I/O (WD)
39	I/O	I/O	I/O	I/O (WD)	81	I/O	PRA, I/O	PRA, I/O	PRA, I/O
40	GND	I/O	I/O	I/O	82	GND	I/O	I/O	I/O
41	I/O	I/O	I/O	I/O	83	I/O	CLKA, I/O	CLKA, I/O	CLKA, I/O
42	I/O	I/O	I/O	I/O	84	I/O	V_{CCA}	V_{CCA}	V_{CCA}

Package Pin Assignments (continued)

100-Pin PQFP Package (Top View)

**100-Pin
PQFP**

100
1
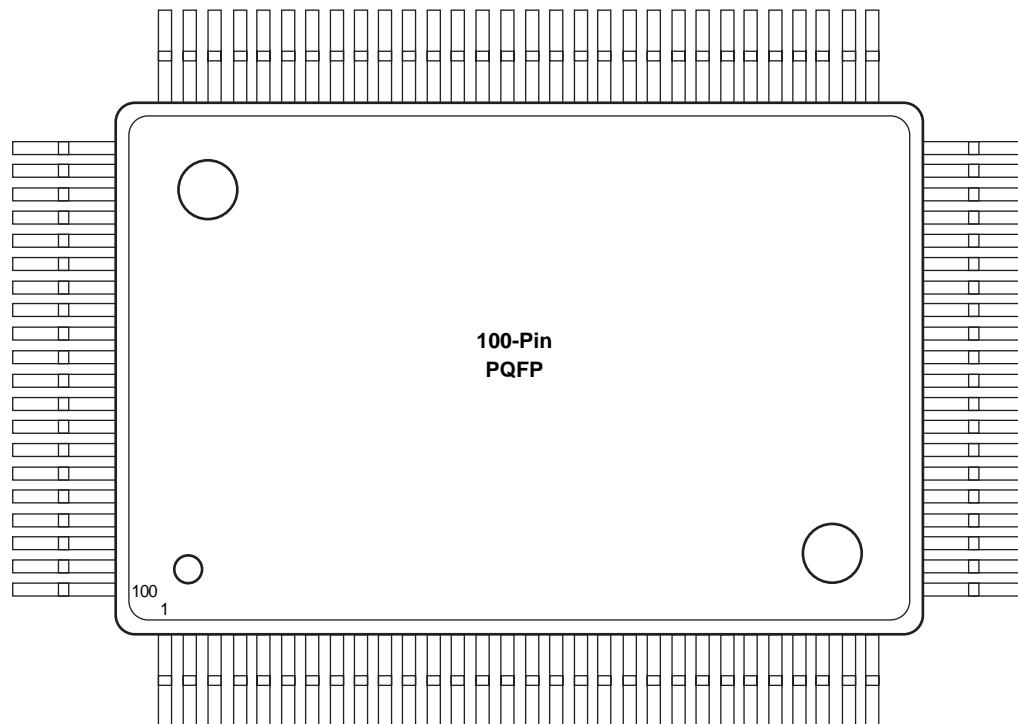
100-Pin PQFP

Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function	Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function
1	NC	NC	I/O	I/O	40	I/O	I/O	V_{CCA}	V_{CCA}
2	NC	NC	DCLK, I/O	DCLK, I/O	41	I/O	I/O	I/O	I/O
3	NC	NC	I/O	I/O	42	I/O	I/O	I/O	I/O
4	NC	NC	MODE	MODE	43	V_{CC}	V_{CC}	I/O	I/O
5	NC	NC	I/O	I/O	44	V_{CC}	V_{CC}	I/O	I/O
6	PRB, I/O	PRB, I/O	I/O	I/O	45	I/O	I/O	I/O	I/O
7	I/O	I/O	I/O	I/O	46	I/O	I/O	GND	GND
8	I/O	I/O	I/O	I/O	47	I/O	I/O	I/O	I/O
9	I/O	I/O	GND	GND	48	NC	I/O	I/O	I/O
10	I/O	I/O	I/O	I/O	49	NC	I/O	I/O	I/O
11	I/O	I/O	I/O	I/O	50	NC	I/O	I/O	I/O
12	I/O	I/O	I/O	I/O	51	NC	NC	I/O	I/O
13	GND	GND	I/O	I/O	52	NC	NC	SDO, I/O	SDO, I/O
14	I/O	I/O	I/O	I/O	53	NC	NC	I/O	I/O
15	I/O	I/O	I/O	I/O	54	NC	NC	I/O	I/O
16	I/O	I/O	V_{CCA}	V_{CCA}	55	NC	NC	I/O	I/O
17	I/O	I/O	V_{CCI}	V_{CCA}	56	V_{CC}	V_{CC}	I/O	I/O
18	I/O	I/O	I/O	I/O	57	I/O	I/O	GND	GND
19	V_{CC}	V_{CC}	I/O	I/O	58	I/O	I/O	I/O	I/O
20	I/O	I/O	I/O	I/O	59	I/O	I/O	I/O	I/O
21	I/O	I/O	I/O	I/O	60	I/O	I/O	I/O	I/O
22	I/O	I/O	GND	GND	61	I/O	I/O	I/O	I/O
23	I/O	I/O	I/O	I/O	62	I/O	I/O	I/O	I/O
24	I/O	I/O	I/O	I/O	63	GND	GND	I/O	I/O
25	I/O	I/O	I/O	I/O	64	I/O	I/O	GND (LP)	GND (LP)
26	I/O	I/O	I/O	I/O	65	I/O	I/O	V_{CCA}	V_{CCA}
27	NC	NC	I/O	I/O	66	I/O	I/O	V_{CCI}	V_{CCI}
28	NC	NC	I/O	I/O	67	I/O	I/O	V_{CCA}	V_{CCA}
29	NC	NC	I/O	I/O	68	I/O	I/O	I/O	I/O
30	NC	NC	I/O	I/O	69	V_{CC}	V_{CC}	I/O	I/O
31	NC	I/O	I/O	I/O	70	I/O	I/O	I/O	I/O
32	NC	I/O	I/O	I/O	71	I/O	I/O	I/O	I/O
33	NC	I/O	I/O	I/O	72	I/O	I/O	GND	GND
34	I/O	I/O	GND	GND	73	I/O	I/O	I/O	I/O
35	I/O	I/O	I/O	I/O	74	I/O	I/O	I/O	I/O
36	GND	GND	I/O	I/O	75	I/O	I/O	I/O	I/O
37	GND	GND	I/O	I/O	76	I/O	I/O	I/O	I/O
38	I/O	I/O	I/O	I/O	77	NC	NC	I/O	I/O
39	I/O	I/O	I/O	I/O	78	NC	NC	I/O	I/O

100-Pin PQFP (Continued)

Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function	Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function
79	NC	NC	SDI, I/O	SDI, I/O	90	CLK, I/O	CLK, I/O	V_{CCA}	V_{CCA}
80	NC	I/O	I/O	I/O	91	I/O	I/O	I/O	I/O
81	NC	I/O	I/O	I/O	92	MODE	MODE	CLKB, I/O	CLKB, I/O
82	NC	I/O	I/O	I/O	93	V_{CC}	V_{CC}	I/O	I/O
83	I/O	I/O	I/O	I/O	94	V_{CC}	V_{CC}	PRB, I/O	PRB, I/O
84	I/O	I/O	GND	GND	95	NC	I/O	I/O	I/O
85	I/O	I/O	I/O	I/O	96	NC	I/O	GND	GND
86	GND	GND	I/O	I/O	97	NC	I/O	I/O	I/O
87	GND	GND	PRA, I/O	PRA, I/O	98	SDI, I/O	SDI, I/O	I/O	I/O
88	I/O	I/O	I/O	I/O	99	DCLK, I/O	DCLK, I/O	I/O	I/O
89	I/O	I/O	CLKA, I/O	CLKA, I/O	100	PRA, I/O	PRA, I/O	I/O	I/O

Package Pin Assignments (continued)

160-Pin PQFP Package (Top View)
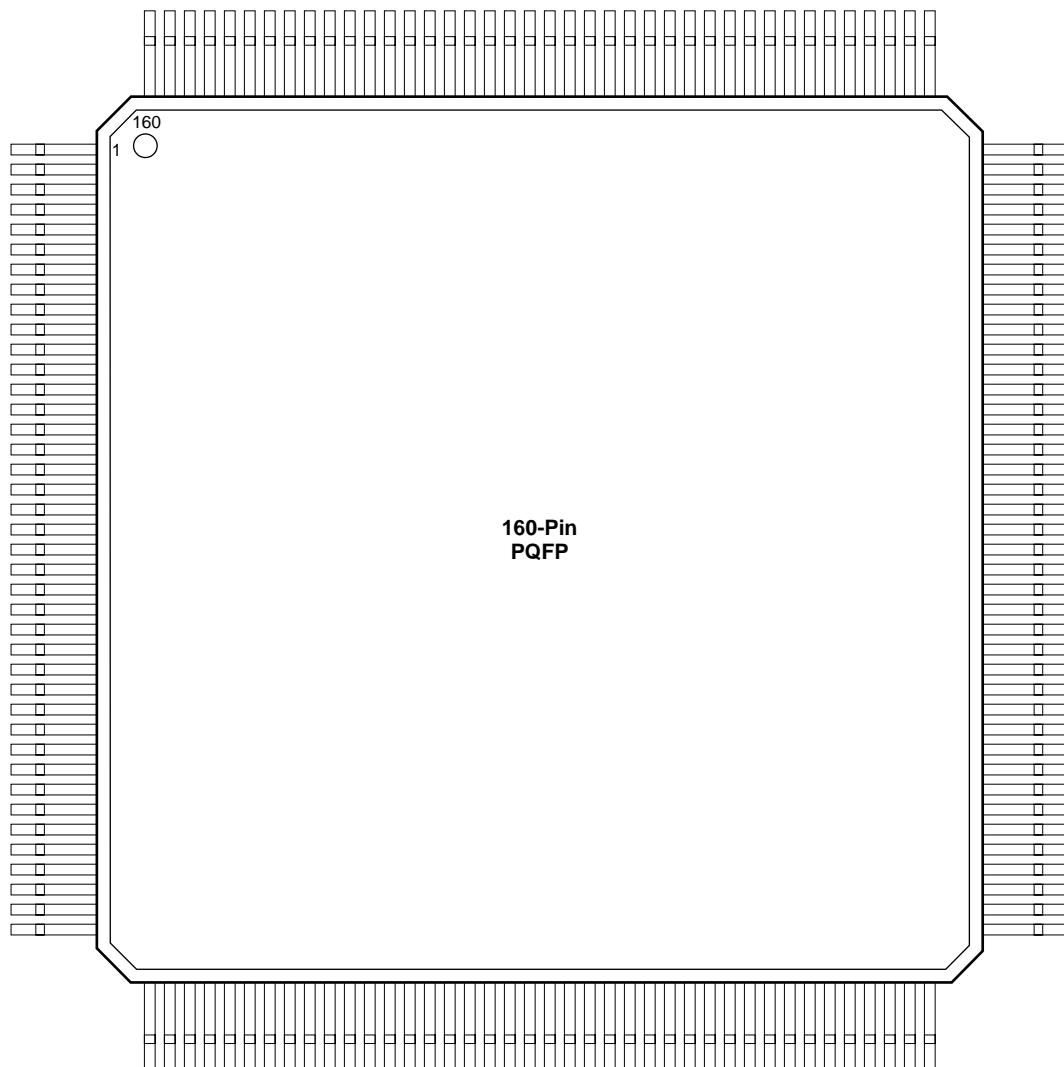
160-Pin
PQFP

160-Pin PQFP

Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Fucntion	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Fucntion
1	I/O	I/O	I/O	41	I/O	I/O	I/O
2	DCLK, I/O	DCLK, I/O	DCLK, I/O	42	I/O	I/O	I/O
3	NC	I/O	I/O	43	I/O	I/O	I/O
4	I/O	I/O	I/O (WD)	44	GND	GND	GND
5	I/O	I/O	I/O (WD)	45	I/O	I/O	I/O
6	NC	V_{CCI}	V_{CCI}	46	I/O	I/O	I/O
7	I/O	I/O	I/O	47	I/O	I/O	I/O
8	I/O	I/O	I/O	48	I/O	I/O	I/O
9	I/O	I/O	I/O	49	GND	GND	GND
10	NC	I/O	I/O	50	I/O	I/O	I/O
11	GND	GND	GND	51	I/O	I/O	I/O
12	NC	I/O	I/O	52	NC	I/O	I/O
13	I/O	I/O	I/O (WD)	53	I/O	I/O	I/O
14	I/O	I/O	I/O (WD)	54	NC	V_{CCA}	V_{CCA}
15	I/O	I/O	I/O	55	I/O	I/O	I/O
16	PRB, I/O	PRB, I/O	PRB, I/O	56	I/O	I/O	I/O
17	I/O	I/O	I/O	57	V_{CCA}	V_{CCA}	V_{CCA}
18	CLKB, I/O	CLKB, I/O	CLKB, I/O	58	V_{CCI}	V_{CCI}	V_{CCI}
19	I/O	I/O	I/O	59	GND	GND	GND
20	V_{CCA}	V_{CCA}	V_{CCA}	60	V_{CCA}	V_{CCA}	V_{CCA}
21	CLKA, I/O	CLKA, I/O	CLKA, I/O	61	GND (LP)	GND (LP)	GND (LP)
22	I/O	I/O	I/O	62	I/O	I/O	TCK, I/O
23	PRA, I/O	PRA, I/O	PRA, I/O	63	I/O	I/O	I/O
24	NC	I/O	I/O (WD)	64	GND	GND	GND
25	I/O	I/O	I/O (WD)	65	I/O	I/O	I/O
26	I/O	I/O	I/O	66	I/O	I/O	I/O
27	I/O	I/O	I/O	67	I/O	I/O	I/O
28	NC	I/O	I/O	68	I/O	I/O	I/O
29	I/O	I/O	I/O (WD)	69	GND	GND	GND
30	GND	GND	GND	70	NC	I/O	I/O
31	NC	I/O	I/O (WD)	71	I/O	I/O	I/O
32	I/O	I/O	I/O	72	I/O	I/O	I/O
33	I/O	I/O	I/O	73	I/O	I/O	I/O
34	I/O	I/O	I/O	74	I/O	I/O	I/O
35	NC	V_{CCI}	V_{CCI}	75	NC	I/O	I/O
36	I/O	I/O	I/O (WD)	76	I/O	I/O	I/O
37	I/O	I/O	I/O (WD)	77	NC	I/O	I/O
38	SDI, I/O	SDI, I/O	SDI, I/O	78	I/O	I/O	I/O
39	I/O	I/O	I/O	79	NC	I/O	I/O
40	GND	GND	GND	80	GND	GND	GND

160-Pin PQFP (Continued)

Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Fucntion	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Fucntion
81	I/O	I/O	I/O	121	I/O	I/O	I/O
82	SDO, I/O	SDO, I/O	SDO, TDO, I/O	122	I/O	I/O	I/O
83	I/O	I/O	I/O (WD)	123	I/O	I/O	I/O
84	I/O	I/O	I/O (WD)	124	NC	I/O	I/O
85	I/O	I/O	I/O	125	GND	GND	GND
86	NC	V_{CCI}	V_{CCI}	126	I/O	I/O	I/O
87	I/O	I/O	I/O	127	I/O	I/O	I/O
88	I/O	I/O	I/O (WD)	128	I/O	I/O	I/O
89	GND	GND	GND	129	NC	I/O	I/O
90	NC	I/O	I/O	130	GND	GND	GND
91	I/O	I/O	I/O	131	I/O	I/O	I/O
92	I/O	I/O	I/O	132	I/O	I/O	I/O
93	I/O	I/O	I/O	133	I/O	I/O	I/O
94	I/O	I/O	I/O	134	I/O	I/O	I/O
95	I/O	I/O	I/O	135	NC	V_{CCA}	V_{CCA}
96	I/O	I/O	I/O (WD)	136	I/O	I/O	I/O
97	I/O	I/O	I/O	137	I/O	I/O	I/O
98	V_{CCA}	V_{CCA}	V_{CCA}	138	NC	V_{CCA}	V_{CCA}
99	GND	GND	GND	139	V_{CCI}	V_{CCI}	V_{CCI}
100	NC	I/O	I/O	140	GND	GND	GND
101	I/O	I/O	I/O	141	NC	I/O	I/O
102	I/O	I/O	I/O	142	I/O	I/O	I/O
103	NC	I/O	I/O	143	I/O	I/O	I/O
104	I/O	I/O	I/O	144	I/O	I/O	I/O
105	I/O	I/O	I/O	145	GND	GND	GND
106	I/O	I/O	I/O (WD)	146	NC	I/O	I/O
107	I/O	I/O	I/O (WD)	147	I/O	I/O	I/O
108	I/O	I/O	I/O	148	I/O	I/O	I/O
109	GND	GND	GND	149	I/O	I/O	I/O
110	NC	I/O	I/O	150	NC	V_{CCA}	V_{CCA}
111	I/O	I/O	I/O (WD)	151	NC	I/O	I/O
112	I/O	I/O	I/O (WD)	152	NC	I/O	I/O
113	I/O	I/O	I/O	153	NC	I/O	I/O
114	NC	V_{CCI}	V_{CCI}	154	NC	I/O	I/O
115	I/O	I/O	I/O (WD)	155	GND	GND	GND
116	NC	I/O	I/O (WD)	156	I/O	I/O	I/O
117	I/O	I/O	I/O	157	I/O	I/O	I/O
118	I/O	I/O	TDI, I/O	158	I/O	I/O	I/O
119	I/O	I/O	TMS, I/O	159	MODE	MODE	MODE
120	GND	GND	GND	160	GND	GND	GND

Package Pin Assignments (continued)

208-Pin PQFP Package (Top View)

208

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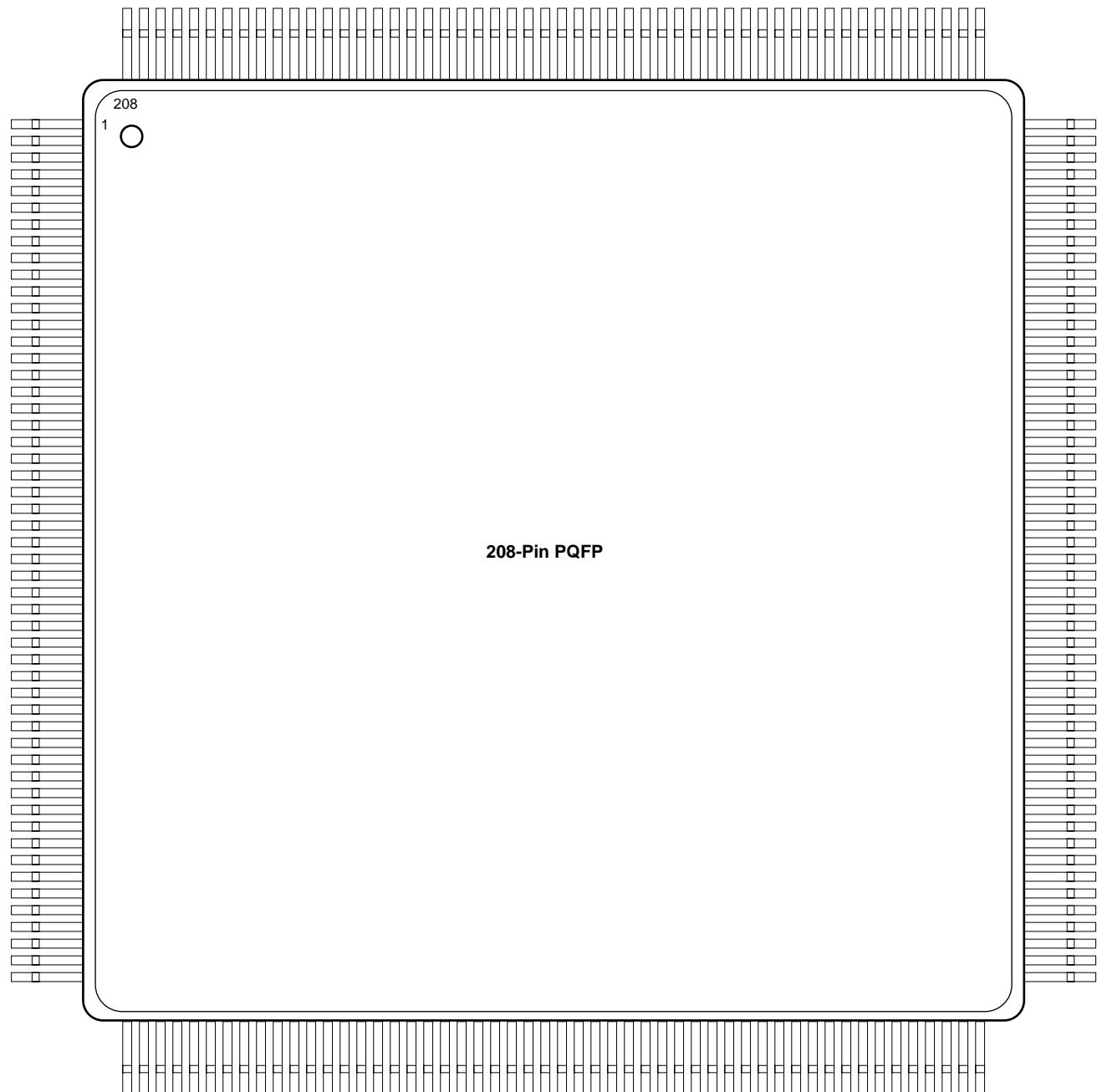
208-Pin PQFP

208-Pin PQFP

Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function	Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function
1	GND	GND	GND	43	NC	I/O	I/O
2	NC	V_{CCA}	V_{CCA}	44	I/O	I/O	I/O
3	MODE	MODE	MODE	45	I/O	I/O	I/O
4	I/O	I/O	I/O	46	I/O	I/O	I/O
5	I/O	I/O	I/O	47	I/O	I/O	I/O
6	I/O	I/O	I/O	48	I/O	I/O	I/O
7	I/O	I/O	I/O	49	I/O	I/O	I/O
8	I/O	I/O	I/O	50	NC	I/O	I/O
9	NC	I/O	I/O	51	NC	I/O	I/O
10	NC	I/O	I/O	52	GND	GND	GND
11	NC	I/O	I/O	53	GND	GND	GND
12	I/O	I/O	I/O	54	I/O	TMS, I/O	TMS, I/O
13	I/O	I/O	I/O	55	I/O	TDI, I/O	TDI, I/O
14	I/O	I/O	I/O	56	I/O	I/O	I/O
15	I/O	I/O	I/O	57	I/O	I/O (WD)	I/O (WD)
16	NC	I/O	I/O	58	I/O	I/O (WD)	I/O (WD)
17	V_{CCA}	V_{CCA}	V_{CCA}	59	I/O	I/O	I/O
18	I/O	I/O	I/O	60	V_{CCI}	V_{CCI}	V_{CCI}
19	I/O	I/O	I/O	61	NC	I/O	I/O
20	I/O	I/O	I/O	62	NC	I/O	I/O
21	I/O	I/O	I/O	63	I/O	I/O	I/O
22	GND	GND	GND	64	I/O	I/O	I/O
23	I/O	I/O	I/O	65	I/O	I/O	QCLKA, I/O
24	I/O	I/O	I/O	66	I/O	I/O (WD)	I/O (WD)
25	I/O	I/O	I/O	67	NC	I/O (WD)	I/O (WD)
26	I/O	I/O	I/O	68	NC	I/O	I/O
27	GND	GND	GND	69	I/O	I/O	I/O
28	V_{CCI}	V_{CCI}	V_{CCI}	70	I/O	I/O (WD)	I/O (WD)
29	V_{CCA}	V_{CCA}	V_{CCA}	71	I/O	I/O (WD)	I/O (WD)
30	I/O	I/O	I/O	72	I/O	I/O	I/O
31	I/O	I/O	I/O	73	I/O	I/O	I/O
32	V_{CCA}	V_{CCA}	V_{CCA}	74	I/O	I/O	I/O
33	I/O	I/O	I/O	75	I/O	I/O	I/O
34	I/O	I/O	I/O	76	I/O	I/O	I/O
35	I/O	I/O	I/O	77	I/O	I/O	I/O
36	I/O	I/O	I/O	78	GND	GND	GND
37	I/O	I/O	I/O	79	V_{CCA}	V_{CCA}	V_{CCA}
38	I/O	I/O	I/O	80	NC	V_{CCI}	V_{CCI}
39	I/O	I/O	I/O	81	I/O	I/O	I/O
40	I/O	I/O	I/O	82	I/O	I/O	I/O
41	NC	I/O	I/O	83	I/O	I/O	I/O
42	NC	I/O	I/O	84	I/O	I/O	I/O

208-Pin PQFP (Continued)

Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function	Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function
85	I/O	I/O (WD)	I/O (WD)	127	I/O	I/O	I/O
86	I/O	I/O (WD)	I/O (WD)	128	I/O	TCK, I/O	TCK, I/O
87	I/O	I/O	I/O	129	GND (LP)	GND (LP)	GND (LP)
88	I/O	I/O	I/O	130	V_{CCA}	V_{CCA}	V_{CCA}
89	NC	I/O	I/O	131	GND	GND	GND
90	NC	I/O	I/O	132	V_{CCI}	V_{CCI}	V_{CCI}
91	I/O	I/O	QCLKB, I/O	133	V_{CCA}	V_{CCA}	V_{CCA}
92	I/O	I/O	I/O	134	I/O	I/O	I/O
93	I/O	I/O (WD)	I/O (WD)	135	I/O	I/O	I/O
94	I/O	I/O (WD)	I/O (WD)	136	V_{CCA}	V_{CCA}	V_{CCA}
95	NC	I/O	I/O	137	I/O	I/O	I/O
96	NC	I/O	I/O	138	I/O	I/O	I/O
97	NC	I/O	I/O	139	I/O	I/O	I/O
98	V_{CCI}	V_{CCI}	V_{CCI}	140	I/O	I/O	I/O
99	I/O	I/O	I/O	141	NC	I/O	I/O
100	I/O	I/O (WD)	I/O (WD)	142	I/O	I/O	I/O
101	I/O	I/O (WD)	I/O (WD)	143	I/O	I/O	I/O
102	I/O	I/O	I/O	144	I/O	I/O	I/O
103	SDO, I/O	SDO, TDO, I/O	SDO, TDO, I/O	145	I/O	I/O	I/O
104	I/O	I/O	I/O	146	NC	I/O	I/O
105	GND	GND	GND	147	NC	I/O	I/O
106	NC	V_{CCA}	V_{CCA}	148	NC	I/O	I/O
107	I/O	I/O	I/O	149	NC	I/O	I/O
108	I/O	I/O	I/O	150	GND	GND	GND
109	I/O	I/O	I/O	151	I/O	I/O	I/O
110	I/O	I/O	I/O	152	I/O	I/O	I/O
111	I/O	I/O	I/O	153	I/O	I/O	I/O
112	NC	I/O	I/O	154	I/O	I/O	I/O
113	NC	I/O	I/O	155	I/O	I/O	I/O
114	NC	I/O	I/O	156	I/O	I/O	I/O
115	NC	I/O	I/O	157	GND	GND	GND
116	I/O	I/O	I/O	158	I/O	I/O	I/O
117	I/O	I/O	I/O	159	SDI, I/O	SDI, I/O	SDI, I/O
118	I/O	I/O	I/O	160	I/O	I/O	I/O
119	I/O	I/O	I/O	161	I/O	I/O (WD)	I/O (WD)
120	I/O	I/O	I/O	162	I/O	I/O (WD)	I/O (WD)
121	I/O	I/O	I/O	163	I/O	I/O	I/O
122	I/O	I/O	I/O	164	V_{CCI}	V_{CCI}	V_{CCI}
123	I/O	I/O	I/O	165	NC	I/O	I/O
124	I/O	I/O	I/O	166	NC	I/O	I/O
125	I/O	I/O	I/O	167	I/O	I/O	I/O
126	GND	GND	GND	168	I/O	I/O (WD)	I/O (WD)

208-Pin PQFP (Continued)

Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function	Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function
169	I/O	I/O (WD)	I/O (WD)	189	I/O	I/O	I/O
170	I/O	I/O	I/O	190	I/O	I/O (WD)	I/O (WD)
171	NC	I/O	QCLKD, I/O	191	I/O	I/O (WD)	I/O (WD)
172	I/O	I/O	I/O	192	I/O	I/O	I/O
173	I/O	I/O	I/O	193	NC	I/O	I/O
174	I/O	I/O	I/O	194	NC	I/O (WD)	I/O (WD)
175	I/O	I/O	I/O	195	NC	I/O (WD)	I/O (WD)
176	I/O	I/O (WD)	I/O (WD)	196	I/O	I/O	QCLKC, I/O
177	I/O	I/O (WD)	I/O (WD)	197	NC	I/O	I/O
178	PRA, I/O	PRA, I/O	PRA, I/O	198	NC	I/O	I/O
179	I/O	I/O	I/O	199	I/O	I/O	I/O
180	CLKA, I/O	CLKA, I/O	CLKA, I/O	200	I/O	I/O	I/O
181	NC	I/O	I/O	201	NC	I/O	I/O
182	NC	V_{CCI}	V_{CCI}	202	V_{CCI}	V_{CCI}	V_{CCI}
183	V_{CCA}	V_{CCA}	V_{CCA}	203	I/O	I/O (WD)	I/O (WD)
184	GND	GND	GND	204	I/O	I/O (WD)	I/O (WD)
185	I/O	I/O	I/O	205	I/O	I/O	I/O
186	CLKB, I/O	CLKB, I/O	CLKB, I/O	206	I/O	I/O	I/O
187	I/O	I/O	I/O	207	DCLK, I/O	DCLK, I/O	DCLK, I/O
188	PRB, I/O	PRB, I/O	PRB, I/O	208	I/O	I/O	I/O

Package Pin Assignments (continued)

240-Pin PQFP Package (Top View)
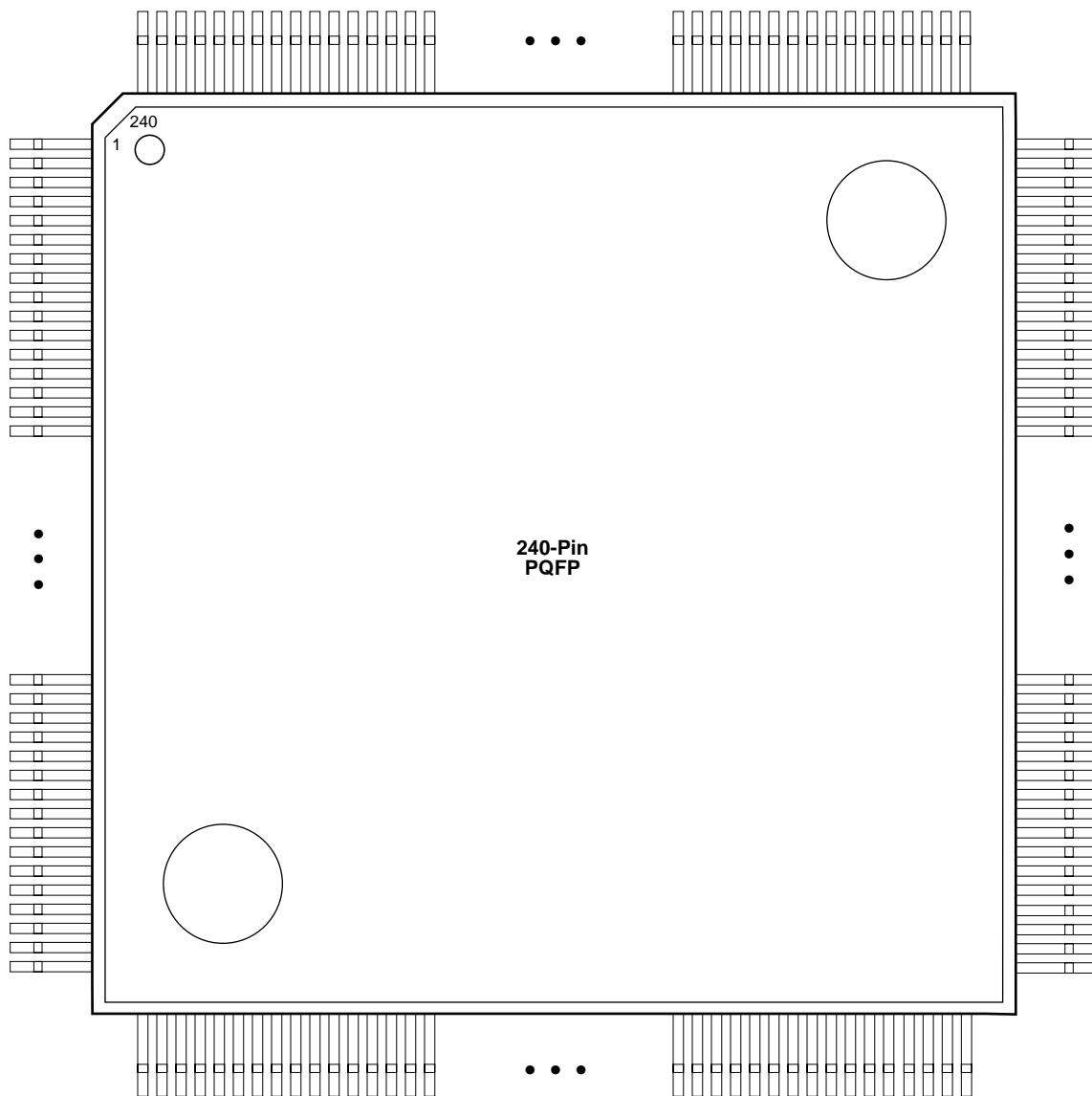
**240-Pin
PQFP**

240-Pin PQFP

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
1	I/O	41	I/O	81	I/O	121	GND
2	DCLK, I/O	42	I/O	82	I/O	122	I/O
3	I/O	43	I/O	83	I/O	123	SDO, TDO, I/O
4	I/O	44	I/O	84	I/O	124	I/O
5	I/O	45	QCLKD, I/O	85	V_{CCA}	125	I/O (WD)
6	I/O (WD)	46	I/O	86	I/O	126	I/O (WD)
7	I/O (WD)	47	I/O (WD)	87	I/O	127	I/O
8	V_{CCI}	48	I/O (WD)	88	V_{CCA}	128	V_{CCI}
9	I/O	49	I/O	89	V_{CCI}	129	I/O
10	I/O	50	I/O	90	V_{CCA}	130	I/O
11	I/O	51	I/O	91	GND (LP)	131	I/O
12	I/O	52	V_{CCI}	92	TCK, I/O	132	I/O (WD)
13	I/O	53	I/O	93	I/O	133	I/O (WD)
14	I/O	54	I/O (WD)	94	GND	134	I/O
15	QCLKC, I/O	55	I/O (WD)	95	I/O	135	QCLKB, I/O
16	I/O	56	I/O	96	I/O	136	I/O
17	I/O (WD)	57	SDI, I/O	97	I/O	137	I/O
18	I/O (WD)	58	I/O	98	I/O	138	I/O
19	I/O	59	V_{CCA}	99	I/O	139	I/O
20	I/O	60	GND	100	I/O	140	I/O
21	I/O (WD)	61	GND	101	I/O	141	I/O
22	I/O (WD)	62	I/O	102	I/O	142	I/O (WD)
23	I/O	63	I/O	103	I/O	143	I/O (WD)
24	PRB, I/O	64	I/O	104	I/O	144	I/O
25	I/O	65	I/O	105	I/O	145	I/O
26	CLKB, I/O	66	I/O	106	I/O	146	I/O
27	I/O	67	I/O	107	I/O	147	I/O
28	GND	68	I/O	108	V_{CCI}	148	I/O
29	V_{CCA}	69	I/O	109	I/O	149	I/O
30	V_{CCI}	70	I/O	110	I/O	150	V_{CCI}
31	I/O	71	V_{CCI}	111	I/O	151	V_{CCA}
32	CLKA, I/O	72	I/O	112	I/O	152	GND
33	I/O	73	I/O	113	I/O	153	I/O
34	PRA, I/O	74	I/O	114	I/O	154	I/O
35	I/O	75	I/O	115	I/O	155	I/O
36	I/O	76	I/O	116	I/O	156	I/O
37	I/O (WD)	77	I/O	117	I/O	157	I/O
38	I/O (WD)	78	I/O	118	V_{CCA}	158	I/O
39	I/O	79	I/O	119	GND	159	I/O (WD)
40	I/O	80	I/O	120	GND	160	I/O (WD)

240-Pin PQFP (Continued)

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
161	I/O	181	V_{CCA}	201	I/O	221	I/O
162	I/O	182	GND	202	I/O	222	I/O
163	I/O (WD)	183	I/O	203	I/O	223	I/O
164	I/O (WD)	184	I/O	204	I/O	224	I/O
165	I/O	185	I/O	205	I/O	225	I/O
166	QCLKA, I/O	186	I/O	206	V_{CCA}	226	I/O
167	I/O	187	I/O	207	I/O	227	V_{CCI}
168	I/O	188	I/O	208	I/O	228	I/O
169	I/O	189	I/O	209	V_{CCA}	229	I/O
170	I/O	190	I/O	210	V_{CCI}	230	I/O
171	I/O	191	I/O	211	I/O	231	I/O
172	V_{CCI}	192	V_{CCI}	212	I/O	232	I/O
173	I/O	193	I/O	213	I/O	233	I/O
174	I/O (WD)	194	I/O	214	I/O	234	I/O
175	I/O (WD)	195	I/O	215	I/O	235	I/O
176	I/O	196	I/O	216	I/O	236	I/O
177	I/O	197	I/O	217	I/O	237	GND
178	TDI, I/O	198	I/O	218	I/O	238	MODE
179	TMS, I/O	199	I/O	219	V_{CCA}	239	V_{CCA}
180	GND	200	I/O	220	I/O	240	GND

Package Pin Assignments (continued)

80-Pin VQFP
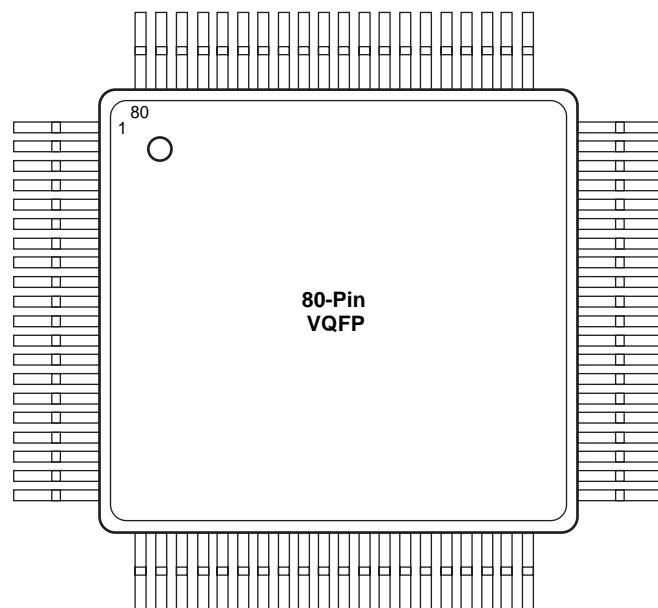
80-Pin VQFP

Pin Number	A40MX02 Function	A40MX04 Function	Pin Number	A40MX02 Function	A40MX04 Function
1	I/O	I/O	41	NC	I/O
2	NC	I/O	42	NC	I/O
3	NC	I/O	43	NC	I/O
4	NC	I/O	44	I/O	I/O
5	I/O	I/O	45	I/O	I/O
6	I/O	I/O	46	I/O	I/O
7	GND	GND	47	GND	GND
8	I/O	I/O	48	I/O	I/O
9	I/O	I/O	49	I/O	I/O
10	I/O	I/O	50	CLK, I/O	CLK, I/O
11	I/O	I/O	51	I/O	I/O
12	I/O	I/O	52	MODE	MODE
13	V_{CC}	V_{CC}	53	V_{CC}	V_{CC}
14	I/O	I/O	54	NC	I/O
15	I/O	I/O	55	NC	I/O
16	I/O	I/O	56	NC	I/O
17	NC	I/O	57	SDI, I/O	SDI, I/O
18	NC	I/O	58	DCLK, I/O	DCLK, I/O
19	NC	I/O	59	PRA, I/O	PRA, I/O
20	V_{CC}	V_{CC}	60	NC	NC
21	I/O	I/O	61	PRB, I/O	PRB, I/O
22	I/O	I/O	62	I/O	I/O
23	I/O	I/O	63	I/O	I/O
24	I/O	I/O	64	I/O	I/O
25	I/O	I/O	65	I/O	I/O
26	I/O	I/O	66	I/O	I/O
27	GND	GND	67	I/O	I/O
28	I/O	I/O	68	GND	GND
29	I/O	I/O	69	I/O	I/O
30	I/O	I/O	70	I/O	I/O
31	I/O	I/O	71	I/O	I/O
32	I/O	I/O	72	I/O	I/O
33	V_{CC}	V_{CC}	73	I/O	I/O
34	I/O	I/O	74	V_{CC}	V_{CC}
35	I/O	I/O	75	I/O	I/O
36	I/O	I/O	76	I/O	I/O
37	I/O	I/O	77	I/O	I/O
38	I/O	I/O	78	I/O	I/O
39	I/O	I/O	79	I/O	I/O
40	I/O	I/O	80	I/O	I/O

Package Pin Assignments (continued)

100-Pin VQFP Package (Top View)
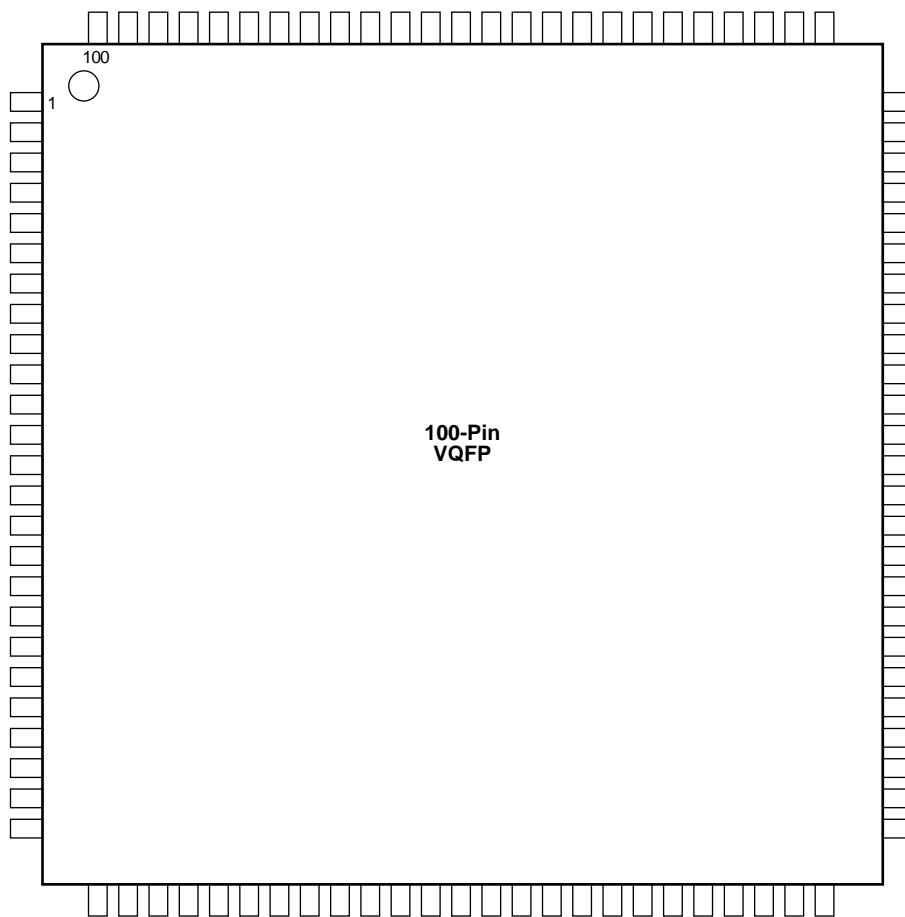
**100-Pin
VQFP**

100-Pin VQFP Package

Pin Number	A42MX09 Function	A42MX16 Function	Pin Number	A42MX09 Function	A42MX16 Function
1	I/O	I/O	51	I/O	I/O
2	MODE	MODE	52	I/O	I/O
3	I/O	I/O	53	I/O	I/O
4	I/O	I/O	54	I/O	I/O
5	I/O	I/O	55	GND	GND
6	I/O	I/O	56	I/O	I/O
7	GND	GND	57	I/O	I/O
8	I/O	I/O	58	I/O	I/O
9	I/O	I/O	59	I/O	I/O
10	I/O	I/O	60	I/O	I/O
11	I/O	I/O	61	I/O	I/O
12	I/O	I/O	62	GND (LP)	GND (LP)
13	I/O	I/O	63	V_{CCA}	V_{CCA}
14	V_{CCA}	NC	64	V_{CCI}	V_{CCI}
15	V_{CCI}	V_{CCI}	65	V_{CCA}	V_{CCA}
16	I/O	I/O	66	I/O	I/O
17	I/O	I/O	67	I/O	I/O
18	I/O	I/O	68	I/O	I/O
19	I/O	I/O	69	I/O	I/O
20	GND	GND	70	GND	GND
21	I/O	I/O	71	I/O	I/O
22	I/O	I/O	72	I/O	I/O
23	I/O	I/O	73	I/O	I/O
24	I/O	I/O	74	I/O	I/O
25	I/O	I/O	75	I/O	I/O
26	I/O	I/O	76	I/O	I/O
27	I/O	I/O	77	SDI, I/O	SDI, I/O
28	I/O	I/O	78	I/O	I/O
29	I/O	I/O	79	I/O	I/O
30	I/O	I/O	80	I/O	I/O
31	I/O	I/O	81	I/O	I/O
32	GND	GND	82	GND	GND
33	I/O	I/O	83	I/O	I/O
34	I/O	I/O	84	I/O	I/O
35	I/O	I/O	85	PRA, I/O	PRA, I/O
36	I/O	I/O	86	I/O	I/O
37	I/O	I/O	87	CLKA, I/O	CLKA, I/O
38	V_{CCA}	V_{CCA}	88	V_{CCA}	V_{CCA}
39	I/O	I/O	89	I/O	I/O
40	I/O	I/O	90	CLKB, I/O	CLKB, I/O
41	I/O	I/O	91	I/O	I/O
42	I/O	I/O	92	PRB, I/O	PRB, I/O
43	I/O	I/O	93	I/O	I/O
44	GND	GND	94	GND	GND
45	I/O	I/O	95	I/O	I/O
46	I/O	I/O	96	I/O	I/O
47	I/O	I/O	97	I/O	I/O
48	I/O	I/O	98	I/O	I/O
49	I/O	I/O	99	I/O	I/O
50	SDO, I/O	SDO, I/O	100	DCLK, I/O	DCLK, I/O

Package Pin Assignments (continued)

176-Pin TQFP Package (Top View)

**176-Pin
TQFP**

176

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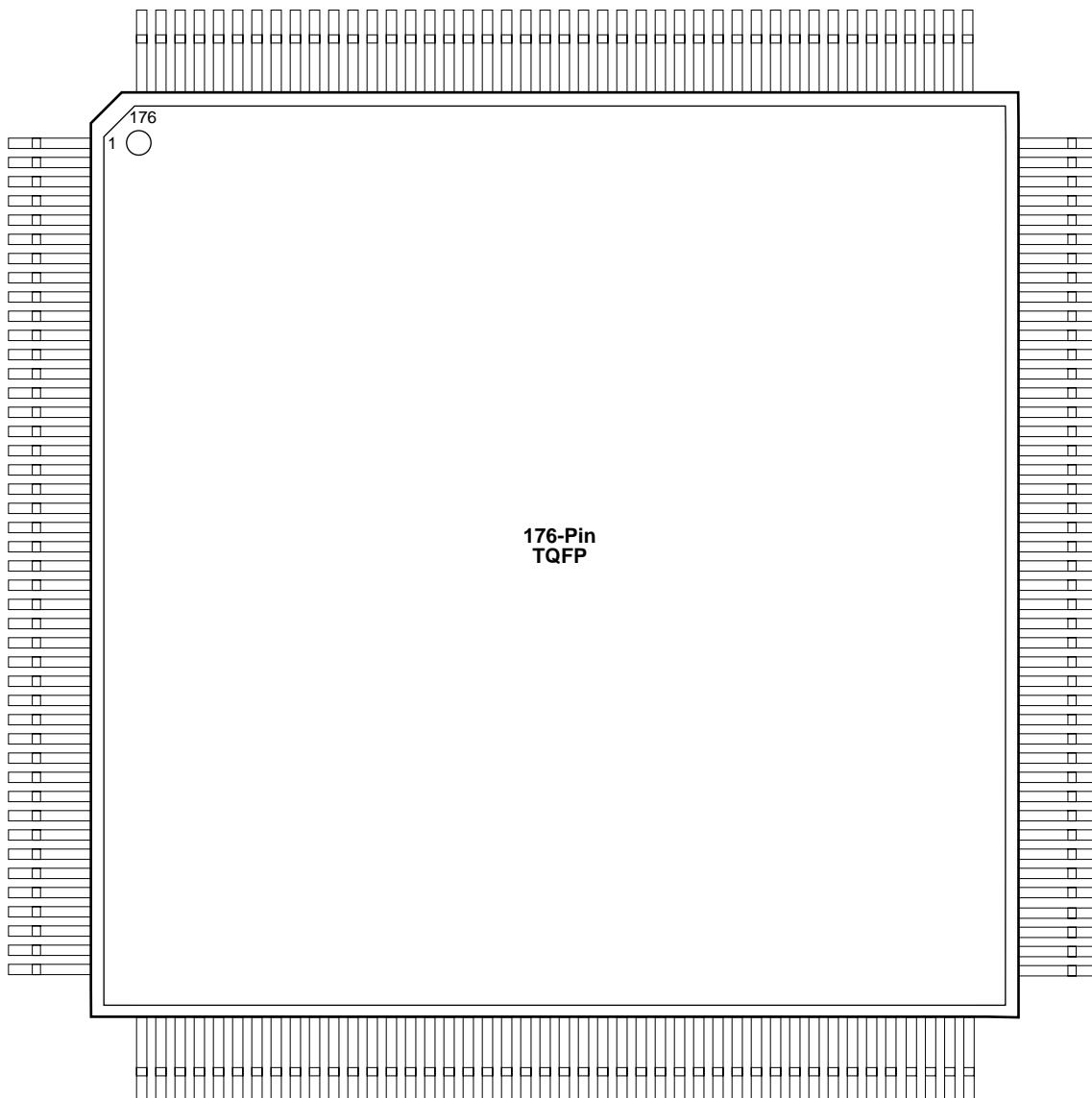
176-Pin TQFP

Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function
1	GND	GND	GND	45	GND	GND	GND
2	MODE	MODE	MODE	46	I/O	I/O	TMS, I/O
3	I/O	I/O	I/O	47	I/O	I/O	TDI, I/O
4	I/O	I/O	I/O	48	I/O	I/O	I/O
5	I/O	I/O	I/O	49	I/O	I/O	I/O (WD)
6	I/O	I/O	I/O	50	I/O	I/O	I/O (WD)
7	I/O	I/O	I/O	51	I/O	I/O	I/O
8	NC	NC	I/O	52	NC	V_{CCI}	V_{CCI}
9	I/O	I/O	I/O	53	I/O	I/O	I/O
10	NC	I/O	I/O	54	NC	I/O	I/O
11	NC	I/O	I/O	55	NC	I/O	I/O (WD)
12	I/O	I/O	I/O	56	I/O	I/O	I/O (WD)
13	NC	V_{CCA}	V_{CCA}	57	NC	NC	I/O
14	I/O	I/O	I/O	58	I/O	I/O	I/O
15	I/O	I/O	I/O	59	I/O	I/O	I/O (WD)
16	I/O	I/O	I/O	60	I/O	I/O	I/O (WD)
17	I/O	I/O	I/O	61	NC	I/O	I/O
18	GND	GND	GND	62	I/O	I/O	I/O
19	NC	I/O	I/O	63	I/O	I/O	I/O
20	NC	I/O	I/O	64	NC	I/O	I/O
21	I/O	I/O	I/O	65	I/O	I/O	I/O
22	NC	I/O	I/O	66	NC	I/O	I/O
23	GND	GND	GND	67	GND	GND	GND
24	NC	V_{CCI}	V_{CCI}	68	V_{CCA}	V_{CCA}	V_{CCA}
25	V_{CCA}	V_{CCA}	V_{CCA}	69	I/O	I/O	I/O (WD)
26	NC	I/O	I/O	70	I/O	I/O	I/O (WD)
27	NC	I/O	I/O	71	I/O	I/O	I/O
28	V_{CCI}	V_{CCA}	V_{CCA}	72	I/O	I/O	I/O
29	NC	I/O	I/O	73	I/O	I/O	I/O
30	I/O	I/O	I/O	74	NC	I/O	I/O
31	I/O	I/O	I/O	75	I/O	I/O	I/O
32	I/O	I/O	I/O	76	I/O	I/O	I/O
33	NC	NC	I/O	77	NC	NC	I/O (WD)
34	I/O	I/O	I/O	78	NC	I/O	I/O (WD)
35	I/O	I/O	I/O	79	I/O	I/O	I/O
36	I/O	I/O	I/O	80	NC	I/O	I/O
37	NC	I/O	I/O	81	I/O	I/O	I/O
38	NC	NC	I/O	82	NC	V_{CCI}	V_{CCI}
39	I/O	I/O	I/O	83	I/O	I/O	I/O
40	I/O	I/O	I/O	84	I/O	I/O	I/O (WD)
41	I/O	I/O	I/O	85	I/O	I/O	I/O (WD)
42	I/O	I/O	I/O	86	NC	I/O	I/O
43	I/O	I/O	I/O	87	SDO, I/O	SDO, I/O	SDO, TDO, I/O
44	I/O	I/O	I/O	88	I/O	I/O	I/O

176-Pin TQFP (Continued)

Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function
89	GND	GND	GND	133	GND	GND	GND
90	I/O	I/O	I/O	134	I/O	I/O	I/O
91	I/O	I/O	I/O	135	SDI, I/O	SDI, I/O	SDI, I/O
92	I/O	I/O	I/O	136	NC	I/O	I/O
93	I/O	I/O	I/O	137	I/O	I/O	I/O (WD)
94	I/O	I/O	I/O	138	I/O	I/O	I/O (WD)
95	I/O	I/O	I/O	139	I/O	I/O	I/O
96	NC	I/O	I/O	140	NC	V_{CCI}	V_{CCI}
97	NC	I/O	I/O	141	I/O	I/O	I/O
98	I/O	I/O	I/O	142	I/O	I/O	I/O
99	I/O	I/O	I/O	143	NC	I/O	I/O
100	I/O	I/O	I/O	144	NC	I/O	I/O (WD)
101	NC	NC	I/O	145	NC	NC	I/O (WD)
102	I/O	I/O	I/O	146	I/O	I/O	I/O
103	NC	I/O	I/O	147	NC	I/O	I/O
104	I/O	I/O	I/O	148	I/O	I/O	I/O
105	I/O	I/O	I/O	149	I/O	I/O	I/O
106	GND	GND	GND	150	I/O	I/O	I/O (WD)
107	NC	I/O	I/O	151	NC	I/O	I/O (WD)
108	NC	I/O	TCK, I/O	152	PRA, I/O	PRA, I/O	PRA, I/O
109	GND (LP)	GND (LP)	GND (LP)	153	I/O	I/O	I/O
110	V_{CCA}	V_{CCA}	V_{CCA}	154	CLKA, I/O	CLKA, I/O	CLKA, I/O
111	GND	GND	GND	155	V_{CCA}	V_{CCA}	V_{CCA}
112	V_{CCI}	V_{CCI}	V_{CCI}	156	GND	GND	GND
113	V_{CCA}	V_{CCA}	V_{CCA}	157	I/O	I/O	I/O
114	NC	I/O	I/O	158	CLKB, I/O	CLKB, I/O	CLKB, I/O
115	NC	I/O	I/O	159	I/O	I/O	I/O
116	NC	V_{CCA}	V_{CCA}	160	PRB, I/O	PRB, I/O	PRB, I/O
117	I/O	I/O	I/O	161	NC	I/O	I/O (WD)
118	I/O	I/O	I/O	162	I/O	I/O	I/O (WD)
119	I/O	I/O	I/O	163	I/O	I/O	I/O
120	I/O	I/O	I/O	164	I/O	I/O	I/O
121	NC	NC	I/O	165	NC	NC	I/O (WD)
122	I/O	I/O	I/O	166	NC	I/O	I/O (WD)
123	I/O	I/O	I/O	167	I/O	I/O	I/O
124	NC	I/O	I/O	168	NC	I/O	I/O
125	NC	I/O	I/O	169	I/O	I/O	I/O
126	NC	NC	I/O	170	NC	V_{CCI}	V_{CCI}
127	I/O	I/O	I/O	171	I/O	I/O	I/O (WD)
128	I/O	I/O	I/O	172	I/O	I/O	I/O (WD)
129	I/O	I/O	I/O	173	NC	I/O	I/O
130	I/O	I/O	I/O	174	I/O	I/O	I/O
131	I/O	I/O	I/O	175	DCLK, I/O	DCLK, I/O	DCLK, I/O
132	I/O	I/O	I/O	176	I/O	I/O	I/O

Package Pin Assignments

208-Pin CQFP (Top View)
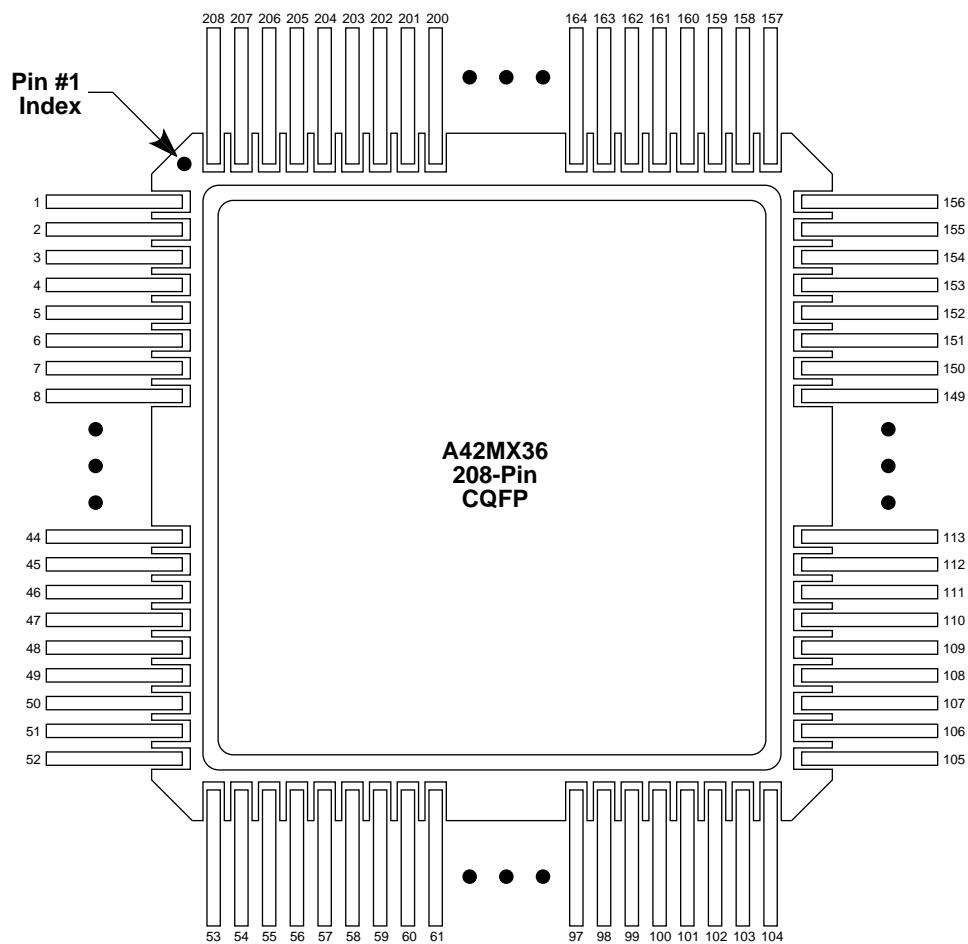
208-Pin CQFP

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
1	GND	40	I/O	79	V$_{CCA}$	118	I/O
2	V$_{CCA}$	41	I/O	80	V$_{CCI}$	119	I/O
3	MODE	42	I/O	81	I/O	120	I/O
4	I/O	43	I/O	82	I/O	121	I/O
5	I/O	44	I/O	83	I/O	122	I/O
6	I/O	45	I/O	84	I/O	123	I/O
7	I/O	46	I/O	85	I/O (WD)	124	I/O
8	I/O	47	I/O	86	I/O (WD)	125	I/O
9	I/O	48	I/O	87	I/O	126	GND
10	I/O	49	I/O	88	I/O	127	I/O
11	I/O	50	I/O	89	I/O	128	TCK, I/O
12	I/O	51	I/O	90	I/O	129	GND (LP)
13	I/O	52	GND	91	QCLKB, I/O	130	V$_{CCA}$
14	I/O	53	GND	92	I/O	131	GND
15	I/O	54	TMS, I/O	93	I/O (WD)	132	V$_{CCI}$
16	I/O	55	TDI, I/O	94	I/O (WD)	133	V$_{CCA}$
17	V$_{CCA}$	56	I/O	95	I/O	134	I/O
18	I/O	57	I/O (WD)	96	I/O	135	I/O
19	I/O	58	I/O (WD)	97	I/O	136	V$_{CCA}$
20	I/O	59	I/O	98	V$_{CCI}$	137	I/O
21	I/O	60	V$_{CCI}$	99	I/O	138	I/O
22	GND	61	I/O	100	I/O (WD)	139	I/O
23	I/O	62	I/O	101	I/O (WD)	140	I/O
24	I/O	63	I/O	102	I/O	141	I/O
25	I/O	64	I/O	103	TDO, I/O	142	I/O
26	I/O	65	QCLKA, I/O	104	I/O	143	I/O
27	GND	66	I/O (WD)	105	GND	144	I/O
28	V$_{CCI}$	67	I/O (WD)	106	V$_{CCA}$	145	I/O
29	V$_{CCA}$	68	I/O	107	I/O	146	I/O
30	I/O	69	I/O	108	I/O	147	I/O
31	I/O	70	I/O (WD)	109	I/O	148	I/O
32	V$_{CCA}$	71	I/O (WD)	110	I/O	149	I/O
33	I/O	72	I/O	111	I/O	150	GND
34	I/O	73	I/O	112	I/O	151	I/O
35	I/O	74	I/O	113	I/O	152	I/O
36	I/O	75	I/O	114	I/O	153	I/O
37	I/O	76	I/O	115	I/O	154	I/O
38	I/O	77	I/O	116	I/O	155	I/O
39	I/O	78	GND	117	I/O	156	I/O

208-Pin CQFP (Continued)

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
157	GND	170	I/O	183	V_{CCA}	196	QCLKC, I/O
158	I/O	171	QCLKD, I/O	184	GND	197	I/O
159	SDI, I/O	172	I/O	185	I/O	198	I/O
160	I/O	173	I/O	186	CLKB, I/O	199	I/O
161	I/O (WD)	174	I/O	187	I/O	200	I/O
162	I/O (WD)	175	I/O	188	PRB, I/O	201	I/O
163	I/O	176	I/O (WD)	189	I/O	202	V_{CCI}
164	V_{CCI}	177	I/O (WD)	190	I/O (WD)	203	I/O (WD)
165	I/O	178	PRA, I/O	191	I/O (WD)	204	I/O (WD)
166	I/O	179	I/O	192	I/O	205	I/O
167	I/O	180	CLKA, I/O	193	I/O	206	I/O
168	I/O (WD)	181	I/O	194	I/O (WD)	207	DCLK, I/O
169	I/O (WD)	182	V_{CCI}	195	I/O (WD)	208	I/O

Package Pin Assignments (continued)

256-Pin CQFP (Top View)
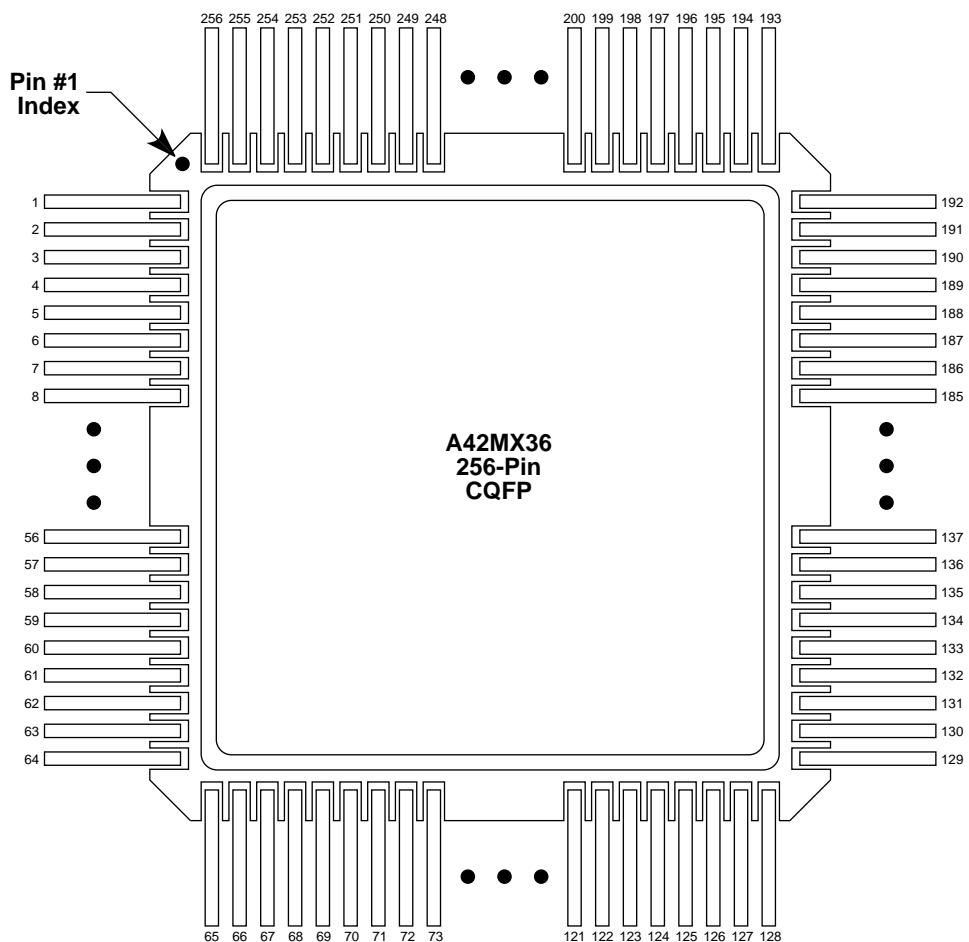
256-Pin CQFP

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
1	NC	44	I/O	87	I/O, (WD)	130	NC
2	GND	45	I/O	88	I/O, (WD)	131	GND
3	I/O	46	I/O	89	I/O	132	I/O
4	I/O	47	I/O	90	I/O	133	I/O
5	I/O	48	GND	91	I/O	134	I/O
6	I/O	49	I/O	92	I/O	135	I/O
7	I/O	50	I/O	93	I/O	136	I/O
8	I/O	51	I/O	94	I/O	137	I/O
9	I/O	52	I/O	95	V_{CCI}	138	I/O
10	GND	53	I/O	96	V_{CCA}	139	GND
11	I/O	54	I/O	97	GND	140	I/O
12	I/O	55	I/O	98	GND	141	I/O
13	I/O	56	I/O	99	I/O	142	I/O
14	I/O	57	I/O	100	I/O	143	I/O
15	I/O	58	I/O	101	I/O	144	I/O
16	I/O	59	I/O	102	I/O	145	I/O
17	I/O	60	V_{CCA}	103	I/O	146	I/O
18	I/O	61	GND	104	I/O	147	I/O
19	I/O	62	GND	105	I/O, (WD)	148	I/O
20	I/O	63	NC	106	I/O, (WD)	149	I/O
21	I/O	64	NC	107	I/O	150	I/O
22	I/O	65	NC	108	I/O	151	I/O
23	I/O	66	I/O	109	I/O, (WD)	152	I/O
24	I/O	67	SDO, TDO, I/O	110	I/O, (WD)	153	I/O
25	I/O	68	I/O	111	I/O	154	I/O
26	V_{CCA}	69	I/O (WD)	112	QCLKA, I/O	155	V_{CCA}
27	I/O	70	I/O (WD)	113	I/O	156	I/O
28	I/O	71	I/O	114	GND	157	I/O
29	V_{CCA}	72	V_{CCI}	115	I/O	158	V_{CCA}
30	V_{CCI}	73	I/O	116	I/O	159	V_{CCI}
31	GND	74	I/O	117	I/O	160	GND
32	V_{CCA}	75	I/O	118	I/O	161	I/O
33	GND	76	I/O (WD)	119	V_{CCI}	162	I/O
34	TCK, I/O	77	GND	120	I/O	163	I/O
35	I/O	78	I/O, (WD)	121	I/O, (WD)	164	I/O
36	GND	79	I/O	122	I/O, (WD)	165	GND
37	I/O	80	QCLKB, I/O	123	I/O	166	I/O
38	I/O	81	I/O	124	I/O	167	I/O
39	I/O	82	I/O	125	I/O	168	I/O
40	I/O	83	I/O	126	I/O	169	I/O
41	I/O	84	I/O	127	GND	170	V_{CCA}
42	I/O	85	I/O	128	NC	171	I/O
43	I/O	86	I/O	129	NC	172	I/O

256-Pin CQFP (Continued)

Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function	Pin Number	A42MX36 Function
173	I/O	194	I/O	215	I/O (WD)	236	I/O
174	I/O	195	DCLK, I/O	216	I/O (WD)	237	I/O
175	I/O	196	I/O	217	I/O	238	I/O
176	I/O	197	I/O	218	PRB, I/O	239	I/O
177	I/O	198	I/O	219	I/O	240	QCLKD, I/O
178	I/O	199	I/O (WD)	220	CLKB, I/O	241	I/O
179	I/O	200	I/O (WD)	221	I/O	242	I/O (WD)
180	GND	201	V_{CCI}	222	GND	243	GND
181	I/O	202	I/O	223	GND	244	I/O (WD)
182	I/O	203	I/O	224	V_{CCA}	245	I/O
183	I/O	204	I/O	225	V_{CCI}	246	I/O
184	I/O	205	I/O	226	I/O	247	I/O
185	I/O	206	GND	227	CLKA, I/O	248	V_{CCI}
186	I/O	207	I/O	228	I/O	249	I/O
187	I/O	208	I/O	229	PRA, I/O	250	I/O (WD)
188	MODE	209	QCLKC, I/O	230	I/O	251	I/O (WD)
189	V_{CCA}	210	I/O	231	I/O	252	I/O
190	GND	211	I/O (WD)	232	I/O (WD)	253	SDI, I/O
191	NC	212	I/O (WD)	233	I/O (WD)	254	I/O
192	NC	213	I/O	234	I/O	255	GND
193	NC	214	I/O	235	I/O	256	NC

Package Pin Assignments (continued)

272-Pin BGA Package (Top View)
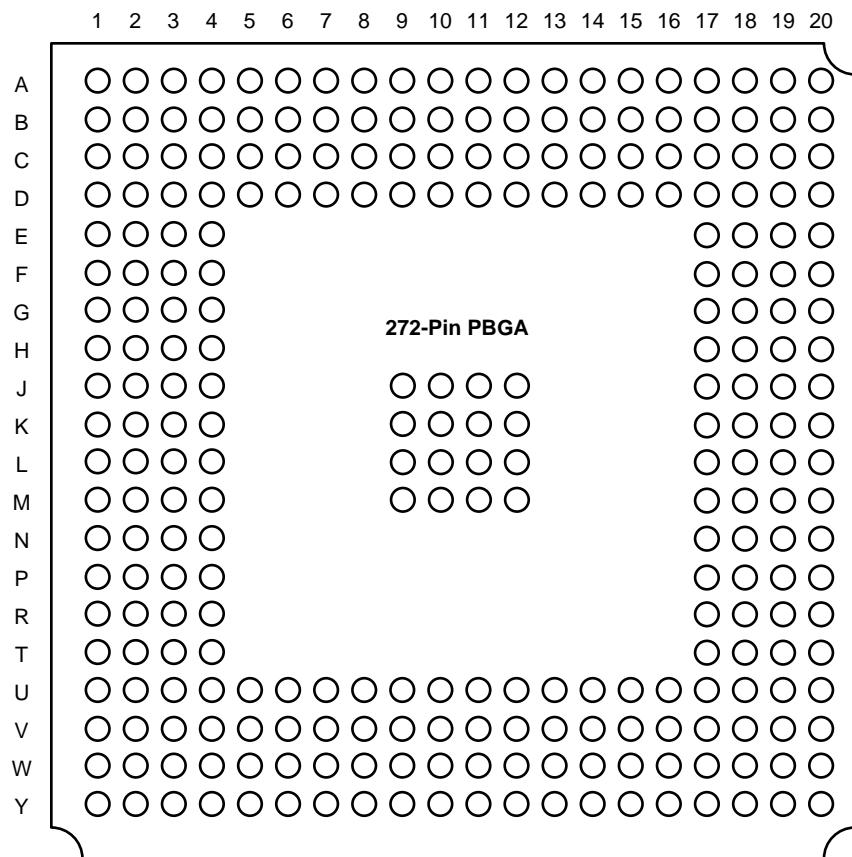
272-Pin PBGA

272-Pin PBGA

Ball	A42MX36 Function	Ball	A42MX36 Function	Ball	A42MX36 Function	Ball	A42MX36 Function
A1	GND	C4	I/O	E19	I/O	K10	GND
A2	GND	C5	I/O (WD)	E20	I/O	K11	GND
A3	I/O	C6	I/O	F1	I/O	K12	GND
A4	I/O (WD)	C7	QCLKC, I/O	F2	I/O	K17	I/O
A5	I/O	C8	I/O	F3	I/O	K18	V_{CCA}
A6	I/O	C9	I/O	F4	V_{CCI}	K19	V_{CCA}
A7	I/O (WD)	C10	CLKB	F17	I/O	K20	GND (LP)
A8	I/O (WD)	C11	PRA, I/O	F18	I/O	L1	I/O
A9	I/O	C12	I/O (WD)	F19	I/O	L2	I/O
A10	I/O	C13	I/O	F20	I/O	L3	V_{CCA}
A11	CLKA	C14	QCLKD, I/O	G1	I/O	L4	V_{CCA}
A12	I/O	C15	I/O	G2	I/O	L9	GND
A13	I/O	C16	I/O (WD)	G3	I/O	L10	GND
A14	I/O	C17	SDI, I/O	G4	V_{CCI}	L11	GND
A15	I/O	C18	I/O	G17	V_{CCI}	L12	GND
A16	I/O (WD)	C19	I/O	G18	I/O	L17	V_{CCI}
A17	I/O	C20	I/O	G19	I/O	L18	I/O
A18	I/O	D1	I/O	G20	I/O	L19	I/O
A19	GND	D2	I/O	H1	I/O	L20	TCK, I/O
A20	GND	D3	I/O	H2	I/O	M1	I/O
B1	GND	D4	I/O	H3	I/O	M2	I/O
B2	GND	D5	V_{CCI}	H4	V_{CCA}	M3	I/O
B3	DCLK, I/O	D6	I/O	H17	I/O	M4	V_{CCI}
B4	I/O	D7	I/O	H18	I/O	M9	GND
B5	I/O	D8	V_{CCA}	H19	I/O	M10	GND
B6	I/O	D9	I/O (WD)	H20	I/O	M11	GND
B7	I/O (WD)	D10	V_{CCI}	J1	I/O	M12	GND
B8	I/O	D11	I/O	J2	I/O	M17	I/O
B9	PRB, I/O	D12	V_{CCI}	J3	I/O	M18	I/O
B10	I/O	D13	I/O	J4	V_{CCI}	M19	I/O
B11	I/O	D14	V_{CCI}	J9	GND	M20	I/O
B12	I/O (WD)	D15	I/O	J10	GND	N1	I/O
B13	I/O	D16	V_{CCA}	J11	GND	N2	I/O
B14	I/O	D17	GND	J12	GND	N3	I/O
B15	I/O (WD)	D18	I/O	J17	V_{CCA}	N4	V_{CCI}
B16	I/O	D19	I/O	J18	I/O	N17	V_{CCI}
B17	I/O (WD)	D20	I/O	J19	I/O	N18	I/O
B18	I/O	E1	I/O	J20	I/O	N19	I/O
B19	GND	E2	I/O	K1	I/O	N20	I/O
B20	GND	E3	I/O	K2	I/O	P1	I/O
C1	I/O	E4	V_{CCA}	K3	I/O	P2	I/O
C2	MODE	E17	V_{CCI}	K4	V_{CCI}	P3	I/O
C3	GND	E18	I/O	K9	GND	P4	V_{CCA}

272-Pin PBGA (Continued)

Ball	A42MX36 Function	Ball	A42MX36 Function	Ball	A42MX36 Function	Ball	A42MX36 Function
P17	I/O	U6	I/O (WD)	V11	I/O	W16	I/O (WD)
P18	I/O	U7	I/O	V12	I/O	W17	I/O
P19	I/O	U8	I/O	V13	I/O (WD)	W18	I/O (WD)
P20	I/O	U9	I/O (WD)	V14	I/O	W19	GND
R1	I/O	U10	V_{CCA}	V15	I/O (WD)	W20	GND
R2	I/O	U11	V_{CCI}	V16	I/O	Y1	GND
R3	I/O	U12	I/O	V17	I/O	Y2	GND
R4	V_{CCI}	U13	I/O	V18	SDO, TDO, I/O	Y3	I/O
R17	V_{CCI}	U14	QCLKB, I/O	V19	I/O	Y4	TDI, I/O
R18	I/O	U15	I/O	V20	I/O	Y5	I/O (WD)
R19	I/O	U16	V_{CCI}	W1	GND	Y6	I/O
R20	I/O	U17	I/O	W2	GND	Y7	QCLKA, I/O
T1	I/O	U18	GND	W3	I/O	Y8	I/O
T2	I/O	U19	I/O	W4	TMS, I/O	Y9	I/O
T3	I/O	U20	I/O	W5	I/O	Y10	I/O
T4	I/O	V1	I/O	W6	I/O	Y11	I/O
T17	V_{CCA}	V2	I/O	W7	I/O	Y12	I/O
T18	I/O	V3	GND	W8	I/O (WD)	Y13	I/O
T19	I/O	V4	GND	W9	I/O (WD)	Y14	I/O
T20	I/O	V5	I/O	W10	I/O	Y15	I/O
U1	I/O	V6	I/O	W11	I/O	Y16	I/O
U2	I/O	V7	I/O	W12	I/O	Y17	I/O
U3	I/O	V8	I/O (WD)	W13	I/O (WD)	Y18	I/O (WD)
U4	I/O	V9	I/O	W14	I/O	Y19	GND
U5	V_{CCI}	V10	I/O	W15	I/O	Y20	GND

List of Changes

The following table lists critical changes that were made in the current version of the document.

Previous version	Changes in current version (v5.1)	Page
v5.0	The "Low Power Mode" on page 5 was updated.	page 5
	Footnote 8 in the "Electrical Specifications" table on page 13 was updated.	page 13
	Footnote 8 in the "Electrical Specifications" table on page 14 was updated.	page 14
v4.0.1	Because the changes in this data sheet are extensive and technical in nature, this should be viewed as a new document. Please read it as you would a data sheet that is published for the first time.	ALL
	Note that the "Package Characteristics and Mechanical Drawings" section has been eliminated from the data sheet. The mechanical drawings are now contained in a separate document, "Package Characteristics and Mechanical Drawings," available on the Actel web site.	

Data Sheet Categories

In order to provide the latest information to designers, some datasheets are published before data has been fully characterized. Datasheets are designated as "Product Brief," "Advanced," "Production," and "Web-only." The definition of these categories are as follows:

Product Brief

The product brief is a summerized version of a advanced datasheet (advanced or production) containing general product information. This brief gives an overview of specific device and family information.

Datasheet Supplement

The datasheet supplement gives specific device information for a derivative family that differs from the general family datasheet. The supplement is to be used in conjunction with the datasheet to obtain more detailed information and for specifications that do not differ between the two families.

Advanced

This datasheet version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production.

Unmarked (production)

This datasheet version contains information that is considered to be final.

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